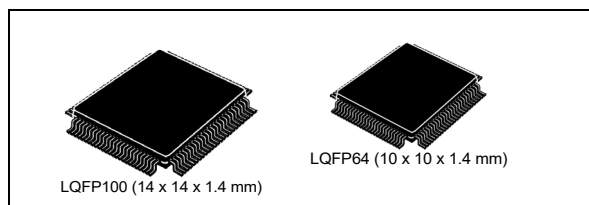


## 32-bit MCU family built on the Power Architecture® for automotive body electronics applications

Datasheet — production data



### Features



- AEC-Q100 qualified
- High-performance up to 48 MHz e200z0h CPU
  - 32-bit Power Architecture® technology CPU
  - Variable length encoding (VLE)
- Memory
  - Up to 256 KB Code Flash with ECC
  - Up to 64 (4x16) KB Data Flash with ECC
  - Up to 16 KB SRAM with ECC
- Interrupts
  - 16 priority levels
  - Non-maskable interrupt (NMI)
  - Up to 38 external interrupts including 18 wakeup lines
- 16-channel eDMA
- GPIOs: 45 (LQFP64), 79 (LQFP100)
- Timer units
  - 4-channel 32-bit periodic interrupt timers
  - 4-channel 32-bit system timer module
  - System watchdog timer
  - 32-bit real-time clock timer
- 16-bit counter time-triggered I/Os
  - Up to 28 channels with PWM/MC/IC/OC
  - 5 independent counters
  - 27-channels with ADC trigger capability
- 12-bit analog-to-digital converter (ADC) with up to 33 channels
  - Up to 61 channels via external multiplexing
  - Individual conversion registers
- Cross triggering unit (CTU)
- Dedicated diagnostic module for lighting
  - Advanced PWM generation
  - Time-triggered diagnostics
  - PWM-synchronized ADC measurements
- Communications interfaces
  - 1 FlexCAN interface (2.0B active) with 32 message buffers
  - 3 LINFlex/UART, 1 with DMA capability
  - 2 DSPI
- Clock generation
  - 4 to 16 MHz fast external crystal oscillator
  - 16 MHz fast internal RC oscillator
  - 128 kHz slow internal RC oscillator
  - Software-controlled FMPLL
  - Clock monitoring unit
- Exhaustive debugging capability
  - Nexus1 on all packages
  - Nexus2+ available on emulation device (SPC560B64B2-ENG)
- On-chip CAN/UART bootstrap loader
- Low power capabilities
  - Several low power mode configurations
  - Ultra-low power standby with RTC, SRAM and CAN monitoring
  - Fast wakeup schemes
- Single 5 V or 3.3 V supply
- Operates in ambient temperature range of -40 to 125 °C

**Table 1. Device summary**

| Package | Part number          |                      |
|---------|----------------------|----------------------|
|         | 128 Kbyte code Flash | 256 Kbyte code Flash |
| LQFP100 | SPC560D30L3          | SPC560D40L3          |
| LQFP64  | SPC560D30L1          | SPC560D40L1          |

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# 1 Introduction

## 1.1 Document overview

This document describes the device features and highlights the important electrical and physical characteristics.

## 1.2 Description

These 32-bit automotive microcontrollers are a family of system-on-chip (SoC) devices designed to be central to the development of the next wave of central vehicle body controller, smart junction box, front module, peripheral body, door control and seat control applications.

This family is one of a series of next-generation integrated automotive microcontrollers based on the Power Architecture technology and designed specifically for embedded applications.

The advanced and cost-efficient e200z0h host processor core of this automotive controller family complies with the Power Architecture technology and only implements the VLE (variable-length encoding) APU (auxiliary processing unit) and provides improved code density. It operates at speed of up to 48 MHz and offers high performance processing optimized for low power consumption. It capitalizes on the available development infrastructure of current power architecture devices and is supported with software drivers, operating systems and configuration code to assist with the user's implementations.

The device platform has a single level of memory hierarchy and can support a wide range of on-chip static random access memory (SRAM) and internal flash memory.

**Table 2. SPC560D30x and SPC560D40x device comparison**

| Feature                                 | Device                |               |               |               |
|-----------------------------------------|-----------------------|---------------|---------------|---------------|
|                                         | SPC560D30L1           | SPC560D30L3   | SPC560D40L1   | SPC560D40L3   |
| CPU                                     | e200z0h               |               |               |               |
| Execution speed                         | Static – up to 48 MHz |               |               |               |
| Code flash memory                       | 128 KB                |               | 256 KB        |               |
| Data flash memory                       | 64 KB (4 × 16 KB)     |               |               |               |
| SRAM                                    | 12 KB                 |               | 16 KB         |               |
| eDMA                                    | 16 ch                 |               |               |               |
| ADC (12-bit)                            | 16 ch                 | 33 ch         | 16 ch         | 33 ch         |
| CTU                                     | 16 ch                 |               |               |               |
| Total timer I/O <sup>(1)</sup><br>eMIOS | 14 ch, 16-bit         | 28 ch, 16-bit | 14 ch, 16-bit | 28 ch, 16-bit |
| Type X <sup>(2)</sup>                   | 2 ch                  | 5 ch          | 2 ch          | 5 ch          |
| Type Y <sup>(3)</sup>                   | —                     | 9 ch          | —             | 9 ch          |
| Type G <sup>(4)</sup>                   | 7 ch                  | 7 ch          | 7 ch          | 7 ch          |

Table 2. SPC560D30x and SPC560D40x device comparison (continued)

| Feature               | Device      |             |             |             |
|-----------------------|-------------|-------------|-------------|-------------|
|                       | SPC560D30L1 | SPC560D30L3 | SPC560D40L1 | SPC560D40L3 |
| Type H <sup>(5)</sup> | 4 ch        | 7 ch        | 4 ch        | 7 ch        |
| SCI (LINFlex)         | 3           |             |             |             |
| SPI (DSPI)            | 2           |             |             |             |
| CAN (FlexCAN)         | 1           |             |             |             |
| GPIO <sup>(6)</sup>   | 45          | 79          | 45          | 79          |
| Debug                 | JTAG        |             |             |             |
| Package               | LQFP64      | LQFP100     | LQFP64      | LQFP100     |

1. Refer to eMIOS chapter of device reference manual for information on the channel configuration and functions.

2. Type X = MC + MCB + OPWMT + OPWMB + OPWFMB + SAIC + SAOC

3. Type Y = OPWMT + OPWMB + SAIC + SAOC

4. Type G = MCB + IPWM + IPM + DAOC + OPWMT + OPWMB + OPWFMB + OPWMCB + SAIC + SAOC

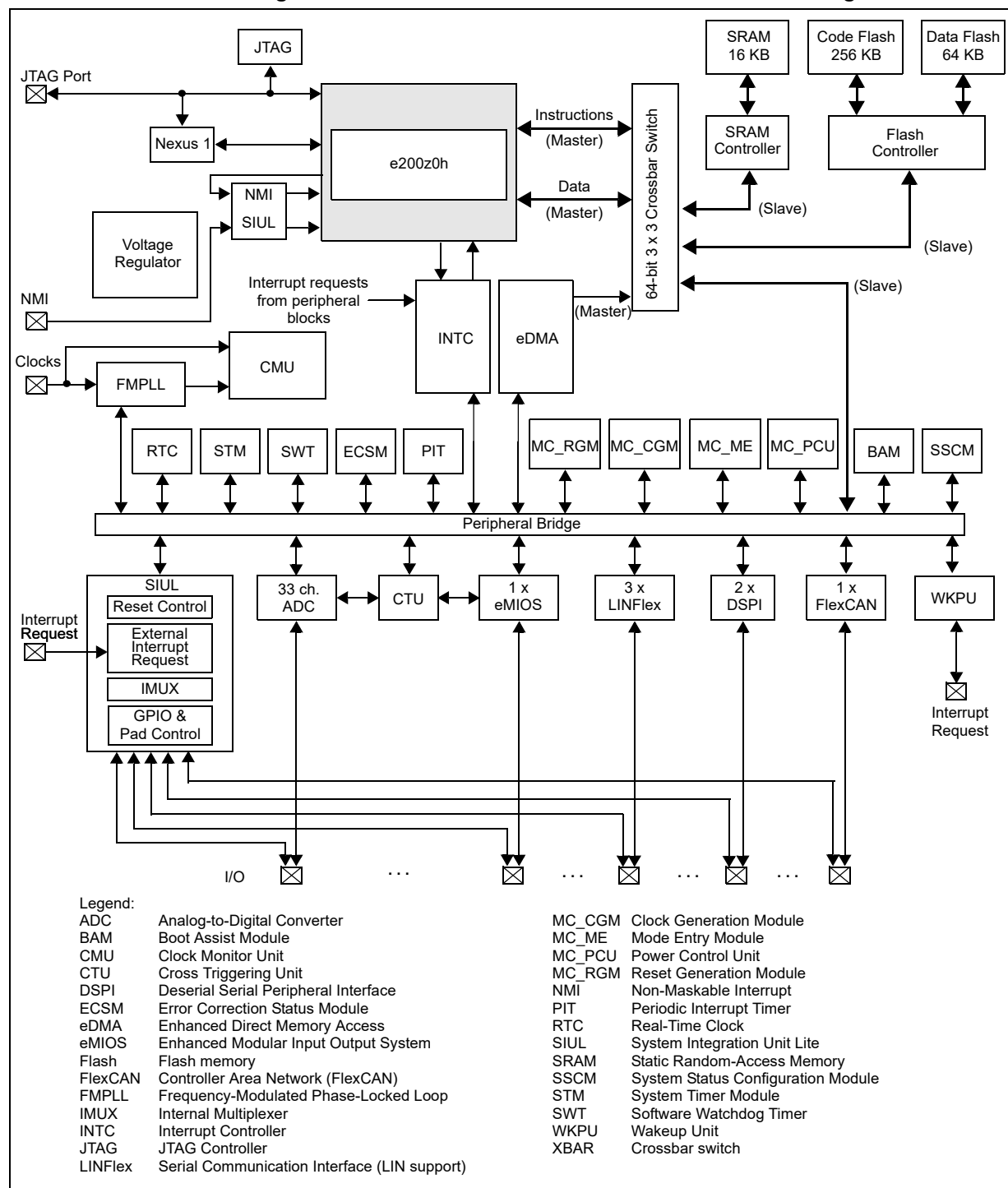
5. Type H = IPWM + IPM + DAOC + OPWMT + OPWMB + SAIC + SAOC

6. I/O count based on multiplexing with peripherals.

## 2 Block diagram

Figure 1 shows a top-level block diagram of the SPC560D30x and SPC560D40x device series.

Figure 1. SPC560D30x and SPC560D40x series block diagram



[Table 3](#) summarizes the functions of all the blocks present in the SPC560D30x and SPC560D40x series of microcontrollers. Note that the presence and number of blocks varies by device and package.

**Table 3. SPC560D30x and SPC560D40x series block summary**

| Block                                         | Function                                                                                                                                                                                                                                                                                                          |
|-----------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Analog-to-digital converter (ADC)             | Multi-channel, 12-bit analog-to-digital converter                                                                                                                                                                                                                                                                 |
| Boot assist module (BAM)                      | A block of read-only memory containing VLE code which is executed according to the boot mode of the device                                                                                                                                                                                                        |
| Clock generation module (MC_CGM)              | Provides logic and control required for the generation of system and peripheral clocks                                                                                                                                                                                                                            |
| Clock monitor unit (CMU)                      | Monitors clock source (internal and external) integrity                                                                                                                                                                                                                                                           |
| Cross triggering unit (CTU)                   | Enables synchronization of ADC conversions with a timer event from the eMIOS or PIT                                                                                                                                                                                                                               |
| Crossbar switch (XBAR)                        | Supports simultaneous connections between two master ports and three slave ports. The crossbar supports a 32-bit address bus width and a 64-bit data bus width.                                                                                                                                                   |
| Deserial serial peripheral interface (DSPI)   | Provides a synchronous serial interface for communication with external devices                                                                                                                                                                                                                                   |
| Enhanced direct memory access (eDMA)          | Performs complex data transfers with minimal intervention from a host processor via "n" programmable channels.                                                                                                                                                                                                    |
| Enhanced modular input output system (eMIOS)  | Provides the functionality to generate or measure events                                                                                                                                                                                                                                                          |
| Error correction status module (ECSM)         | Provides a myriad of miscellaneous control functions for the device including program-visible information about configuration and revision levels, a reset status register, wakeup control for exiting sleep modes, and optional features such as information on memory errors reported by error-correcting codes |
| Flash memory                                  | Provides non-volatile storage for program code, constants and variables                                                                                                                                                                                                                                           |
| FlexCAN (controller area network)             | Supports the standard CAN communications protocol                                                                                                                                                                                                                                                                 |
| Frequency-modulated phase-locked loop (FMPLL) | Generates high-speed system clocks and supports programmable frequency modulation                                                                                                                                                                                                                                 |
| Internal multiplexer (IMUX) SIU subblock      | Allows flexible mapping of peripheral interface on the different pins of the device                                                                                                                                                                                                                               |
| Interrupt controller (INTC)                   | Provides priority-based preemptive scheduling of interrupt requests                                                                                                                                                                                                                                               |
| JTAG controller (JTAGC)                       | Provides the means to test chip functionality and connectivity while remaining transparent to system logic when not in test mode                                                                                                                                                                                  |
| LINFlex controller                            | Manages a high number of LIN (Local Interconnect Network protocol) messages efficiently with a minimum of CPU load                                                                                                                                                                                                |
| Mode entry module (MC_ME)                     | Provides a mechanism for controlling the device operational mode and mode transition sequences in all functional states. It also manages the power control unit, reset generation module, clock generation module, and holds the configuration, control and status registers accessible for applications          |
| Non-maskable interrupt (NMI)                  | Handles external events which produces an immediate response, such as power down detection                                                                                                                                                                                                                        |

**Table 3. SPC560D30x and SPC560D40x series block summary (continued)**

| Block                                         | Function                                                                                                                                                                                                                          |
|-----------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Periodic interrupt timer (PIT)                | Produces periodic interrupts and triggers                                                                                                                                                                                         |
| Power control unit (MC_PCU)                   | Reduces the overall power consumption by disconnecting parts of the device from the power supply via a power switching device; device components are grouped into sections called "power domains" which are controlled by the PCU |
| Real-time counter (RTC)                       | Provides a free-running counter and interrupt generation capability that can be used for timekeeping applications                                                                                                                 |
| Reset generation module (MC_RGM)              | Centralizes reset sources and manages the device reset sequence of the device                                                                                                                                                     |
| Static random-access memory (SRAM)            | Provides storage for program code, constants, and variables                                                                                                                                                                       |
| System integration unit lite (SIUL)           | Provides control over all the electrical pad controls and up to 32 ports with 16-bits of bidirectional, general-purpose input and output signals and supports up to 32 external interrupts with trigger event configuration       |
| System status and configuration module (SSCM) | Provides system configuration and status data (such as memory size and status, device mode and security status), device identification data, debug status port enable and selection, and bus and peripheral abort enable/disable  |
| System timer module (STM)                     | Provides a set of output compare events to support AUTOSAR (Automotive Open System Architecture) and operating system tasks                                                                                                       |
| Software watchdog timer (SWT)                 | Provides protection from runaway code                                                                                                                                                                                             |
| Wakeup unit (WKPU)                            | Supports up to 18 external sources that can generate interrupts or wakeup events, of which one can cause non-maskable interrupt requests or wakeup events.                                                                        |



## 3 Package pinouts and signal descriptions

### 3.1 Package pinouts

The available LQFP pinouts are provided in the following figures. For pin signal descriptions, refer to [Table 6](#).

[Figure 2](#) shows the SPC560D30x and SPC560D40x in the LQFP100 package.

**Figure 2. LQFP100 LQFP pin configuration (top view)**

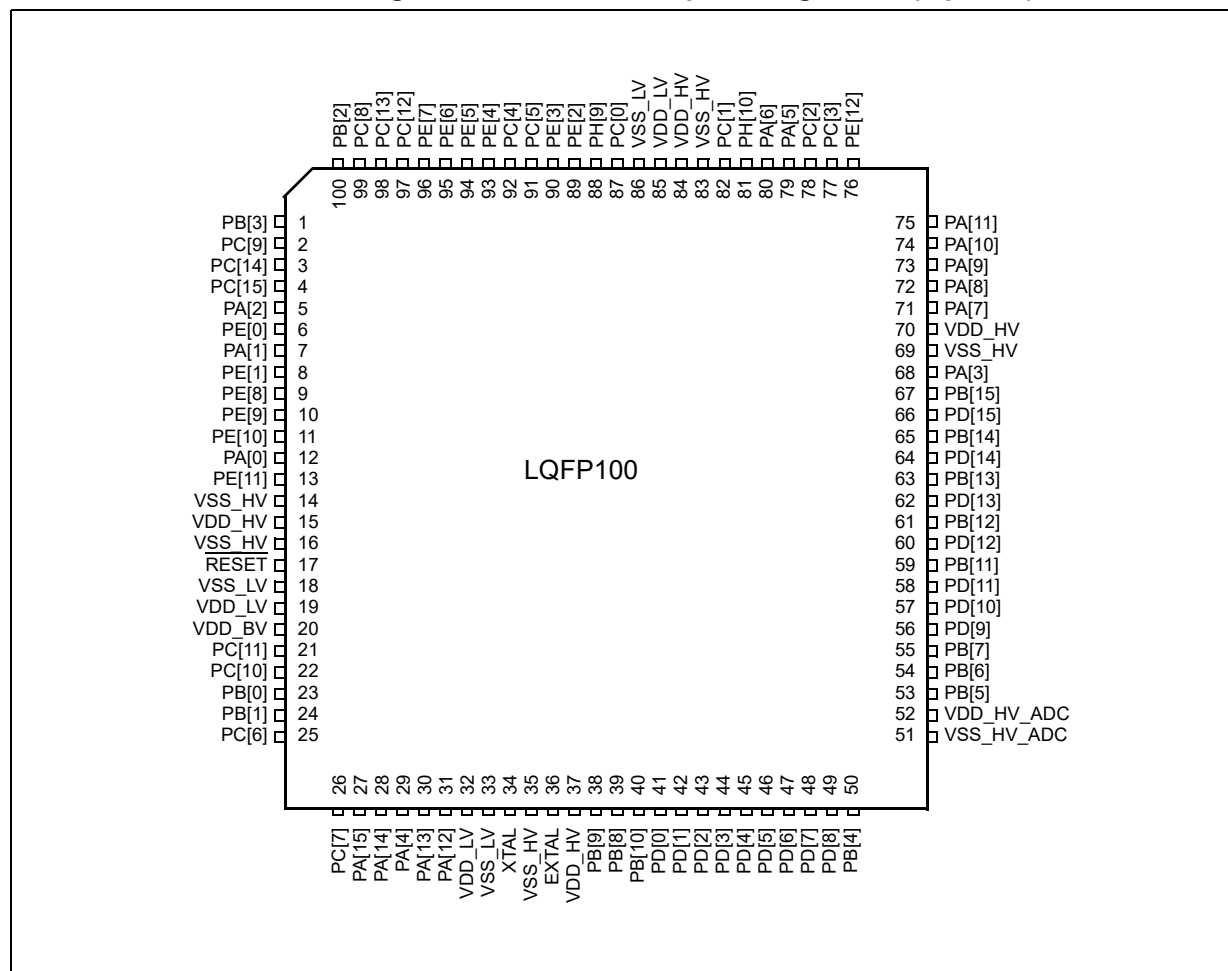
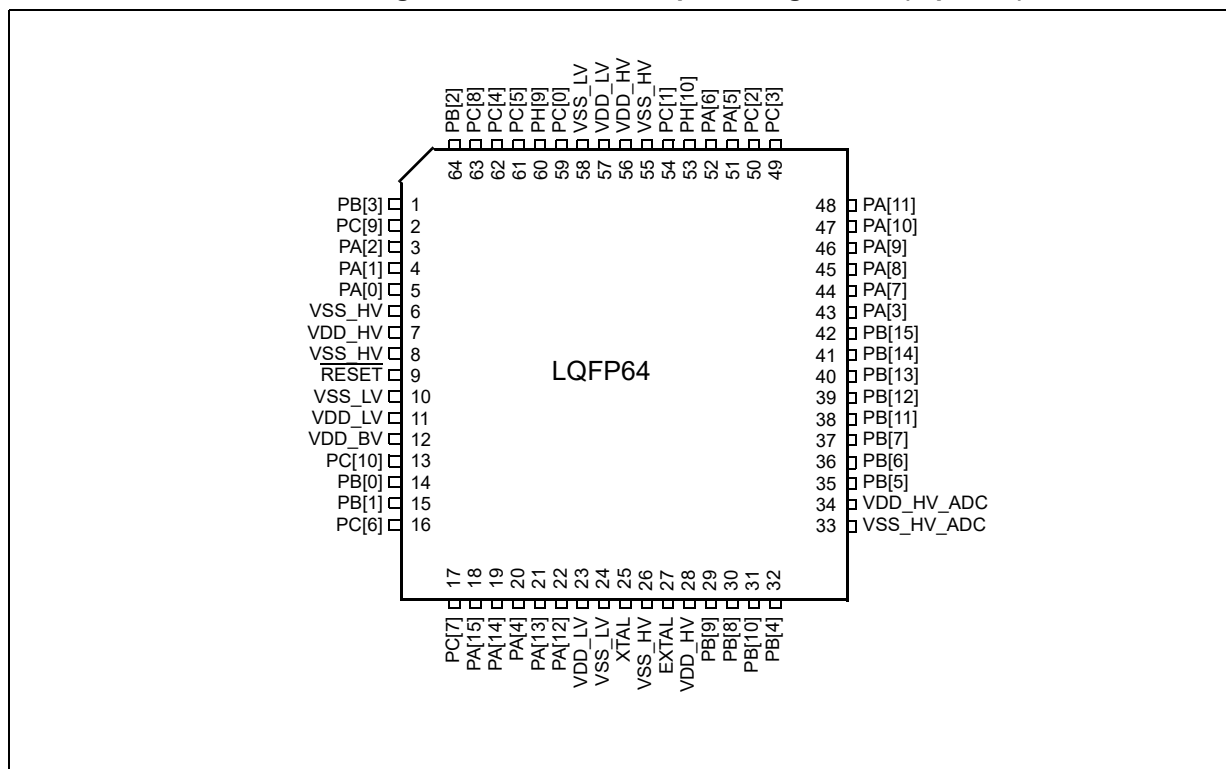


Figure 3 shows the SPC560D30x and SPC560D40x in the LQFP64 package.

Figure 3. LQFP64 LQFP pin configuration (top view)



### 3.2 Pad configuration during reset phases

All pads have a fixed configuration under reset.

During the power-up phase, all pads are forced to tristate.

After power-up phase, all pads are forced to tristate with the following exceptions:

- PA[9] (FAB) is pull-down. Without external strong pull-up the device starts fetching from flash.
- PA[8] (ABS[0]) is pull-up.
- RESET pad is driven low. This is pull-up only after PHASE2 reset completion.
- JTAG pads (TCK, TMS and TDI) are pull-up while TDO remains tristate.
- Precise ADC pads (PB[7:4] and PD[11:0]) are left tristate (no output buffer available).
- Main oscillator pads (EXTAL, XTAL) are tristate.

### 3.3 Voltage supply pins

Voltage supply pins are used to provide power to the device. Two dedicated pins are used for 1.2 V regulator stabilization.

Table 4. Voltage supply pin descriptions

| Port pin | Function                                                                                                                               | Pin number       |                        |
|----------|----------------------------------------------------------------------------------------------------------------------------------------|------------------|------------------------|
|          |                                                                                                                                        | LQFP64           | LQFP100                |
| VDD_HV   | Digital supply voltage                                                                                                                 | 7, 28, 34, 56    | 15, 37, 52, 70, 84     |
| VSS_HV   | Digital ground                                                                                                                         | 6, 8, 26, 33, 55 | 14, 16, 35, 51, 69, 83 |
| VDD_LV   | 1.2 V decoupling pins. Decoupling capacitor must be connected between these pins and the nearest V <sub>SS_LV</sub> pin <sup>(1)</sup> | 11, 23, 57       | 19, 32, 85             |
| VSS_LV   | 1.2 V decoupling pins. Decoupling capacitor must be connected between these pins and the nearest V <sub>DD_LV</sub> pin <sup>(1)</sup> | 10, 24, 58       | 18, 33, 86             |
| VDD_BV   | Internal regulator supply voltage                                                                                                      | 12               | 20                     |

1. A decoupling capacitor must be placed between each of the three VDD\_LV/VSS\_LV supply pairs to ensure stable voltage (refer the [Section 4.5: Recommended operating conditions](#) in the device datasheet for details).

### 3.4 Pad types

In the device the following types of pads are available for system pins and functional port pins:

- S = Slow <sup>(1)</sup>
- M = Medium <sup>(1)</sup> (2)
- F = Fast <sup>(1)</sup> (2)
- I = Input only with analog feature <sup>(1)</sup>
- J = Input/Output ('S' pad) with analog feature
- X = Oscillator

### 3.5 System pins

The system pins are listed in [Table 5](#).

- Refer, [Section 4.7: I/O pad electrical characteristics](#) in the device datasheet for details.
- All medium and fast pads are in slow configuration by default at reset and can be configured as fast or medium (see the PCR[SRC] description in the device reference manual).

Table 5. System pin descriptions

| Port pin                  | Function                                                                                                                                                                                | I/O direction | Pad type | RESET configuration                   | Pin number |         |
|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------|----------|---------------------------------------|------------|---------|
|                           |                                                                                                                                                                                         |               |          |                                       | LQFP64     | LQFP100 |
| $\overline{\text{RESET}}$ | Bidirectional reset with Schmitt-Trigger characteristics and noise filter                                                                                                               | I/O           | M        | Input, weak pull-up only after PHASE2 | 9          | 17      |
| EXTAL                     | Analog output of the oscillator amplifier circuit, when the oscillator is not in bypass mode. Analog input for the clock generator when the oscillator is in bypass mode <sup>(1)</sup> | I/O           | X        | Tristate                              | 27         | 36      |
| XTAL                      | Analog input of the oscillator amplifier circuit. Needs to be grounded if oscillator is used in bypass mode <sup>(1)</sup>                                                              | I             | X        | Tristate                              | 25         | 34      |

1. Refer to the relevant section of the device datasheet.

### 3.6 Functional ports

The functional port pins are listed in [Table 6](#).

Table 6. Functional port pin descriptions

| Port pin | PCR    | Alternate function <sup>(1)</sup>  | Function                                                                     | Peripheral                                | I/O direction <sup>(2)</sup>   | Pad type | RESET configuration | Pin number |         |
|----------|--------|------------------------------------|------------------------------------------------------------------------------|-------------------------------------------|--------------------------------|----------|---------------------|------------|---------|
|          |        |                                    |                                                                              |                                           |                                |          |                     | LQFP64     | LQFP100 |
| Port A   |        |                                    |                                                                              |                                           |                                |          |                     |            |         |
| PA[0]    | PCR[0] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[0]<br>E0UC[0]<br>CLKOUT<br>E0UC[13]<br>WKPU[19] <sup>(3)</sup>          | SIUL<br>eMIOS_0<br>CGL<br>eMIOS_0<br>WKPU | I/O<br>I/O<br>O<br>I/O<br>I    | M        | Tristate            | 5          | 12      |
| PA[1]    | PCR[1] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[1]<br>E0UC[1]<br>—<br>—<br>NMI <sup>(4)</sup><br>WKPU[2] <sup>(3)</sup> | SIUL<br>eMIOS_0<br>—<br>—<br>WKPU<br>WKPU | I/O<br>I/O<br>—<br>—<br>I<br>I | S        | Tristate            | 4          | 7       |
| PA[2]    | PCR[2] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[2]<br>E0UC[2]<br>—<br>MA[2]<br>WKPU[3] <sup>(3)</sup>                   | SIUL<br>eMIOS_0<br>—<br>ADC<br>WKPU       | I/O<br>I/O<br>—<br>O<br>I      | S        | Tristate            | 3          | 5       |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR    | Alternate function <sup>(1)</sup>                   | Function                                                   | Peripheral                                     | I/O direction <sup>(2)</sup>     | Pad type | RESET configuration | Pin number |         |
|----------|--------|-----------------------------------------------------|------------------------------------------------------------|------------------------------------------------|----------------------------------|----------|---------------------|------------|---------|
|          |        |                                                     |                                                            |                                                |                                  |          |                     | LQFP64     | LQFP100 |
| PA[3]    | PCR[3] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>—                  | GPIO[3]<br>E0UC[3]<br>—<br>CS4_0<br>EIRQ[0]<br>ADC1_S[0]   | SIUL<br>eMIOS_0<br>—<br>DSPI_0<br>SIUL<br>ADC  | I/O<br>I/O<br>—<br>I/O<br>I<br>I | S        | Tristate            | 43         | 68      |
| PA[4]    | PCR[4] | AF0<br>AF1<br>AF2<br>AF3<br>—                       | GPIO[4]<br>E0UC[4]<br>—<br>CS0_1<br>WKPU[9] <sup>(3)</sup> | SIUL<br>eMIOS_0<br>—<br>DSPI_1<br>WKPU         | I/O<br>I/O<br>—<br>I/O<br>I      | S        | Tristate            | 20         | 29      |
| PA[5]    | PCR[5] | AF0<br>AF1<br>AF2<br>AF3                            | GPIO[5]<br>E0UC[5]<br>—<br>—                               | SIUL<br>eMIOS_0<br>—<br>—                      | I/O<br>I/O<br>—<br>—             | M        | Tristate            | 51         | 79      |
| PA[6]    | PCR[6] | AF0<br>AF1<br>AF2<br>AF3<br>—                       | GPIO[6]<br>E0UC[6]<br>—<br>CS1_1<br>EIRQ[1]                | SIUL<br>eMIOS_0<br>—<br>DSPI_1<br>SIUL         | I/O<br>I/O<br>—<br>I/O<br>I      | S        | Tristate            | 52         | 80      |
| PA[7]    | PCR[7] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>—                  | GPIO[7]<br>E0UC[7]<br>—<br>—<br>EIRQ[2]<br>ADC1_S[1]       | SIUL<br>eMIOS_0<br>—<br>—<br>SIUL<br>ADC       | I/O<br>I/O<br>—<br>—<br>I<br>I   | S        | Tristate            | 44         | 71      |
| PA[8]    | PCR[8] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>N/A <sup>(5)</sup> | GPIO[8]<br>E0UC[8]<br>E0UC[14]<br>—<br>EIRQ[3]<br>ABS[0]   | SIUL<br>eMIOS_0<br>eMIOS_0<br>—<br>SIUL<br>BAM | I/O<br>I/O<br>—<br>—<br>I<br>I   | S        | Input, weak pull-up | 45         | 72      |
| PA[9]    | PCR[9] | AF0<br>AF1<br>AF2<br>AF3<br>N/A <sup>(5)</sup>      | GPIO[9]<br>E0UC[9]<br>—<br>CS2_1<br>FAB                    | SIUL<br>eMIOS_0<br>—<br>DSPI_1<br>BAM          | I/O<br>I/O<br>—<br>I/O<br>I      | S        | Pull-down           | 46         | 73      |

Table 6. Functional port pin descriptions (continued)

| Port pin      | PCR     | Alternate function <sup>(1)</sup>       | Function                                                          | Peripheral                                            | I/O direction <sup>(2)</sup>        | Pad type | RESET configuration | Pin number |         |
|---------------|---------|-----------------------------------------|-------------------------------------------------------------------|-------------------------------------------------------|-------------------------------------|----------|---------------------|------------|---------|
|               |         |                                         |                                                                   |                                                       |                                     |          |                     | LQFP64     | LQFP100 |
| PA[10]        | PCR[10] | AF0<br>AF1<br>AF2<br>AF3<br>—           | GPIO[10]<br>E0UC[10]<br>—<br>LIN2TX<br>ADC1_S[2]                  | SIUL<br>eMIOS_0<br>—<br>LINFlex_2<br>ADC              | I/O<br>I/O<br>—<br>O<br>I           | S        | Tristate            | 47         | 74      |
| PA[11]        | PCR[11] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>—<br>— | GPIO[11]<br>E0UC[11]<br>—<br>—<br>EIRQ[16]<br>ADC1_S[3]<br>LIN2RX | SIUL<br>eMIOS_0<br>—<br>—<br>SIUL<br>ADC<br>LINFlex_2 | I/O<br>I/O<br>—<br>—<br>I<br>I<br>I | S        | Tristate            | 48         | 75      |
| PA[12]        | PCR[12] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>—      | GPIO[12]<br>—<br>—<br>—<br>EIRQ[17]<br>SIN_0                      | SIUL<br>—<br>—<br>—<br>SIUL<br>DSPI_0                 | I/O<br>—<br>—<br>—<br>I<br>I        | S        | Tristate            | 22         | 31      |
| PA[13]        | PCR[13] | AF0<br>AF1<br>AF2<br>AF3                | GPIO[13]<br>SOUT_0<br>—<br>CS3_1                                  | SIUL<br>DSPI_0<br>—<br>DSPI_1                         | I/O<br>O<br>—<br>I/O                | M        | Tristate            | 21         | 30      |
| PA[14]        | PCR[14] | AF0<br>AF1<br>AF2<br>AF3<br>—           | GPIO[14]<br>SCK_0<br>CS0_0<br>E0UC[0]<br>EIRQ[4]                  | SIUL<br>DSPI_0<br>DSPI_0<br>eMIOS_0<br>SIUL           | I/O<br>I/O<br>I/O<br>I/O<br>I       | M        | Tristate            | 19         | 28      |
| PA[15]        | PCR[15] | AF0<br>AF1<br>AF2<br>AF3<br>—           | GPIO[15]<br>CS0_0<br>SCK_0<br>E0UC[1]<br>WKPU[10] <sup>(3)</sup>  | SIUL<br>DSPI_0<br>DSPI_0<br>eMIOS_0<br>WKPU           | I/O<br>I/O<br>I/O<br>I/O<br>I       | M        | Tristate            | 18         | 27      |
| <b>Port B</b> |         |                                         |                                                                   |                                                       |                                     |          |                     |            |         |
| PB[0]         | PCR[16] | AF0<br>AF1<br>AF2<br>AF3                | GPIO[16]<br>CAN0TX<br>—<br>LIN2TX                                 | SIUL<br>FlexCAN_0<br>—<br>LINFlex_2                   | I/O<br>O<br>—<br>O                  | M        | Tristate            | 14         | 23      |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup>  | Function                                                         | Peripheral                                       | I/O direction <sup>(2)</sup> | Pad type | RESET configuration | Pin number |         |
|----------|---------|------------------------------------|------------------------------------------------------------------|--------------------------------------------------|------------------------------|----------|---------------------|------------|---------|
|          |         |                                    |                                                                  |                                                  |                              |          |                     | LQFP64     | LQFP100 |
| PB[1]    | PCR[17] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[17]<br>—<br>—<br>LIN0RX<br>WKPU[4] <sup>(3)</sup><br>CAN0RX | SIUL<br>—<br>—<br>LINFlex_0<br>WKPU<br>FlexCAN_0 | I/O<br>—<br>—<br>I<br>I<br>I | S        | Tristate            | 15         | 24      |
| PB[2]    | PCR[18] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[18]<br>LIN0TX<br>—<br>—                                     | SIUL<br>LINFlex_0<br>—<br>—                      | I/O<br>O<br>—<br>—           | M        | Tristate            | 64         | 100     |
| PB[3]    | PCR[19] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[19]<br>—<br>—<br>—<br>WKPU[11] <sup>(3)</sup><br>LIN0RX     | SIUL<br>—<br>—<br>—<br>WKPU<br>LINFlex_0         | I/O<br>—<br>—<br>—<br>I<br>I | S        | Tristate            | 1          | 1       |
| PB[4]    | PCR[20] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[20]<br>—<br>—<br>—<br>ADC1_P[0]                             | SIUL<br>—<br>—<br>—<br>ADC                       | I<br>—<br>—<br>—<br>I        | I        | Tristate            | 32         | 50      |
| PB[5]    | PCR[21] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[21]<br>—<br>—<br>—<br>ADC1_P[1]                             | SIUL<br>—<br>—<br>—<br>ADC                       | I<br>—<br>—<br>—<br>I        | I        | Tristate            | 35         | 53      |
| PB[6]    | PCR[22] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[22]<br>—<br>—<br>—<br>ADC1_P[2]                             | SIUL<br>—<br>—<br>—<br>ADC                       | I<br>—<br>—<br>—<br>I        | I        | Tristate            | 36         | 54      |
| PB[7]    | PCR[23] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[23]<br>—<br>—<br>—<br>ADC1_P[3]                             | SIUL<br>—<br>—<br>—<br>ADC                       | I<br>—<br>—<br>—<br>I        | I        | Tristate            | 37         | 55      |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup> | Function                | Peripheral | I/O direction <sup>(2)</sup> | Pad type | RESET configuration | Pin number |         |
|----------|---------|-----------------------------------|-------------------------|------------|------------------------------|----------|---------------------|------------|---------|
|          |         |                                   |                         |            |                              |          |                     | LQFP64     | LQFP100 |
| PB[8]    | PCR[24] | AF0                               | GPIO[24]                | SIUL       | I                            | I        | Tristate            | 30         | 39      |
|          |         | AF1                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —                       | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[4]               | ADC        | I                            |          |                     |            |         |
|          |         | —                                 | WKPU[25] <sup>(3)</sup> | WKPU       | I                            |          |                     |            |         |
| PB[9]    | PCR[25] | AF0                               | GPIO[25]                | SIUL       | I                            | I        | Tristate            | 29         | 38      |
|          |         | AF1                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —                       | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[5]               | ADC        | I                            |          |                     |            |         |
|          |         | —                                 | WKPU[26] <sup>(3)</sup> | WKPU       | I                            |          |                     |            |         |
| PB[10]   | PCR[26] | AF0                               | GPIO[26]                | SIUL       | I/O                          | J        | Tristate            | 31         | 40      |
|          |         | AF1                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —                       | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[6]               | ADC        | I                            |          |                     |            |         |
|          |         | —                                 | WKPU[8] <sup>(3)</sup>  | WKPU       | I                            |          |                     |            |         |
| PB[11]   | PCR[27] | AF0                               | GPIO[27]                | SIUL       | I/O                          | J        | Tristate            | 38         | 59      |
|          |         | AF1                               | E0UC[3]                 | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | CS0_0                   | DSPI_0     | I/O                          |          |                     |            |         |
|          |         | —                                 | ADC1_S[12]              | ADC        | I                            |          |                     |            |         |
| PB[12]   | PCR[28] | AF0                               | GPIO[28]                | SIUL       | I/O                          | J        | Tristate            | 39         | 61      |
|          |         | AF1                               | E0UC[4]                 | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | CS1_0                   | DSPI_0     | O                            |          |                     |            |         |
|          |         | —                                 | ADC1_X[0]               | ADC        | I                            |          |                     |            |         |
| PB[13]   | PCR[29] | AF0                               | GPIO[29]                | SIUL       | I/O                          | J        | Tristate            | 40         | 63      |
|          |         | AF1                               | E0UC[5]                 | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | CS2_0                   | DSPI_0     | O                            |          |                     |            |         |
|          |         | —                                 | ADC1_X[1]               | ADC        | I                            |          |                     |            |         |
| PB[14]   | PCR[30] | AF0                               | GPIO[30]                | SIUL       | I/O                          | J        | Tristate            | 41         | 65      |
|          |         | AF1                               | E0UC[6]                 | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF2                               | —                       | —          | —                            |          |                     |            |         |
|          |         | AF3                               | CS3_0                   | DSPI_0     | O                            |          |                     |            |         |
|          |         | —                                 | ADC1_X[2]               | ADC        | I                            |          |                     |            |         |



Table 6. Functional port pin descriptions (continued)

| Port pin             | PCR     | Alternate function <sup>(1)</sup>  | Function                                       | Peripheral                            | I/O direction <sup>(2)</sup> | Pad type | RESET configuration       | Pin number |         |
|----------------------|---------|------------------------------------|------------------------------------------------|---------------------------------------|------------------------------|----------|---------------------------|------------|---------|
|                      |         |                                    |                                                |                                       |                              |          |                           | LQFP64     | LQFP100 |
| PB[15]               | PCR[31] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[31]<br>E0UC[7]<br>—<br>CS4_0<br>ADC1_X[3] | SIUL<br>eMIOS_0<br>—<br>DSPI_0<br>ADC | I/O<br>I/O<br>—<br>O<br>I    | J        | Tristate                  | 42         | 67      |
| <b>Port C</b>        |         |                                    |                                                |                                       |                              |          |                           |            |         |
| PC[0] <sup>(6)</sup> | PCR[32] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[32]<br>—<br>TDI<br>—                      | SIUL<br>—<br>JTAGC<br>—               | I/O<br>—<br>I<br>—           | M        | Input,<br>weak<br>pull-up | 59         | 87      |
| PC[1] <sup>(6)</sup> | PCR[33] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[33]<br>—<br>TDO<br>—                      | SIUL<br>—<br>JTAGC<br>—               | I/O<br>—<br>O<br>—           | F        | Tristate                  | 54         | 82      |
| PC[2]                | PCR[34] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[34]<br>SCK_1<br>—<br>—<br>EIRQ[5]         | SIUL<br>DSPI_1<br>—<br>—<br>SIUL      | I/O<br>I/O<br>—<br>—<br>I    | M        | Tristate                  | 50         | 78      |
| PC[3]                | PCR[35] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[35]<br>CS0_1<br>MA[0]<br>—<br>EIRQ[6]     | SIUL<br>DSPI_1<br>ADC<br>—<br>SIUL    | I/O<br>I/O<br>O<br>—<br>I    | S        | Tristate                  | 49         | 77      |
| PC[4]                | PCR[36] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[36]<br>—<br>—<br>—<br>SIN_1<br>EIRQ[18]   | SIUL<br>—<br>—<br>—<br>DSPI_1<br>SIUL | I/O<br>—<br>—<br>—<br>I<br>I | M        | Tristate                  | 62         | 92      |
| PC[5]                | PCR[37] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[37]<br>SOUT_1<br>—<br>—<br>EIRQ[7]        | SIUL<br>DSPI_1<br>—<br>—<br>SIUL      | I/O<br>O<br>—<br>—<br>I      | M        | Tristate                  | 61         | 91      |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup>  | Function                                                           | Peripheral                                     | I/O direction <sup>(2)</sup>   | Pad type | RESET configuration | Pin number |         |
|----------|---------|------------------------------------|--------------------------------------------------------------------|------------------------------------------------|--------------------------------|----------|---------------------|------------|---------|
|          |         |                                    |                                                                    |                                                |                                |          |                     | LQFP64     | LQFP100 |
| PC[6]    | PCR[38] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[38]<br>LIN1TX<br>—<br>—                                       | SIUL<br>LINFlex_1<br>—<br>—                    | I/O<br>O<br>—<br>—             | S        | Tristate            | 16         | 25      |
| PC[7]    | PCR[39] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[39]<br>—<br>—<br>—<br>LIN1RX<br>WKPU[12] <sup>(3)</sup>       | SIUL<br>—<br>—<br>—<br>LINFlex_1<br>WKPU       | I/O<br>—<br>—<br>—<br>I<br>I   | S        | Tristate            | 17         | 26      |
| PC[8]    | PCR[40] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[40]<br>LIN2TX<br>E0UC[3]<br>—                                 | SIUL<br>LINFlex_2<br>eMIOS_0<br>—              | I/O<br>O<br>I/O<br>—           | S        | Tristate            | 63         | 99      |
| PC[9]    | PCR[41] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[41]<br>—<br>E0UC[7]<br>—<br>LIN2RX<br>WKPU[13] <sup>(3)</sup> | SIUL<br>—<br>eMIOS_0<br>—<br>LINFlex_2<br>WKPU | I/O<br>—<br>I/O<br>—<br>I<br>I | S        | Tristate            | 2          | 2       |
| PC[10]   | PCR[42] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[42]<br>—<br>—<br>MA[1]                                        | SIUL<br>—<br>—<br>ADC                          | I/O<br>—<br>—<br>O             | M        | Tristate            | 13         | 22      |
| PC[11]   | PCR[43] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[43]<br>—<br>—<br>MA[2]<br>WKPU[5] <sup>(3)</sup>              | SIUL<br>—<br>—<br>ADC<br>WKPU                  | I/O<br>—<br>—<br>O<br>I        | S        | Tristate            | —          | 21      |
| PC[12]   | PCR[44] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[44]<br>E0UC[12]<br>—<br>—<br>EIRQ[19]                         | SIUL<br>eMIOS_0<br>—<br>—<br>SIUL              | I/O<br>I/O<br>—<br>—<br>I      | M        | Tristate            | —          | 97      |
| PC[13]   | PCR[45] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[45]<br>E0UC[13]<br>—<br>—                                     | SIUL<br>eMIOS_0<br>—<br>—                      | I/O<br>I/O<br>—<br>—           | S        | Tristate            | —          | 98      |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup>  | Function                                                        | Peripheral                         | I/O direction <sup>(2)</sup> | Pad type | RESET configuration | Pin number |         |
|----------|---------|------------------------------------|-----------------------------------------------------------------|------------------------------------|------------------------------|----------|---------------------|------------|---------|
|          |         |                                    |                                                                 |                                    |                              |          |                     | LQFP64     | LQFP100 |
| PC[14]   | PCR[46] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[46]<br>E0UC[14]<br>—<br>—<br>EIRQ[8]                       | SIUL<br>eMIOS_0<br>—<br>—<br>SIUL  | I/O<br>I/O<br>—<br>—<br>I    | S        | Tristate            | —          | 3       |
| PC[15]   | PCR[47] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[47]<br>E0UC[15]<br>—<br>—<br>EIRQ[20]                      | SIUL<br>eMIOS_0<br>—<br>—<br>SIUL  | I/O<br>I/O<br>—<br>—<br>I    | M        | Tristate            | —          | 4       |
| Port D   |         |                                    |                                                                 |                                    |                              |          |                     |            |         |
| PD[0]    | PCR[48] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[48]<br>—<br>—<br>—<br>WKPU[27] <sup>(3)</sup><br>ADC1_P[4] | SIUL<br>—<br>—<br>—<br>WKPU<br>ADC | I<br>—<br>—<br>—<br>I<br>I   | I        | Tristate            | —          | 41      |
| PD[1]    | PCR[49] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[49]<br>—<br>—<br>—<br>WKPU[28] <sup>(3)</sup><br>ADC1_P[5] | SIUL<br>—<br>—<br>—<br>WKPU<br>ADC | I<br>—<br>—<br>—<br>I<br>I   | I        | Tristate            | —          | 42      |
| PD[2]    | PCR[50] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[50]<br>—<br>—<br>—<br>ADC1_P[6]                            | SIUL<br>—<br>—<br>—<br>ADC         | I<br>—<br>—<br>—<br>I        | I        | Tristate            | —          | 43      |
| PD[3]    | PCR[51] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[51]<br>—<br>—<br>—<br>ADC1_P[7]                            | SIUL<br>—<br>—<br>—<br>ADC         | I<br>—<br>—<br>—<br>I        | I        | Tristate            | —          | 44      |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup> | Function   | Peripheral | I/O direction <sup>(2)</sup> | Pad type | RESET configuration | Pin number |         |
|----------|---------|-----------------------------------|------------|------------|------------------------------|----------|---------------------|------------|---------|
|          |         |                                   |            |            |                              |          |                     | LQFP64     | LQFP100 |
| PD[4]    | PCR[52] | AF0                               | GPIO[52]   | SIUL       | I                            | I        | Tristate            | —          | 45      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[8]  | ADC        | I                            |          |                     |            |         |
| PD[5]    | PCR[53] | AF0                               | GPIO[53]   | SIUL       | I                            | I        | Tristate            | —          | 46      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[9]  | ADC        | I                            |          |                     |            |         |
| PD[6]    | PCR[54] | AF0                               | GPIO[54]   | SIUL       | I                            | I        | Tristate            | —          | 47      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[10] | ADC        | I                            |          |                     |            |         |
| PD[7]    | PCR[55] | AF0                               | GPIO[55]   | SIUL       | I                            | I        | Tristate            | —          | 48      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[11] | ADC        | I                            |          |                     |            |         |
| PD[8]    | PCR[56] | AF0                               | GPIO[56]   | SIUL       | I                            | I        | Tristate            | —          | 49      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[12] | ADC        | I                            |          |                     |            |         |
| PD[9]    | PCR[57] | AF0                               | GPIO[57]   | SIUL       | I                            | I        | Tristate            | —          | 56      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[13] | ADC        | I                            |          |                     |            |         |
| PD[10]   | PCR[58] | AF0                               | GPIO[58]   | SIUL       | I                            | I        | Tristate            | —          | 57      |
|          |         | AF1                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —          | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —          | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[14] | ADC        | I                            |          |                     |            |         |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup> | Function               | Peripheral | I/O direction <sup>(2)</sup> | Pad type | RESET configuration | Pin number |         |
|----------|---------|-----------------------------------|------------------------|------------|------------------------------|----------|---------------------|------------|---------|
|          |         |                                   |                        |            |                              |          |                     | LQFP64     | LQFP100 |
| PD[11]   | PCR[59] | AF0                               | GPIO[59]               | SIUL       | I                            | I        | Tristate            | —          | 58      |
|          |         | AF1                               | —                      | —          | —                            |          |                     |            |         |
|          |         | AF2                               | —                      | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_P[15]             | ADC        | I                            |          |                     |            |         |
| PD[12]   | PCR[60] | AF0                               | GPIO[60]               | SIUL       | I/O                          | J        | Tristate            | —          | 60      |
|          |         | AF1                               | CS5_0                  | DSPI_0     | O                            |          |                     |            |         |
|          |         | AF2                               | E0UC[24]               | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[8]              | ADC        | I                            |          |                     |            |         |
| PD[13]   | PCR[61] | AF0                               | GPIO[61]               | SIUL       | I/O                          | J        | Tristate            | —          | 62      |
|          |         | AF1                               | CS0_1                  | DSPI_1     | I/O                          |          |                     |            |         |
|          |         | AF2                               | E0UC[25]               | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[9]              | ADC        | I                            |          |                     |            |         |
| PD[14]   | PCR[62] | AF0                               | GPIO[62]               | SIUL       | I/O                          | J        | Tristate            | —          | 64      |
|          |         | AF1                               | CS1_1                  | DSPI_1     | O                            |          |                     |            |         |
|          |         | AF2                               | E0UC[26]               | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[10]             | ADC        | I                            |          |                     |            |         |
| PD[15]   | PCR[63] | AF0                               | GPIO[63]               | SIUL       | I/O                          | J        | Tristate            | —          | 66      |
|          |         | AF1                               | CS2_1                  | DSPI_1     | O                            |          |                     |            |         |
|          |         | AF2                               | E0UC[27]               | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         | —                                 | ADC1_S[11]             | ADC        | I                            |          |                     |            |         |
| Port E   |         |                                   |                        |            |                              |          |                     |            |         |
| PE[0]    | PCR[64] | AF0                               | GPIO[64]               | SIUL       | I/O                          | S        | Tristate            | —          | 6       |
|          |         | AF1                               | E0UC[16]               | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF2                               | —                      | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         | —                                 | WKPU[6] <sup>(3)</sup> | WKPU       | I                            |          |                     |            |         |
| PE[1]    | PCR[65] | AF0                               | GPIO[65]               | SIUL       | I/O                          | M        | Tristate            | —          | 8       |
|          |         | AF1                               | E0UC[17]               | eMIOS_0    | I/O                          |          |                     |            |         |
|          |         | AF2                               | —                      | —          | —                            |          |                     |            |         |
|          |         | AF3                               | —                      | —          | —                            |          |                     |            |         |
|          |         |                                   |                        |            |                              |          |                     |            |         |

Table 6. Functional port pin descriptions (continued)

| Port pin | PCR     | Alternate function <sup>(1)</sup>  | Function                                                 | Peripheral                                  | I/O direction <sup>(2)</sup>   | Pad type | RESET configuration | Pin number |         |
|----------|---------|------------------------------------|----------------------------------------------------------|---------------------------------------------|--------------------------------|----------|---------------------|------------|---------|
|          |         |                                    |                                                          |                                             |                                |          |                     | LQFP64     | LQFP100 |
| PE[2]    | PCR[66] | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[66]<br>E0UC[18]<br>—<br>—<br>EIRQ[21]<br>SIN_1      | SIUL<br>eMIOS_0<br>—<br>—<br>SIUL<br>DSPI_1 | I/O<br>I/O<br>—<br>—<br>I<br>I | M        | Tristate            | —          | 89      |
| PE[3]    | PCR[67] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[67]<br>E0UC[19]<br>SOUT_1<br>—                      | SIUL<br>eMIOS_0<br>DSPI_1<br>—              | I/O<br>I/O<br>O<br>—           | M        | Tristate            | —          | 90      |
| PE[4]    | PCR[68] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[68]<br>E0UC[20]<br>SCK_1<br>—<br>EIRQ[9]            | SIUL<br>eMIOS_0<br>DSPI_1<br>—<br>SIUL      | I/O<br>I/O<br>I/O<br>—<br>I    | M        | Tristate            | —          | 93      |
| PE[5]    | PCR[69] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[69]<br>E0UC[21]<br>CS0_1<br>MA[2]                   | SIUL<br>eMIOS_0<br>DSPI_1<br>ADC            | I/O<br>I/O<br>I/O<br>O         | M        | Tristate            | —          | 94      |
| PE[6]    | PCR[70] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[70]<br>E0UC[22]<br>CS3_0<br>MA[1]<br>EIRQ[22]       | SIUL<br>eMIOS_0<br>DSPI_0<br>ADC<br>SIUL    | I/O<br>I/O<br>O<br>O<br>I      | M        | Tristate            | —          | 95      |
| PE[7]    | PCR[71] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[71]<br>E0UC[23]<br>CS2_0<br>MA[0]<br>EIRQ[23]       | SIUL<br>eMIOS_0<br>DSPI_0<br>ADC<br>SIUL    | I/O<br>I/O<br>O<br>O<br>I      | M        | Tristate            | —          | 96      |
| PE[8]    | PCR[72] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[72]<br>—<br>E0UC[22]<br>—                           | SIUL<br>—<br>eMIOS_0<br>—                   | I/O<br>—<br>I/O<br>—           | M        | Tristate            | —          | 9       |
| PE[9]    | PCR[73] | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[73]<br>—<br>E0UC[23]<br>—<br>WKPU[7] <sup>(3)</sup> | SIUL<br>—<br>eMIOS_0<br>—<br>WKPU           | I/O<br>—<br>I/O<br>—<br>I      | S        | Tristate            | —          | 10      |

Table 6. Functional port pin descriptions (continued)

| Port pin              | PCR      | Alternate function <sup>(1)</sup>  | Function                                                      | Peripheral                             | I/O direction <sup>(2)</sup> | Pad type | RESET configuration | Pin number |         |
|-----------------------|----------|------------------------------------|---------------------------------------------------------------|----------------------------------------|------------------------------|----------|---------------------|------------|---------|
|                       |          |                                    |                                                               |                                        |                              |          |                     | LQFP64     | LQFP100 |
| PE[10]                | PCR[74]  | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[74]<br>—<br>CS3_1<br>—<br>EIRQ[10]                       | SIUL<br>—<br>DSPI_1<br>—<br>SIUL       | I/O<br>—<br>O<br>—<br>I      | S        | Tristate            | —          | 11      |
| PE[11]                | PCR[75]  | AF0<br>AF1<br>AF2<br>AF3<br>—      | GPIO[75]<br>E0UC[24]<br>CS4_1<br>—<br>WKPU[14] <sup>(3)</sup> | SIUL<br>eMIOS_0<br>DSPI_1<br>—<br>WKPU | I/O<br>I/O<br>O<br>—<br>I    | S        | Tristate            | —          | 13      |
| PE[12]                | PCR[76]  | AF0<br>AF1<br>AF2<br>AF3<br>—<br>— | GPIO[76]<br>—<br>—<br>—<br>ADC1_S[7]<br>EIRQ[11]              | SIUL<br>—<br>—<br>—<br>ADC<br>SIUL     | I/O<br>—<br>—<br>—<br>I<br>I | S        | Tristate            | —          | 76      |
| <b>Port H</b>         |          |                                    |                                                               |                                        |                              |          |                     |            |         |
| PH[9] <sup>(6)</sup>  | PCR[121] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[121]<br>—<br>TCK<br>—                                    | SIUL<br>—<br>JTAGC<br>—                | I/O<br>—<br>I<br>—           | S        | Input, weak pull-up | 60         | 88      |
| PH[10] <sup>(6)</sup> | PCR[122] | AF0<br>AF1<br>AF2<br>AF3           | GPIO[122]<br>—<br>TMS<br>—                                    | SIUL<br>—<br>JTAGC<br>—                | I/O<br>—<br>I<br>—           | S        | Input, weak pull-up | 53         | 81      |

1. Alternate functions are chosen by setting the values of the PCR.PA bitfields inside the SIUL module. PCR.PA = 00 @ AF0; PCR.PA = 01 @ AF1; PCR.PA = 10 @ AF2; PCR.PA = 11 @ AF3. This is intended to select the output functions; to use one of the input functions, the PCR.IBE bit must be written to '1', regardless of the values selected in the PCR.PA bitfields. For this reason, the value corresponding to an input only function is reported as "—".
2. Multiple inputs are routed to all respective modules internally. The input of some modules must be configured by setting the values of the PSMIO.PADSELx bitfields inside the SIUL module.
3. All WKPU pins also support external interrupt capability. See "wake-up unit" chapter of the device reference manual for further details.
4. NMI has higher priority than alternate function. When NMI is selected, the PCR.AF field is ignored.
5. "Not applicable" because these functions are available only while the device is booting. Refer to "BAM" chapter of the device reference manual for details.
6. Out of reset all the functional pins except PC[0:1] and PH[9:10] are available to the user as GPIO. PC[0:1] are available as JTAG pins (TDI and TDO respectively). PH[9:10] are available as JTAG pins (TCK and TMS respectively). If the user configures these JTAG pins in GPIO mode the device is no longer compliant with IEEE 1149.1 2001.

## 4 Electrical characteristics

### 4.1 Introduction

This section contains electrical characteristics of the device as well as temperature and power considerations.

This product contains devices to protect the inputs against damage due to high static voltages. However, it is advisable to take precautions to avoid application of any voltage higher than the specified maximum rated voltages.

To enhance reliability, unused inputs can be driven to an appropriate logic voltage level ( $V_{DD}$  or  $V_{SS}$ ). This can be done by the internal pull-up or pull-down, which is provided by the product for most general purpose pins.

The parameters listed in the following tables represent the characteristics of the device and its demands on the system.

In the tables where the device logic provides signals with their respective timing characteristics, the symbol “CC” for Controller Characteristics is included in the Symbol column.

In the tables where the external system must provide signals with their respective timing characteristics to the device, the symbol “SR” is for System Requirement is included in the Symbol column.

### 4.2 Parameter classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding, the classifications listed in [Table 7](#) are used and the parameters are tagged accordingly in the tables where appropriate.

**Table 7. Parameter classifications**

| Classification tag | Tag description                                                                                                                                                                                                        |
|--------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| P                  | Those parameters are guaranteed during production testing on each individual device.                                                                                                                                   |
| C                  | Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.                                                                              |
| T                  | Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category. |
| D                  | Those parameters are derived mainly from simulations.                                                                                                                                                                  |

*Note:* The classification is shown in the column labeled “C” in the parameter tables where appropriate.



## 4.3 NVUSRO register

Bit values in the Non-Volatile User Options (NVUSRO) Register control portions of the device configuration, namely electrical parameters such as high voltage supply and oscillator margin, as well as digital functionality (watchdog enable/disable after reset).

For a detailed description of the NVUSRO register, refer to the device reference manual.

### 4.3.1 NVUSRO[PAD3V5V] field description

The DC electrical characteristics are dependent on the PAD3V5V bit value. [Table 8](#) shows how NVUSRO[PAD3V5V] controls the device configuration.

**Table 8. PAD3V5V field description**

| Value <sup>(1)</sup> | Description                  |
|----------------------|------------------------------|
| 0                    | High voltage supply is 5.0 V |
| 1                    | High voltage supply is 3.3 V |

1. Default manufacturing value is '1'. Value can be programmed by customer in Shadow Flash.

### 4.3.2 NVUSRO[OSCILLATOR\_MARGIN] field description

The fast external crystal oscillator consumption is dependent on the OSCILLATOR\_MARGIN bit value. [Table 9](#) shows how NVUSRO[OSCILLATOR\_MARGIN] controls the device configuration.

**Table 9. OSCILLATOR\_MARGIN field description**

| Value <sup>(1)</sup> | Description                                 |
|----------------------|---------------------------------------------|
| 0                    | Low consumption configuration (4 MHz/8 MHz) |
| 1                    | High margin configuration (4 MHz/16 MHz)    |

1. Default manufacturing value is '1'. Value can be programmed by customer in Shadow Flash.

### 4.3.3 NVUSRO[WATCHDOG\_EN] field description

The watchdog enable/disable configuration after reset is dependent on the WATCHDOG\_EN bit value. [Table 10](#) shows how NVUSRO[WATCHDOG\_EN] controls the device configuration.

**Table 10. WATCHDOG\_EN field description**

| Value <sup>(1)</sup> | Description         |
|----------------------|---------------------|
| 0                    | Disable after reset |
| 1                    | Enable after reset  |

1. Default manufacturing value is '1'. Value can be programmed by customer in Shadow Flash.

## 4.4 Absolute maximum ratings

Table 11. Absolute maximum ratings

| Symbol               |    | Parameter                                                                                     | Conditions                                    | Value                 |                       | Unit |
|----------------------|----|-----------------------------------------------------------------------------------------------|-----------------------------------------------|-----------------------|-----------------------|------|
|                      |    |                                                                                               |                                               | Min                   | Max                   |      |
| V <sub>SS</sub>      | SR | Digital ground on VSS_HV pins                                                                 | —                                             | 0                     | 0                     | V    |
| V <sub>DD</sub>      | SR | Voltage on VDD_HV pins with respect to ground (V <sub>SS</sub> )                              | —                                             | −0.3                  | 6.0                   | V    |
| V <sub>SS_LV</sub>   | SR | Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V <sub>SS</sub> ) | —                                             | V <sub>SS</sub> − 0.1 | V <sub>SS</sub> + 0.1 | V    |
| V <sub>DD_BV</sub>   | SR | Voltage on VDD_BV (regulator supply) pin with respect to ground (V <sub>SS</sub> )            | —                                             | −0.3                  | 6.0                   | V    |
|                      |    |                                                                                               | Relative to V <sub>DD</sub>                   | V <sub>DD</sub> − 0.3 | V <sub>DD</sub> + 0.3 |      |
| V <sub>SS_ADC</sub>  | SR | Voltage on VSS_HV_ADC (ADC reference) pin with respect to ground (V <sub>SS</sub> )           | —                                             | V <sub>SS</sub> − 0.1 | V <sub>SS</sub> + 0.1 | V    |
| V <sub>DD_ADC</sub>  | SR | Voltage on VDD_HV_ADC (ADC reference) pin with respect to ground (V <sub>SS</sub> )           | —                                             | −0.3                  | 6.0                   | V    |
|                      |    |                                                                                               | Relative to V <sub>DD</sub>                   | V <sub>DD</sub> − 0.3 | V <sub>DD</sub> + 0.3 |      |
| V <sub>IN</sub>      | SR | Voltage on any GPIO pin with respect to ground (V <sub>SS</sub> )                             | —                                             | −0.3                  | 6.0                   | V    |
|                      |    |                                                                                               | Relative to V <sub>DD</sub>                   | V <sub>DD</sub> − 0.3 | V <sub>DD</sub> + 0.3 |      |
| I <sub>INJPAD</sub>  | SR | Injected input current on any pin during overload condition                                   | —                                             | −10                   | 10                    | mA   |
| I <sub>INJSUM</sub>  | SR | Absolute sum of all injected input currents during overload condition                         | —                                             | −50                   | 50                    | mA   |
| I <sub>AVGSEG</sub>  | SR | Sum of all the static I/O current within a supply segment <sup>(1)</sup>                      | V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0 | —                     | 70                    | mA   |
|                      |    |                                                                                               | V <sub>DD</sub> = 3.3 V ± 10%,<br>PAD3V5V = 1 | —                     | 64                    |      |
| I <sub>CORELV</sub>  | SR | Low voltage static current sink through VDD_BV                                                | —                                             | —                     | 150                   | mA   |
| T <sub>STORAGE</sub> | SR | Storage temperature                                                                           | —                                             | −55                   | 150                   | °C   |

1. Supply segments are described in [Section 4.7.5: I/O pad current specification](#).

**Note:** Stresses exceeding the recommended absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. During overload conditions ( $V_{IN} > V_{DD}$  or  $V_{IN} < V_{SS}$ ), the voltage on pins with respect to ground (V<sub>SS</sub>) must not exceed the recommended values.

## 4.5 Recommended operating conditions

Table 12. Recommended operating conditions (3.3 V)

| Symbol                             |    | C | Parameter                                                                                     | Conditions                  | Value                 |                                        | Unit |
|------------------------------------|----|---|-----------------------------------------------------------------------------------------------|-----------------------------|-----------------------|----------------------------------------|------|
|                                    |    |   |                                                                                               |                             | Min                   | Max                                    |      |
| V <sub>SS</sub>                    | SR | — | Digital ground on VSS_HV pins                                                                 | —                           | 0                     | 0                                      | V    |
| V <sub>DD</sub> <sup>(1)</sup>     | SR | — | Voltage on VDD_HV pins with respect to ground (V <sub>SS</sub> )                              | —                           | 3.0                   | 3.6                                    | V    |
| V <sub>SS_LV</sub> <sup>(2)</sup>  | SR | — | Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V <sub>SS</sub> ) | —                           | V <sub>SS</sub> – 0.1 | V <sub>SS</sub> + 0.1                  | V    |
| V <sub>DD_BV</sub> <sup>(3)</sup>  | SR | — | Voltage on VDD_BV pin (regulator supply) with respect to ground (V <sub>SS</sub> )            | —                           | 3.0                   | 3.6                                    | V    |
|                                    |    |   |                                                                                               | Relative to V <sub>DD</sub> | V <sub>DD</sub> – 0.1 | V <sub>DD</sub> + 0.1                  |      |
| V <sub>SS_ADC</sub>                | SR | — | Voltage on VSS_HV_ADC (ADC reference) pin with respect to ground (V <sub>SS</sub> )           | —                           | V <sub>SS</sub> – 0.1 | V <sub>SS</sub> + 0.1                  | V    |
| V <sub>DD_ADC</sub> <sup>(4)</sup> | SR | — | Voltage on VDD_HV_ADC pin (ADC reference) with respect to ground (V <sub>SS</sub> )           | —                           | 3.0 <sup>(5)</sup>    | 3.6                                    | V    |
|                                    |    |   |                                                                                               | Relative to V <sub>DD</sub> | V <sub>DD</sub> – 0.1 | V <sub>DD</sub> + 0.1                  |      |
| V <sub>IN</sub>                    | SR | — | Voltage on any GPIO pin with respect to ground (V <sub>SS</sub> )                             | —                           | V <sub>SS</sub> – 0.1 | —                                      | V    |
|                                    |    |   |                                                                                               | Relative to V <sub>DD</sub> | —                     | V <sub>DD</sub> + 0.1                  |      |
| I <sub>INJPAD</sub>                | SR | — | Injected input current on any pin during overload condition                                   | —                           | –5                    | 5                                      | mA   |
| I <sub>INJSUM</sub>                | SR | — | Absolute sum of all injected input currents during overload condition                         | —                           | –50                   | 50                                     | mA   |
| TV <sub>DD</sub>                   | SR | — | V <sub>DD</sub> slope to ensure correct power up <sup>(6)</sup>                               | —                           | 3.0 <sup>(7)</sup>    | 250 x 10 <sup>3</sup><br>(0.25 [V/μs]) | V/s  |

1. 100 nF capacitance needs to be provided between each  $V_{DD}/V_{SS}$  pair.
2. 330 nF capacitance needs to be provided between each  $V_{DD\_LV}/V_{SS\_LV}$  supply pair.
3. 470 nF capacitance needs to be provided between  $V_{DD\_BV}$  and the nearest  $V_{SS\_LV}$  (higher value may be needed depending on external regulator characteristics).
4. 100 nF capacitance needs to be provided between  $V_{DD\_ADC}/V_{SS\_ADC}$  pair.
5. Full electrical specification cannot be guaranteed when voltage drops below 3.0 V. In particular, ADC electrical characteristics and I/Os DC electrical specification may not be guaranteed. When voltage drops below  $V_{LVDHVL}$ , device is reset.
6. Guaranteed by device validation.
7. Minimum value of  $TV_{DD}$  must be guaranteed until  $V_{DD}$  reaches 2.6 V (maximum value of  $V_{PORH}$ ).

Table 13. Recommended operating conditions (5.0 V)

| Symbol                             |    | C | Parameter                                                                                     | Conditions                  | Value                 |                                         | Unit |
|------------------------------------|----|---|-----------------------------------------------------------------------------------------------|-----------------------------|-----------------------|-----------------------------------------|------|
|                                    |    |   |                                                                                               |                             | Min                   | Max                                     |      |
| V <sub>SS</sub>                    | SR | — | Digital ground on VSS_HV pins                                                                 | —                           | 0                     | 0                                       | V    |
| V <sub>DD</sub> <sup>(1)</sup>     | SR | — | Voltage on VDD_HV pins with respect to ground (V <sub>SS</sub> )                              | —                           | 4.5                   | 5.5                                     | V    |
|                                    |    |   |                                                                                               | Voltage drop <sup>(2)</sup> | 3.0                   | 5.5                                     |      |
| V <sub>SS_LV</sub> <sup>(3)</sup>  | SR | — | Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V <sub>SS</sub> ) | —                           | V <sub>SS</sub> – 0.1 | V <sub>SS</sub> + 0.1                   | V    |
| V <sub>DD_BV</sub> <sup>(4)</sup>  | SR | — | Voltage on VDD_BV pin (regulator supply) with respect to ground (V <sub>SS</sub> )            | —                           | 4.5                   | 5.5                                     | V    |
|                                    |    |   |                                                                                               | Voltage drop <sup>(2)</sup> | 3.0                   | 5.5                                     |      |
|                                    |    |   |                                                                                               | Relative to V <sub>DD</sub> | V <sub>DD</sub> – 0.1 | V <sub>DD</sub> + 0.1                   |      |
| V <sub>SS_ADC</sub>                | SR | — | Voltage on VSS_HV_ADC (ADC reference) pin with respect to ground (V <sub>SS</sub> )           | —                           | V <sub>SS</sub> – 0.1 | V <sub>SS</sub> + 0.1                   | V    |
| V <sub>DD_ADC</sub> <sup>(5)</sup> | SR | — | Voltage on VDD_HV_ADC pin (ADC reference) with respect to ground (V <sub>SS</sub> )           | —                           | 4.5                   | 5.5                                     | V    |
|                                    |    |   |                                                                                               | Voltage drop <sup>(2)</sup> | 3.0                   | 5.5                                     |      |
|                                    |    |   |                                                                                               | Relative to V <sub>DD</sub> | V <sub>DD</sub> – 0.1 | V <sub>DD</sub> + 0.1                   |      |
| V <sub>IN</sub>                    | SR | — | Voltage on any GPIO pin with respect to ground (V <sub>SS</sub> )                             | —                           | V <sub>SS</sub> – 0.1 | —                                       | V    |
|                                    |    |   |                                                                                               | Relative to V <sub>DD</sub> | —                     | V <sub>DD</sub> + 0.1                   |      |
| I <sub>INJPAD</sub>                | SR | — | Injected input current on any pin during overload condition                                   | —                           | –5                    | 5                                       | mA   |
| I <sub>INJSUM</sub>                | SR | — | Absolute sum of all injected input currents during overload condition                         | —                           | –50                   | 50                                      | mA   |
| TV <sub>DD</sub>                   | SR | — | V <sub>DD</sub> slope to ensure correct power up <sup>(6)</sup>                               | —                           | 3.0 <sup>(7)</sup>    | 250 x 10 <sup>3</sup><br>(0.25 [V/ μs]) | V/ s |

1. 100 nF capacitance needs to be provided between each  $V_{DD}/V_{SS}$  pair.
2. Full device operation is guaranteed by design when the voltage drops below 4.5 V down to 3.6 V. However, certain analog electrical characteristics will not be guaranteed to stay within the stated limits.
3. 330 nF capacitance needs to be provided between each  $V_{DD\_LV}/V_{SS\_LV}$  supply pair.
4. 470 nF capacitance needs to be provided between  $V_{DD\_BV}$  and the nearest  $V_{SS\_LV}$  (higher value may be needed depending on external regulator characteristics).
5. 100 nF capacitance needs to be provided between  $V_{DD\_ADC}/V_{SS\_ADC}$  pair.
6. Guaranteed by device validation.
7. Minimum value of  $TV_{DD}$  must be guaranteed until  $V_{DD}$  reaches 2.6 V (maximum value of  $V_{PORH}$ ).

**Note:** SRAM data retention is guaranteed with  $V_{DD\_LV}$  not below 1.08 V.

## 4.6 Thermal characteristics

### 4.6.1 Package thermal characteristics

Table 14. LQFP thermal characteristics

| Symbol           |    | C | Parameter                                                                 | Conditions <sup>(1)</sup> |         | Value | Unit |
|------------------|----|---|---------------------------------------------------------------------------|---------------------------|---------|-------|------|
| R <sub>θJA</sub> | CC | D | Thermal resistance, junction-to-ambient natural convection <sup>(2)</sup> | Single-layer board — 1s   | LQFP64  | 72.1  | °C/W |
|                  |    |   |                                                                           |                           | LQFP100 | 65.2  |      |
|                  |    |   |                                                                           | Four-layer board — 2s2p   | LQFP64  | 57.3  |      |
|                  |    |   |                                                                           |                           | LQFP100 | 51.8  |      |
| R <sub>θJB</sub> | CC | D | Thermal resistance, junction-to-board <sup>(3)</sup>                      | Four-layer board — 2s2p   | LQFP64  | 44.1  | °C/W |
|                  |    |   |                                                                           |                           | LQFP100 | 41.3  |      |
| R <sub>θJC</sub> | CC | D | Thermal resistance, junction-to-case <sup>(4)</sup>                       | Single-layer board — 1s   | LQFP64  | 26.5  | °C/W |
|                  |    |   |                                                                           |                           | LQFP100 | 23.9  |      |
|                  |    |   |                                                                           | Four-layer board — 2s2p   | LQFP64  | 26.2  |      |
|                  |    |   |                                                                           |                           | LQFP100 | 23.7  |      |
| Ψ <sub>JB</sub>  | CC | D | Junction-to-board thermal characterization parameter, natural convection  | Single-layer board — 1s   | LQFP64  | 41    | °C/W |
|                  |    |   |                                                                           |                           | LQFP100 | 41.6  |      |
|                  |    |   |                                                                           | Four-layer board — 2s2p   | LQFP64  | 43    |      |
|                  |    |   |                                                                           |                           | LQFP100 | 43.4  |      |
| Ψ <sub>JC</sub>  | CC | D | Junction-to-case thermal characterization parameter, natural convection   | Single-layer board — 1s   | LQFP64  | 11.5  | °C/W |
|                  |    |   |                                                                           |                           | LQFP100 | 10.4  |      |
|                  |    |   |                                                                           | Four-layer board — 2s2p   | LQFP64  | 11.1  |      |
|                  |    |   |                                                                           |                           | LQFP100 | 10.2  |      |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^{\circ}\text{C}$

2. Junction-to-ambient thermal resistance determined per JEDEC JESD51-3 and JESD51-7. Thermal test board meets JEDEC specification for this package. When Greek letters are not available, the symbols are typed as  $R_{thJA}$ .

3. Junction-to-board thermal resistance determined per JEDEC JESD51-8. Thermal test board meets JEDEC specification for the specified package. When Greek letters are not available, the symbols are typed as  $R_{thJB}$ .

4. Junction-to-case at the top of the package determined using MIL-STD 883 Method 1012.1. The cold plate temperature is used for the case temperature. Reported value includes the thermal resistance of the interface layer. When Greek letters are not available, the symbols are typed as  $R_{thJC}$ .

**Note:** Thermal characteristics are targets based on simulation that are subject to change per device characterization.

### 4.6.2 Power considerations

The average chip-junction temperature,  $T_J$ , in degrees Celsius, may be calculated using [Equation 1](#):

$$\text{Equation 1 } T_J = T_A + (P_D \times R_{\theta JA})$$

Where:

$T_A$  is the ambient temperature in °C.

$R_{\theta JA}$  is the package junction-to-ambient thermal resistance, in °C/W.

$P_D$  is the sum of  $P_{INT}$  and  $P_{I/O}$  ( $P_D = P_{INT} + P_{I/O}$ ).

$P_{INT}$  is the product of  $I_{DD}$  and  $V_{DD}$ , expressed in watts. This is the chip internal power.

$P_{I/O}$  represents the power dissipation on input and output pins; user determined.

Most of the time for the applications,  $P_{I/O} < P_{INT}$  and may be neglected. On the other hand,  $P_{I/O}$  may be significant, if the device is configured to continuously drive external modules and/or memories.

An approximate relationship between  $P_D$  and  $T_J$  (if  $P_{I/O}$  is neglected) is given by:

$$\text{Equation 2 } P_D = K / (T_J + 273 \text{ °C})$$

Therefore, solving equations 1 and 2:

$$\text{Equation 3 } K = P_D \times (T_A + 273 \text{ °C}) + R_{\theta JA} \times P_D^2$$

Where:

$K$  is a constant for the particular part, which may be determined from [Equation 3](#) by measuring  $P_D$  (at equilibrium) for a known  $T_A$ . Using this value of  $K$ , the values of  $P_D$  and  $T_J$  may be obtained by solving equations 1 and 2 iteratively for any value of  $T_A$ .

## 4.7 I/O pad electrical characteristics

### 4.7.1 I/O pad types

The device provides four main I/O pad types depending on the associated alternate functions:

- Slow pads — These pads are the most common pads, providing a good compromise between transition time and low electromagnetic emission.
- Medium pads — These pads provide transition fast enough for the serial communication channels with controlled current to reduce electromagnetic emission.
- Input only pads — These pads are associated to ADC channels (ADC\_P[X]) providing low input leakage.

Medium pads can use slow configuration to reduce electromagnetic emission except for PC[1], that is medium only, at the cost of reducing AC performance.

### 4.7.2 I/O input DC characteristics

[Table 15](#) provides input DC electrical characteristics as described in [Figure 4](#).

Figure 4. Input DC electrical characteristics definition

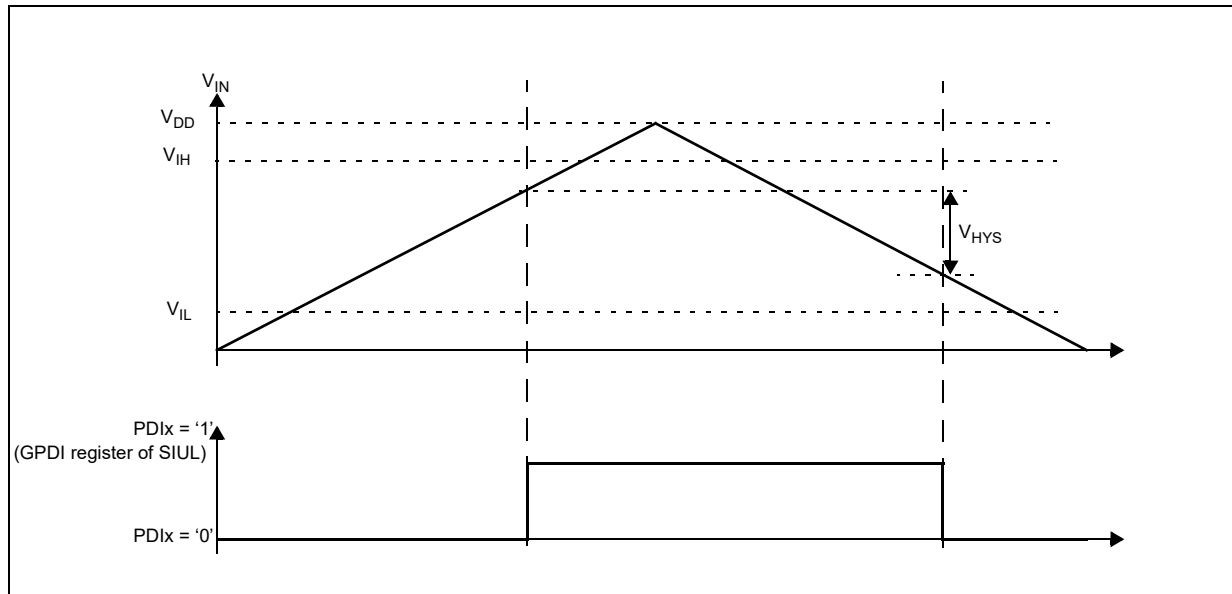


Table 15. I/O input DC electrical characteristics

| Symbol          | C  | Parameter | Conditions <sup>(1)</sup>               | Value                 |     |              | Unit |
|-----------------|----|-----------|-----------------------------------------|-----------------------|-----|--------------|------|
|                 |    |           |                                         | Min                   | Typ | Max          |      |
| $V_{IH}$        | SR | P         | Input high level CMOS (Schmitt Trigger) | —                     | —   | $0.65V_{DD}$ | V    |
| $V_{IL}$        | SR | P         | Input low level CMOS (Schmitt Trigger)  | —                     | —   | $0.35V_{DD}$ | V    |
| $V_{HYS}$       | CC | C         | Input hysteresis CMOS (Schmitt Trigger) | —                     | —   | $0.1V_{DD}$  | V    |
| $I_{LKG}$       | CC | D         | No injection on adjacent pin            | $T_A = -40\text{ °C}$ | —   | 2            | 200  |
|                 |    | D         |                                         | $T_A = 25\text{ °C}$  | —   | 2            | 200  |
|                 |    | D         |                                         | $T_A = 85\text{ °C}$  | —   | 5            | 300  |
|                 |    | D         |                                         | $T_A = 105\text{ °C}$ | —   | 12           | 500  |
|                 |    | P         |                                         | $T_A = 125\text{ °C}$ | —   | 70           | 1000 |
| $W_{FI}^{(2)}$  | SR | P         | Digital input filtered pulse            | —                     | —   | 40           | ns   |
| $W_{NFI}^{(2)}$ | SR | P         | Digital input not filtered pulse        | —                     | —   | —            | ns   |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40\text{ to }125\text{ °C}$ , unless otherwise specified.

2. In the range from 40 to 1000 ns, pulses can be filtered or not filtered, according to the operating temperature and voltage.

### 4.7.3 I/O output DC characteristics

The following tables provide DC characteristics for bidirectional pads:

- [Table 16](#) provides weak pull figures. Both pull-up and pull-down resistances are supported.
- [Table 17](#) provides output driver characteristics for I/O pads when in SLOW configuration.
- [Table 18](#) provides output driver characteristics for I/O pads when in MEDIUM configuration.

**Table 16. I/O pull-up/pull-down DC electrical characteristics**

| Symbol           |    | C                          | Parameter                                | Conditions <sup>(1)</sup>                                         |             | Value |     |     | Unit |
|------------------|----|----------------------------|------------------------------------------|-------------------------------------------------------------------|-------------|-------|-----|-----|------|
|                  |    |                            |                                          |                                                                   |             | Min   | Typ | Max |      |
| I <sub>WPU</sub> | CC | P                          | Weak pull-up current<br>absolute value   | V <sub>IN</sub> = V <sub>IL</sub> , V <sub>DD</sub> = 5.0 V ± 10% | PAD3V5V = 0 | 10    | —   | 150 | μA   |
|                  |    | PAD3V5V = 1 <sup>(2)</sup> |                                          |                                                                   | 10          | —     | 250 |     |      |
|                  |    | P                          |                                          | V <sub>IN</sub> = V <sub>IL</sub> , V <sub>DD</sub> = 3.3 V ± 10% | PAD3V5V = 1 | 10    | —   | 150 |      |
| I <sub>WPD</sub> | CC | P                          | Weak pull-down current<br>absolute value | V <sub>IN</sub> = V <sub>IH</sub> , V <sub>DD</sub> = 5.0 V ± 10% | PAD3V5V = 0 | 10    | —   | 150 | μA   |
|                  |    | PAD3V5V = 1 <sup>(2)</sup> |                                          |                                                                   | 10          | —     | 250 |     |      |
|                  |    | P                          |                                          | V <sub>IN</sub> = V <sub>IH</sub> , V <sub>DD</sub> = 3.3 V ± 10% | PAD3V5V = 1 | 10    | —   | 150 |      |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

2. The configuration PAD3V5 = 1 when V<sub>DD</sub> = 5 V is only a transient configuration during power-up. All pads but RESET are configured in input or in high impedance state.

**Table 17. SLOW configuration output buffer electrical characteristics**

| Symbol          |    | C | Parameter                            | Conditions <sup>(1)</sup> |                                                                                    | Value                 |     |                    | Unit |
|-----------------|----|---|--------------------------------------|---------------------------|------------------------------------------------------------------------------------|-----------------------|-----|--------------------|------|
|                 |    |   |                                      |                           |                                                                                    | Min                   | Typ | Max                |      |
| V <sub>OH</sub> | CC | P | Output high level SLOW configuration | Push Pull                 | I <sub>OH</sub> = −2 mA, V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 (recommended)  | 0.8V <sub>DD</sub>    | —   | —                  | V    |
|                 |    | C |                                      |                           | I <sub>OH</sub> = −2 mA, V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 1 <sup>(2)</sup> | 0.8V <sub>DD</sub>    | —   | —                  |      |
|                 |    | C |                                      |                           | I <sub>OH</sub> = −1 mA, V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 (recommended)  | V <sub>DD</sub> − 0.8 | —   | —                  |      |
| V <sub>OL</sub> | CC | P | Output low level SLOW configuration  | Push Pull                 | I <sub>OL</sub> = 2 mA, V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 (recommended)   | —                     | —   | 0.1V <sub>DD</sub> | V    |
|                 |    | C |                                      |                           | I <sub>OL</sub> = 2 mA, V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 1 <sup>(2)</sup>  | —                     | —   | 0.1V <sub>DD</sub> |      |
|                 |    | C |                                      |                           | I <sub>OL</sub> = 1 mA, V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 (recommended)   | —                     | —   | 0.5                |      |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.



2. The configuration PAD3V5 = 1 when  $V_{DD} = 5\text{ V}$  is only a transient configuration during power-up. All pads but RESET are configured in input or in high impedance state.

Table 18. MEDIUM configuration output buffer electrical characteristics

| Symbol   | C  | Parameter                                 | Conditions <sup>(1)</sup> | Value                                                                                      |                |             | Unit |
|----------|----|-------------------------------------------|---------------------------|--------------------------------------------------------------------------------------------|----------------|-------------|------|
|          |    |                                           |                           | Min                                                                                        | Typ            | Max         |      |
| $V_{OH}$ | CC | Output high level<br>MEDIUM configuration | Push Pull                 | $I_{OH} = -3.8\text{ mA}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 0              | $0.8V_{DD}$    | —           | V    |
|          |    |                                           |                           | $I_{OH} = -2\text{ mA}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 0 (recommended)  | $0.8V_{DD}$    | —           |      |
|          |    |                                           |                           | $I_{OH} = -1\text{ mA}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 1 <sup>(2)</sup> | $0.8V_{DD}$    | —           |      |
|          |    |                                           |                           | $I_{OH} = -1\text{ mA}$ ,<br>$V_{DD} = 3.3\text{ V} \pm 10\%$ , PAD3V5V = 1 (recommended)  | $V_{DD} - 0.8$ | —           |      |
|          |    |                                           |                           | $I_{OH} = -100\text{ }\mu\text{A}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 0     | $0.8V_{DD}$    | —           |      |
| $V_{OL}$ | CC | Output low level<br>MEDIUM configuration  | Push Pull                 | $I_{OL} = 3.8\text{ mA}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 0               | —              | $0.2V_{DD}$ | V    |
|          |    |                                           |                           | $I_{OL} = 2\text{ mA}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 0 (recommended)   | —              | $0.1V_{DD}$ |      |
|          |    |                                           |                           | $I_{OL} = 1\text{ mA}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 1 <sup>(2)</sup>  | —              | $0.1V_{DD}$ |      |
|          |    |                                           |                           | $I_{OL} = 1\text{ mA}$ ,<br>$V_{DD} = 3.3\text{ V} \pm 10\%$ , PAD3V5V = 1 (recommended)   | —              | 0.5         |      |
|          |    |                                           |                           | $I_{OL} = 100\text{ }\mu\text{A}$ ,<br>$V_{DD} = 5.0\text{ V} \pm 10\%$ , PAD3V5V = 0      | —              | $0.1V_{DD}$ |      |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^\circ\text{C}$ , unless otherwise specified.

2. The configuration PAD3V5 = 1 when  $V_{DD} = 5\text{ V}$  is only a transient configuration during power-up. All pads but RESET are configured in input or in high impedance state.

#### 4.7.4 Output pin transition times

Table 19. Output pin transition times

| Symbol   | C  | Parameter                                                                | Conditions <sup>(1)</sup> | Value |     |     | Unit |
|----------|----|--------------------------------------------------------------------------|---------------------------|-------|-----|-----|------|
|          |    |                                                                          |                           | Min   | Typ | Max |      |
| $t_{tr}$ | CC | Output transition time output pin <sup>(2)</sup><br>SLOW configuration   | $C_L = 25\text{ pF}$      | —     | —   | 50  | ns   |
|          |    |                                                                          | $C_L = 50\text{ pF}$      | —     | —   | 100 |      |
|          |    |                                                                          | $C_L = 100\text{ pF}$     | —     | —   | 125 |      |
|          |    | SLOW configuration                                                       | $C_L = 25\text{ pF}$      | —     | —   | 50  |      |
|          |    |                                                                          | $C_L = 50\text{ pF}$      | —     | —   | 100 |      |
|          |    |                                                                          | $C_L = 100\text{ pF}$     | —     | —   | 125 |      |
| $t_{tr}$ | CC | Output transition time output pin <sup>(2)</sup><br>MEDIUM configuration | $C_L = 25\text{ pF}$      | —     | —   | 10  | ns   |
|          |    |                                                                          | $C_L = 50\text{ pF}$      | —     | —   | 20  |      |
|          |    |                                                                          | $C_L = 100\text{ pF}$     | —     | —   | 40  |      |
|          |    | MEDIUM configuration                                                     | $C_L = 25\text{ pF}$      | —     | —   | 12  |      |
|          |    |                                                                          | $C_L = 50\text{ pF}$      | —     | —   | 25  |      |
|          |    |                                                                          | $C_L = 100\text{ pF}$     | —     | —   | 40  |      |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^\circ\text{C}$ , unless otherwise specified.

2.  $C_L$  includes device and package capacitances ( $C_{PKG} < 5\text{ pF}$ ).

#### 4.7.5 I/O pad current specification

The I/O pads are distributed across the I/O supply segment. Each I/O supply segment is associated to a  $V_{DD}/V_{SS}$  supply pair as described in [Table 20](#).

[Table 21](#) provides I/O consumption figures.

In order to ensure device reliability, the average current of the I/O on a single segment should remain below the  $I_{AVGSEG}$  maximum value.

Table 20. I/O supply segment

| Package | Supply segment  |                 |                 |                 |
|---------|-----------------|-----------------|-----------------|-----------------|
|         | 1               | 2               | 3               | 4               |
| LQFP100 | pin 16 – pin 35 | pin 37 – pin 69 | pin 70 – pin 83 | pin 84 – pin 15 |
| LQFP64  | pin 8 – pin 26  | pin 28 – pin 55 | pin 56 – pin 7  | —               |

Table 21. I/O consumption

| Symbol                             |    | C | Parameter                                                 | Conditions <sup>(1)</sup>                  |                                            | Value |     |      | Unit |
|------------------------------------|----|---|-----------------------------------------------------------|--------------------------------------------|--------------------------------------------|-------|-----|------|------|
|                                    |    |   |                                                           |                                            |                                            | Min   | Typ | Max  |      |
| I <sub>SWTSLW</sub> <sup>(2)</sup> | CC | D | Dynamic I/O current for SLOW configuration                | C <sub>L</sub> = 25 pF                     | V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 | —     | —   | 20   | mA   |
|                                    |    |   |                                                           |                                            | V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 | —     | —   | 16   |      |
| I <sub>SWTMED</sub> <sup>(2)</sup> | CC | D | Dynamic I/O current for MEDIUM configuration              | C <sub>L</sub> = 25 pF                     | V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 | —     | —   | 29   | mA   |
|                                    |    |   |                                                           |                                            | V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 | —     | —   | 17   |      |
| I <sub>RMSSLW</sub>                | CC | D | Root mean square I/O current for SLOW configuration       | C <sub>L</sub> = 25 pF, 2 MHz              | V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 | —     | —   | 2.3  | mA   |
|                                    |    |   |                                                           | C <sub>L</sub> = 25 pF, 4 MHz              |                                            | —     | —   | 3.2  |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 100 pF, 2 MHz             |                                            | —     | —   | 6.6  |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 25 pF, 2 MHz              | V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 | —     | —   | 1.6  |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 25 pF, 4 MHz              |                                            | —     | —   | 2.3  |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 100 pF, 2 MHz             |                                            | —     | —   | 4.7  |      |
| I <sub>RMSMED</sub>                | CC | D | Root mean square I/O current for MEDIUM configuration     | C <sub>L</sub> = 25 pF, 13 MHz             | V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 | —     | —   | 6.6  | mA   |
|                                    |    |   |                                                           | C <sub>L</sub> = 25 pF, 40 MHz             |                                            | —     | —   | 13.4 |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 100 pF, 13 MHz            |                                            | —     | —   | 18.3 |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 25 pF, 13 MHz             | V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 | —     | —   | 5    |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 25 pF, 40 MHz             |                                            | —     | —   | 8.5  |      |
|                                    |    |   |                                                           | C <sub>L</sub> = 100 pF, 13 MHz            |                                            | —     | —   | 11   |      |
| I <sub>AVGSEG</sub>                | SR | D | Sum of all the static I/O current within a supply segment | V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 | —                                          | —     | 70  | mA   |      |
|                                    |    |   |                                                           | V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 | —                                          | —     | 65  |      |      |

1.  $V_{\text{DD}} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125^\circ\text{C}$ , unless otherwise specified.

2. Stated maximum values represent peak consumption that lasts only a few ns during I/O transition.

Table 22 provides the weight of concurrent switching I/Os.

In order to ensure device functionality, the sum of the weight of concurrent switching I/Os on a single segment should remain below 100%.

Table 22. I/O weight

| Pad   | LQFP100/LQFP64         |                  |                  |                  |
|-------|------------------------|------------------|------------------|------------------|
|       | Weight 5 V             |                  | Weight 3.3 V     |                  |
|       | $\text{SRC}^{(1)} = 0$ | $\text{SRC} = 1$ | $\text{SRC} = 0$ | $\text{SRC} = 1$ |
| PB[3] | 9%                     | 9%               | 10%              | 10%              |
| PC[9] | 8%                     | 8%               | 10%              | 10%              |

Table 22. I/O weight (continued)

| Pad    | LQFP100/LQFP64         |         |              |         |
|--------|------------------------|---------|--------------|---------|
|        | Weight 5 V             |         | Weight 3.3 V |         |
|        | SRC <sup>(1)</sup> = 0 | SRC = 1 | SRC = 0      | SRC = 1 |
| PC[14] | 8%                     | 8%      | 10%          | 10%     |
| PC[15] | 8%                     | 11%     | 9%           | 10%     |
| PA[2]  | 8%                     | 8%      | 9%           | 9%      |
| PE[0]  | 7%                     | 7%      | 9%           | 9%      |
| PA[1]  | 7%                     | 7%      | 8%           | 8%      |
| PE[1]  | 7%                     | 10%     | 8%           | 8%      |
| PE[8]  | 6%                     | 9%      | 8%           | 8%      |
| PE[9]  | 6%                     | 6%      | 7%           | 7%      |
| PE[10] | 6%                     | 6%      | 7%           | 7%      |
| PA[0]  | 5%                     | 7%      | 6%           | 7%      |
| PE[11] | 5%                     | 5%      | 6%           | 6%      |
| PC[11] | 7%                     | 7%      | 9%           | 9%      |
| PC[10] | 8%                     | 11%     | 9%           | 10%     |
| PB[0]  | 8%                     | 11%     | 9%           | 10%     |
| PB[1]  | 8%                     | 8%      | 10%          | 10%     |
| PC[6]  | 8%                     | 8%      | 10%          | 10%     |
| PC[7]  | 8%                     | 8%      | 10%          | 10%     |
| PA[15] | 8%                     | 11%     | 9%           | 10%     |
| PA[14] | 7%                     | 11%     | 9%           | 9%      |
| PA[4]  | 7%                     | 7%      | 8%           | 8%      |
| PA[13] | 7%                     | 10%     | 8%           | 9%      |
| PA[12] | 7%                     | 7%      | 8%           | 8%      |
| PB[9]  | 1%                     | 1%      | 1%           | 1%      |
| PB[8]  | 1%                     | 1%      | 1%           | 1%      |
| PB[10] | 5%                     | 5%      | 6%           | 6%      |
| PD[0]  | 1%                     | 1%      | 1%           | 1%      |
| PD[1]  | 1%                     | 1%      | 1%           | 1%      |
| PD[2]  | 1%                     | 1%      | 1%           | 1%      |
| PD[3]  | 1%                     | 1%      | 1%           | 1%      |
| PD[4]  | 1%                     | 1%      | 1%           | 1%      |
| PD[5]  | 1%                     | 1%      | 1%           | 1%      |
| PD[6]  | 1%                     | 1%      | 1%           | 1%      |

Table 22. I/O weight (continued)

| Pad    | LQFP100/LQFP64         |         |              |         |
|--------|------------------------|---------|--------------|---------|
|        | Weight 5 V             |         | Weight 3.3 V |         |
|        | SRC <sup>(1)</sup> = 0 | SRC = 1 | SRC = 0      | SRC = 1 |
| PD[7]  | 1%                     | 1%      | 1%           | 1%      |
| PD[8]  | 1%                     | 1%      | 1%           | 1%      |
| PB[4]  | 1%                     | 1%      | 1%           | 1%      |
| PB[5]  | 1%                     | 1%      | 1%           | 1%      |
| PB[6]  | 1%                     | 1%      | 1%           | 1%      |
| PB[7]  | 1%                     | 1%      | 1%           | 1%      |
| PD[9]  | 1%                     | 1%      | 1%           | 1%      |
| PD[10] | 1%                     | 1%      | 1%           | 1%      |
| PD[11] | 1%                     | 1%      | 1%           | 1%      |
| PB[11] | 9%                     | 9%      | 11%          | 11%     |
| PD[12] | 8%                     | 8%      | 10%          | 10%     |
| PB[12] | 8%                     | 8%      | 10%          | 10%     |
| PD[13] | 8%                     | 8%      | 9%           | 9%      |
| PB[13] | 8%                     | 8%      | 9%           | 9%      |
| PD[14] | 7%                     | 7%      | 9%           | 9%      |
| PB[14] | 7%                     | 7%      | 8%           | 8%      |
| PD[15] | 7%                     | 7%      | 8%           | 8%      |
| PB[15] | 6%                     | 6%      | 7%           | 7%      |
| PA[3]  | 6%                     | 6%      | 7%           | 7%      |
| PA[7]  | 4%                     | 4%      | 5%           | 5%      |
| PA[8]  | 4%                     | 4%      | 5%           | 5%      |
| PA[9]  | 4%                     | 4%      | 5%           | 5%      |
| PA[10] | 5%                     | 5%      | 6%           | 6%      |
| PA[11] | 5%                     | 5%      | 6%           | 6%      |
| PE[12] | 5%                     | 5%      | 6%           | 6%      |
| PC[3]  | 5%                     | 5%      | 6%           | 6%      |
| PC[2]  | 5%                     | 7%      | 6%           | 6%      |
| PA[5]  | 5%                     | 6%      | 5%           | 6%      |
| PA[6]  | 4%                     | 4%      | 5%           | 5%      |
| PC[1]  | 5%                     | 17%     | 4%           | 12%     |
| PC[0]  | 6%                     | 9%      | 7%           | 8%      |
| PE[2]  | 7%                     | 10%     | 8%           | 9%      |

Table 22. I/O weight (continued)

| Pad    | LQFP100/LQFP64         |         |              |         |
|--------|------------------------|---------|--------------|---------|
|        | Weight 5 V             |         | Weight 3.3 V |         |
|        | SRC <sup>(1)</sup> = 0 | SRC = 1 | SRC = 0      | SRC = 1 |
| PE[3]  | 7%                     | 10%     | 9%           | 9%      |
| PC[5]  | 8%                     | 11%     | 9%           | 10%     |
| PC[4]  | 8%                     | 11%     | 9%           | 10%     |
| PE[4]  | 8%                     | 12%     | 10%          | 10%     |
| PE[5]  | 8%                     | 12%     | 10%          | 11%     |
| PE[6]  | 9%                     | 12%     | 10%          | 11%     |
| PE[7]  | 9%                     | 12%     | 10%          | 11%     |
| PC[12] | 9%                     | 13%     | 11%          | 11%     |
| PC[13] | 9%                     | 9%      | 11%          | 11%     |
| PC[8]  | 9%                     | 9%      | 11%          | 11%     |
| PB[2]  | 9%                     | 13%     | 11%          | 12%     |

1. SRC: "Slew Rate Control" bit in SIU\_PCR

Note:  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40\text{ to }125\text{ }^{\circ}\text{C}$ , unless otherwise specified.

## 4.8 RESET electrical characteristics

The device implements a dedicated bidirectional  $\overline{\text{RESET}}$  pin.

Figure 5. Start-up reset requirements

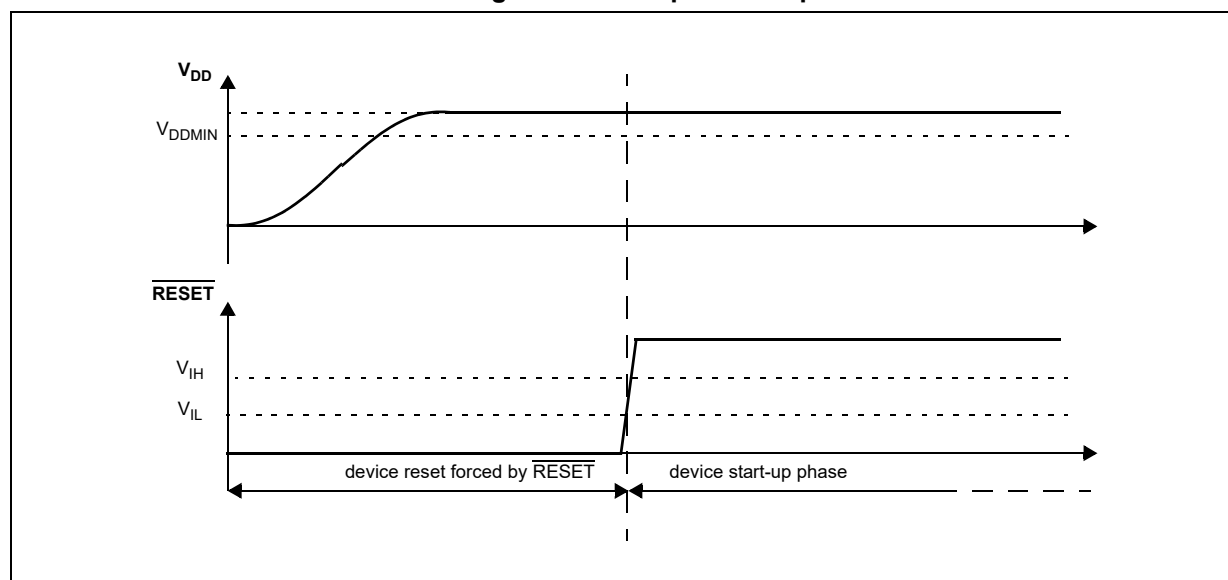


Figure 6. Noise filtering on reset signal

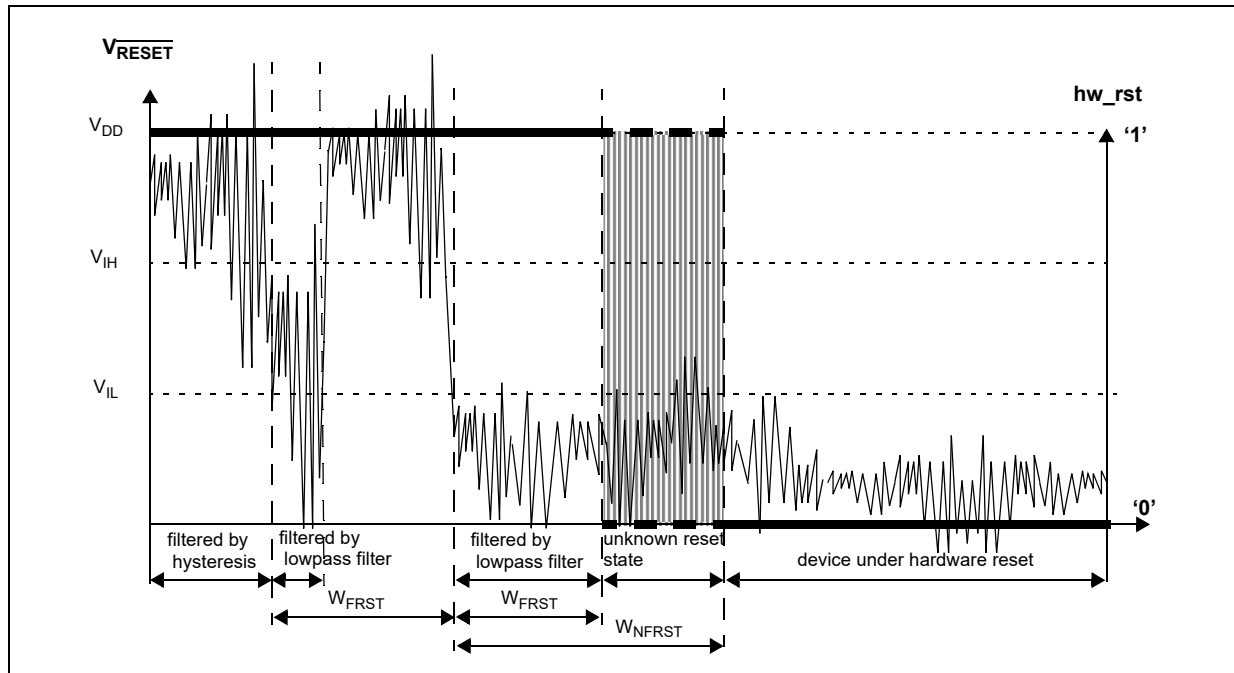


Table 23. Reset electrical characteristics

| Symbol           | C  | Parameter | Conditions <sup>(1)</sup>                                                                                                                              | Value |     |                       | Unit |
|------------------|----|-----------|--------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-----|-----------------------|------|
|                  |    |           |                                                                                                                                                        | Min   | Typ | Max                   |      |
| $V_{\text{IH}}$  | SR | P         | Input High Level<br>CMOS (Schmitt<br>Trigger)                                                                                                          | —     | —   | $V_{\text{DD}} + 0.4$ | V    |
| $V_{\text{IL}}$  | SR | P         | Input low Level<br>CMOS (Schmitt<br>Trigger)                                                                                                           | —     | —   | $0.35V_{\text{DD}}$   | V    |
| $V_{\text{HYS}}$ | CC | C         | Input hysteresis<br>CMOS (Schmitt<br>Trigger)                                                                                                          | —     | —   | —                     | V    |
| $V_{\text{OL}}$  | CC | P         | Output low level<br>Push Pull, $I_{\text{OL}} = 2 \text{ mA}$ ,<br>$V_{\text{DD}} = 5.0 \text{ V} \pm 10\%$ ,<br>$\text{PAD3V5V} = 0$<br>(recommended) | —     | —   | $0.1V_{\text{DD}}$    | V    |
|                  |    |           | Push Pull, $I_{\text{OL}} = 1 \text{ mA}$ ,<br>$V_{\text{DD}} = 5.0 \text{ V} \pm 10\%$ ,<br>$\text{PAD3V5V} = 1^{(2)}$                                | —     | —   | $0.1V_{\text{DD}}$    |      |
|                  |    |           | Push Pull, $I_{\text{OL}} = 1 \text{ mA}$ ,<br>$V_{\text{DD}} = 3.3 \text{ V} \pm 10\%$ ,<br>$\text{PAD3V5V} = 1$<br>(recommended)                     | —     | —   | 0.5                   |      |

Table 23. Reset electrical characteristics (continued)

| Symbol      | C  | Parameter                                                                | Conditions <sup>(1)</sup>                                                   | Value |      |     | Unit          |
|-------------|----|--------------------------------------------------------------------------|-----------------------------------------------------------------------------|-------|------|-----|---------------|
|             |    |                                                                          |                                                                             | Min   | Typ  | Max |               |
| $t_{tr}$    | CC | Output transition time output pin <sup>(3)</sup><br>MEDIUM configuration | $C_L = 25 \text{ pF}$ ,<br>$V_{DD} = 5.0 \text{ V} \pm 10\%$ , PAD3V5V = 0  | —     | —    | 10  | ns            |
|             |    |                                                                          | $C_L = 50 \text{ pF}$ ,<br>$V_{DD} = 5.0 \text{ V} \pm 10\%$ , PAD3V5V = 0  | —     | —    | 20  |               |
|             |    |                                                                          | $C_L = 100 \text{ pF}$ ,<br>$V_{DD} = 5.0 \text{ V} \pm 10\%$ , PAD3V5V = 0 | —     | —    | 40  |               |
|             |    |                                                                          | $C_L = 25 \text{ pF}$ ,<br>$V_{DD} = 3.3 \text{ V} \pm 10\%$ , PAD3V5V = 1  | —     | —    | 12  |               |
|             |    |                                                                          | $C_L = 50 \text{ pF}$ ,<br>$V_{DD} = 3.3 \text{ V} \pm 10\%$ , PAD3V5V = 1  | —     | —    | 25  |               |
|             |    |                                                                          | $C_L = 100 \text{ pF}$ ,<br>$V_{DD} = 3.3 \text{ V} \pm 10\%$ , PAD3V5V = 1 | —     | —    | 40  |               |
| $W_{FRST}$  | SR | P                                                                        | RESET input filtered pulse                                                  | —     | —    | 40  | ns            |
| $W_{NFRST}$ | SR | P                                                                        | RESET input not filtered pulse                                              | —     | 1000 | —   | ns            |
| $ I_{WPU} $ | CC | Weak pull-up current absolute value                                      | $V_{DD} = 3.3 \text{ V} \pm 10\%$ , PAD3V5V = 1                             | 10    | —    | 150 | $\mu\text{A}$ |
|             |    |                                                                          | $V_{DD} = 5.0 \text{ V} \pm 10\%$ , PAD3V5V = 0                             | 10    | —    | 150 |               |
|             |    |                                                                          | $V_{DD} = 5.0 \text{ V} \pm 10\%$ ,<br>PAD3V5V = 1 <sup>(4)</sup>           | 10    | —    | 250 |               |

1.  $V_{DD} = 3.3 \text{ V} \pm 10\%$  /  $5.0 \text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125^\circ\text{C}$ , unless otherwise specified.

2. This is a transient configuration during power-up, up to the end of reset PHASE2 (refer to RGM module section of the device reference manual).

3.  $C_L$  includes device and package capacitance ( $C_{PKG} < 5 \text{ pF}$ ).

4. The configuration PAD3V5 = 1 when  $V_{DD} = 5 \text{ V}$  is only transient configuration during power-up. All pads but RESET are configured in input or in high impedance state.

## 4.9 Power management electrical characteristics

### 4.9.1 Voltage regulator electrical characteristics

The device implements an internal voltage regulator to generate the low voltage core supply  $V_{DD\_LV}$  from the high voltage ballast supply  $V_{DD\_BV}$ . The regulator itself is supplied by the common I/O supply  $V_{DD}$ . The following supplies are involved:

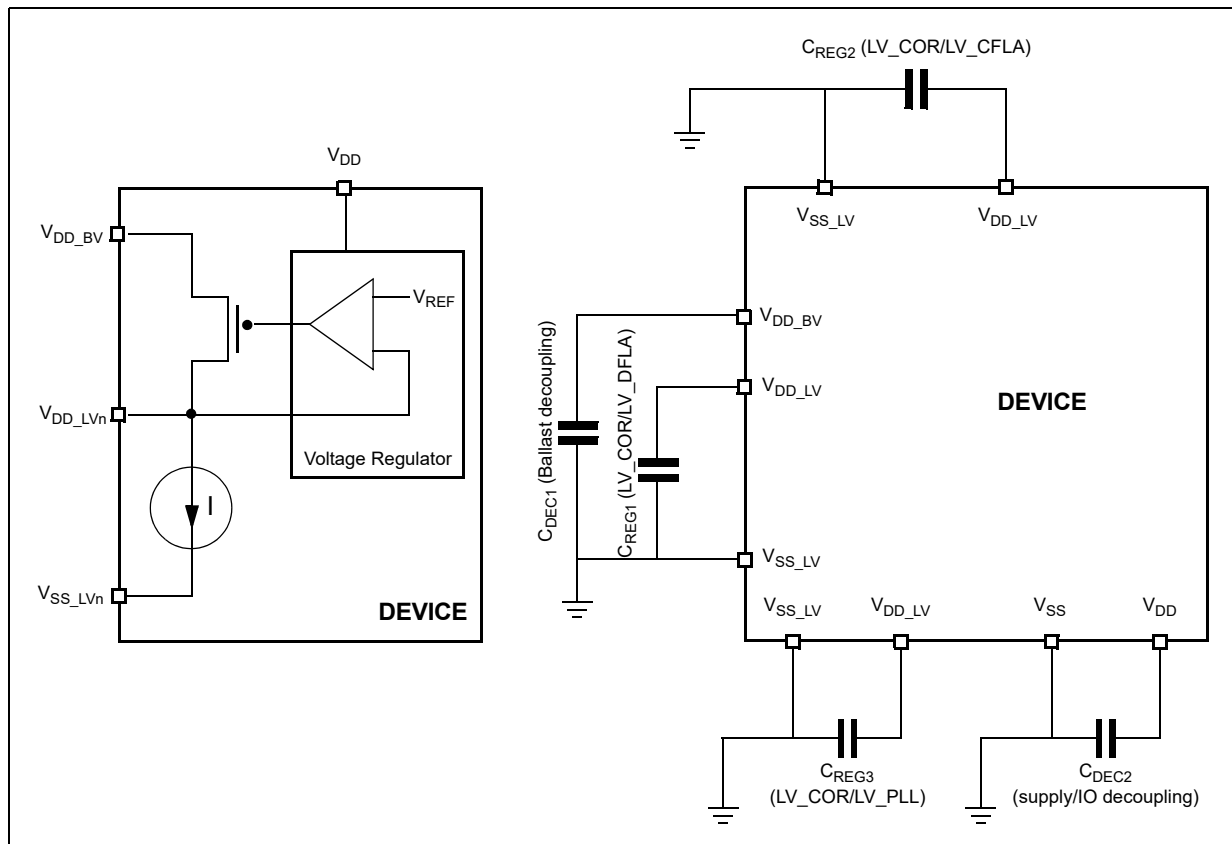
- HV: High voltage external power supply for voltage regulator module. This must be provided externally through  $V_{DD}$  power pin.
- BV: High voltage external power supply for internal ballast module. This must be provided externally through  $V_{DD\_BV}$  power pin. Voltage values should be aligned with  $V_{DD}$ .
- LV: Low voltage internal power supply for core, FMPLL and flash digital logic. This is generated by the internal voltage regulator but provided outside to connect stability



capacitor. It is further split into four main domains to ensure noise isolation between critical LV modules within the device:

- LV\_COR: Low voltage supply for the core. It is also used to provide supply for FMPLL through double bonding.
- LV\_CFLA: Low voltage supply for code flash module. It is supplied with dedicated ballast and shorted to LV\_COR through double bonding.
- LV\_DFLA: Low voltage supply for data flash module. It is supplied with dedicated ballast and shorted to LV\_COR through double bonding.
- LV\_PLL: Low voltage supply for FMPLL. It is shorted to LV\_COR through double bonding.

**Figure 7. Voltage regulator capacitance connection**



The internal voltage regulator requires external capacitance ( $C_{REGn}$ ) to be connected to the device in order to provide a stable low voltage digital supply to the device. Capacitances should be placed on the board as near as possible to the associated pins. Care should also be taken to limit the serial inductance of the board to less than 5 nH.

Each decoupling capacitor must be placed between each of the three  $V_{DD\_LV}/V_{SS\_LV}$  supply pairs to ensure stable voltage (see [Section 4.5: Recommended operating conditions](#)).

Table 24. Voltage regulator electrical characteristics

| Symbol                 |    | C | Parameter                                                                    | Conditions <sup>(1)</sup>                                                           | Value              |                    |                    | Unit |
|------------------------|----|---|------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|--------------------|--------------------|--------------------|------|
|                        |    |   |                                                                              |                                                                                     | Min                | Typ                | Max                |      |
| C <sub>REGn</sub>      | SR | — | Internal voltage regulator external capacitance                              | —                                                                                   | 200                | —                  | 500                | nF   |
| R <sub>REG</sub>       | SR | — | Stability capacitor equivalent serial resistance                             | Range:<br>10 kHz to 20 MHz                                                          | —                  | —                  | 0.2                | W    |
| C <sub>DEC1</sub>      | SR | — | Decoupling capacitance <sup>(2)</sup> ballast                                | V <sub>DD_BV</sub> /V <sub>SS_LV</sub> pair:<br>V <sub>DD_BV</sub> = 4.5 V to 5.5 V | 100 <sup>(3)</sup> | 470 <sup>(4)</sup> | —                  | nF   |
|                        |    |   |                                                                              | V <sub>DD_BV</sub> /V <sub>SS_LV</sub> pair:<br>V <sub>DD_BV</sub> = 3 V to 3.6 V   | 400                |                    | —                  |      |
| C <sub>DEC2</sub>      | SR | — | Decoupling capacitance regulator supply                                      | V <sub>DD</sub> /V <sub>SS</sub> pair                                               | 10                 | 100                | —                  | nF   |
| V <sub>MREG</sub>      | CC | T | Main regulator output voltage                                                | Before exiting from reset                                                           | —                  | 1.32               | —                  | V    |
|                        |    | P |                                                                              | After trimming                                                                      | 1.16               | 1.28               | —                  |      |
| I <sub>MREG</sub>      | SR | — | Main regulator current provided to V <sub>DD_LV</sub> domain                 | —                                                                                   | —                  | —                  | 150                | mA   |
| I <sub>MREGINT</sub>   | CC | D | Main regulator module current consumption                                    | I <sub>MREG</sub> = 200 mA                                                          | —                  | —                  | 2                  | mA   |
|                        |    |   |                                                                              | I <sub>MREG</sub> = 0 mA                                                            | —                  | —                  | 1                  |      |
| V <sub>LPREG</sub>     | CC | P | Low-power regulator output voltage                                           | After trimming                                                                      | 1.16               | 1.28               | —                  | V    |
| I <sub>LPREG</sub>     | SR | — | Low power regulator current provided to V <sub>DD_LV</sub> domain            | —                                                                                   | —                  | —                  | 15                 | mA   |
| I <sub>LPREGINT</sub>  | CC | D | Low-power regulator module current consumption                               | I <sub>LPREG</sub> = 15 mA;<br>T <sub>A</sub> = 55°C                                | —                  | —                  | 600                | μA   |
|                        |    | — |                                                                              | I <sub>LPREG</sub> = 0 mA;<br>T <sub>A</sub> = 55°C                                 | —                  | 5                  | —                  |      |
| V <sub>ULPREG</sub>    | CC | P | Ultra low power regulator output voltage                                     | After trimming                                                                      | 1.16               | 1.28               | —                  | V    |
| I <sub>ULPREG</sub>    | SR | — | Ultra low power regulator current provided to V <sub>DD_LV</sub> domain      | —                                                                                   | —                  | —                  | 5                  | mA   |
| I <sub>ULPREGINT</sub> | CC | D | Ultra low power regulator module current consumption                         | I <sub>ULPREG</sub> = 5 mA;<br>T <sub>A</sub> = 55°C                                | —                  | —                  | 100                | μA   |
|                        |    |   |                                                                              | I <sub>ULPREG</sub> = 0 mA;<br>T <sub>A</sub> = 55 °C                               | —                  | 2                  | —                  |      |
| I <sub>DD_BV</sub>     | CC | D | In-rush average current on V <sub>DD_BV</sub> during power-up <sup>(5)</sup> | —                                                                                   | —                  | —                  | 300 <sup>(6)</sup> | mA   |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

2. This capacitance value is driven by the constraints of the external voltage regulator supplying the V<sub>DD\_BV</sub> voltage. A typical value is in the range of 470 nF.

3. This value is acceptable to guarantee operation from 4.5 V to 5.5 V.

4. External regulator and capacitance circuitry must be capable of providing  $I_{DD\_BV}$  while maintaining supply  $V_{DD\_BV}$  in operating range.
5. In-rush average current is seen only for short time during power-up and on standby exit (maximum 20  $\mu$ s, depending on external capacitances to be loaded).
6. The duration of the in-rush current depends on the capacitance placed on LV pins. BV decoupling capacitors must be sized accordingly. Refer to  $I_{MREG}$  value for minimum amount of current to be provided in cc.

#### 4.9.2 Low voltage detector electrical characteristics

The device implements a power-on reset (POR) module to ensure correct power-up initialization, as well as five low voltage detectors (LVDs) to monitor the  $V_{DD}$  and the  $V_{DD\_LV}$  voltage while device is supplied:

- POR monitors  $V_{DD}$  during the power-up phase to ensure device is maintained in a safe reset state (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_POR in device reference manual)
- LVDHV3 monitors  $V_{DD}$  to ensure device reset below minimum functional supply (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD27 in device reference manual)
- LVDHV3B monitors  $V_{DD\_BV}$  to ensure device reset below minimum functional supply (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD27\_VREG in device reference manual)
- LVDHV5 monitors  $V_{DD}$  when application uses device in the 5.0 V  $\pm$  10% range (refer to RGM Functional Event Status (RGM\_FES) Register flag F\_LVD45 in device reference manual)
- LVDLVCOR monitors power domain No. 1 (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD12\_PD1 in device reference manual)
- LVDLVBKP monitors power domain No. 0 (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD12\_PD0 in device reference manual)

Figure 8. Low voltage detector vs reset

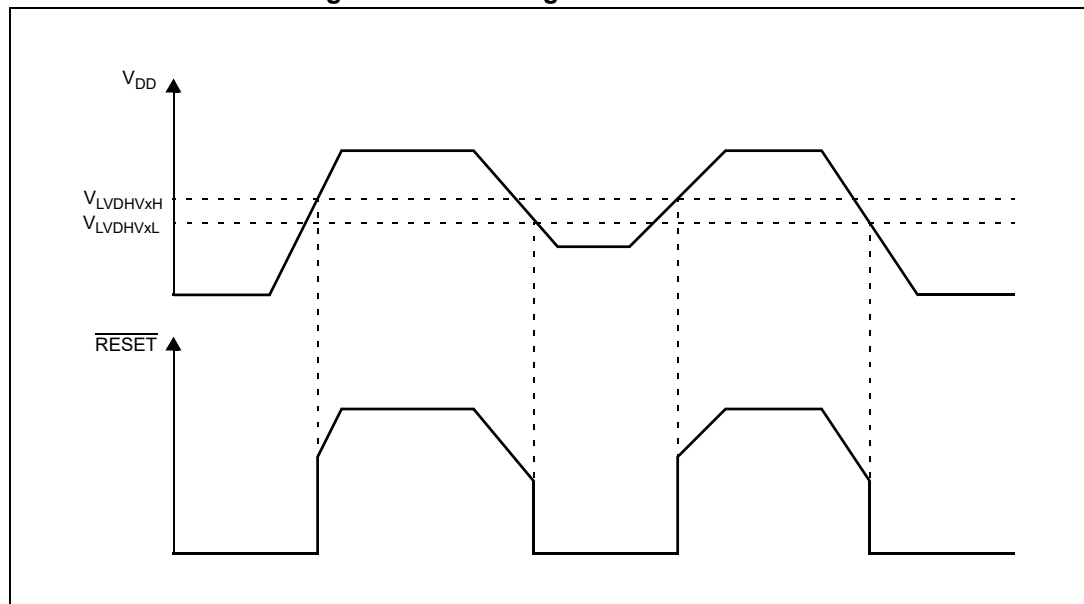


Table 25. Low voltage detector electrical characteristics

| Symbol                 | C  | Parameter | Conditions <sup>(1)</sup>                   | Value |     |      | Unit |
|------------------------|----|-----------|---------------------------------------------|-------|-----|------|------|
|                        |    |           |                                             | Min   | Typ | Max  |      |
| V <sub>PORUP</sub>     | SR | P         | Supply for functional POR module            | 1.0   | —   | 5.5  | V    |
| V <sub>PORH</sub>      | CC | P         | Power-on reset threshold                    | 1.5   | —   | 2.6  | V    |
| V <sub>LVDHV3H</sub>   | CC | T         | LVDHV3 low voltage detector high threshold  | —     | —   | 2.95 | V    |
| V <sub>LVDHV3L</sub>   | CC | P         | LVDHV3 low voltage detector low threshold   | 2.6   | —   | 2.9  | V    |
| V <sub>LVDHV3BH</sub>  | CC | P         | LVDHV3B low voltage detector high threshold | —     | —   | 2.95 | V    |
| V <sub>LVDHV3BL</sub>  | CC | P         | LVDHV3B low voltage detector low threshold  | 2.6   | —   | 2.9  | V    |
| V <sub>LVDHV5H</sub>   | CC | T         | LVDHV5 low voltage detector high threshold  | —     | —   | 4.5  | V    |
| V <sub>LVDHV5L</sub>   | CC | P         | LVDHV5 low voltage detector low threshold   | 3.8   | —   | 4.4  | V    |
| V <sub>LVDLVCORL</sub> | CC | P         | LVDLVCOR low voltage detector low threshold | 1.08  | —   | 1.16 | V    |
| V <sub>LVDLVBKPL</sub> | CC | P         | LVDLVBKP low voltage detector low threshold | 1.08  | —   | 1.16 | V    |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

## 4.10 Power consumption

Table 26 provides DC electrical characteristics for significant application modes. These values are indicative values; actual consumption depends on the application.

Table 26. Power consumption on VDD\_BV and VDD\_HV

| Symbol                            |    | C                         | Parameter                                       | Conditions <sup>(1)</sup>                     |                         | Value |     |                    | Unit |
|-----------------------------------|----|---------------------------|-------------------------------------------------|-----------------------------------------------|-------------------------|-------|-----|--------------------|------|
|                                   |    |                           |                                                 |                                               |                         | Min   | Typ | Max                |      |
| I <sub>DDMAX</sub> <sup>(2)</sup> | CC | D                         | RUN mode maximum average current                | —                                             |                         | —     | 90  | 130 <sup>(3)</sup> | mA   |
| I <sub>DDRUN</sub> <sup>(4)</sup> | CC | T                         | RUN mode typical average current <sup>(5)</sup> | f <sub>CPU</sub> = 8 MHz                      |                         | —     | 7   | —                  | mA   |
|                                   |    | f <sub>CPU</sub> = 16 MHz |                                                 | —                                             | 18                      | —     |     |                    |      |
|                                   |    | f <sub>CPU</sub> = 32 MHz |                                                 | —                                             | 29                      | —     |     |                    |      |
|                                   |    | f <sub>CPU</sub> = 48 MHz |                                                 | —                                             | 40                      | 100   |     |                    |      |
| I <sub>DDHALT</sub>               | CC | C                         | HALT mode current <sup>(6)</sup>                | Slow internal RC oscillator (128 kHz) running | T <sub>A</sub> = 25 °C  | —     | 8   | 15                 | mA   |
|                                   |    | P                         |                                                 |                                               | T <sub>A</sub> = 125 °C | —     | 14  | 25                 |      |
| I <sub>DDSTOP</sub>               | CC | P                         | STOP mode current <sup>(7)</sup>                | Slow internal RC oscillator (128 kHz) running | T <sub>A</sub> = 25 °C  | —     | 180 | 700 <sup>(8)</sup> | μA   |
|                                   |    | D                         |                                                 |                                               | T <sub>A</sub> = 55 °C  | —     | 500 | —                  |      |
|                                   |    | D                         |                                                 |                                               | T <sub>A</sub> = 85 °C  | —     | 1   | 6 <sup>(8)</sup>   | mA   |
|                                   |    | D                         |                                                 |                                               | T <sub>A</sub> = 105 °C | —     | 2   | 9 <sup>(8)</sup>   |      |
|                                   |    | P                         |                                                 |                                               | T <sub>A</sub> = 125 °C | —     | 4.5 | 12 <sup>(8)</sup>  |      |

Table 26. Power consumption on VDD\_BV and VDD\_HV (continued)

| Symbol               |    | C | Parameter                           | Conditions <sup>(1)</sup>                     |                         | Value |     |      | Unit |
|----------------------|----|---|-------------------------------------|-----------------------------------------------|-------------------------|-------|-----|------|------|
|                      |    |   |                                     |                                               |                         | Min   | Typ | Max  |      |
| I <sub>DDSTDBY</sub> | CC | P | STANDBY mode current <sup>(9)</sup> | Slow internal RC oscillator (128 kHz) running | T <sub>A</sub> = 25 °C  | —     | 30  | 100  | μA   |
|                      |    | D |                                     |                                               | T <sub>A</sub> = 55 °C  | —     | 75  | —    |      |
|                      |    | D |                                     |                                               | T <sub>A</sub> = 85 °C  | —     | 180 | 700  |      |
|                      |    | D |                                     |                                               | T <sub>A</sub> = 105 °C | —     | 315 | 1000 |      |
|                      |    | P |                                     |                                               | T <sub>A</sub> = 125 °C | —     | 560 | 1700 |      |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = –40 to 125 °C, unless otherwise specified.
2. Running consumption does not include I/Os toggling which is highly dependent on the application. The given value is thought to be a worst case value with all peripherals running, and code fetched from code flash while modify operation ongoing on data flash. Notice that this value can be significantly reduced by application: switch off not used peripherals (default), reduce peripheral frequency through internal prescaler, fetch from RAM most used functions, use low power mode when possible.
3. Higher current may be sinked by device during power-up and standby exit. Refer to in-rush average current on [Table 24](#).
4. RUN current measured with typical application with accesses on both flash memory and SRAM.
5. Only for the “P” classification: Code fetched from SRAM: serial IPs CAN and LIN in loop-back mode, DSPI as Master, PLL as system clock (3 × Multiplier) peripherals on (eMIOS/CTU/ADC) and running at maximum frequency, periodic SW/WDG timer reset enabled.
6. Data flash power down. Code flash in low power. SIRC (128 kHz) and FIRC (16 MHz) on. 10 MHz XTAL clock. FlexCAN: 0 ON (clocked but no reception or transmission). LINFlex: instances: 0, 1, 2 ON (clocked but no reception or transmission), instance: 3 clocks gated. eMIOS: instance: 0 ON (16 channels on PA[0]–PA[11] and PC[12]–PC[15]) with PWM 20 kHz, instance: 1 clock gated. DSPI: instance: 0 (clocked but no communication). RTC/API ON. PIT ON. STM ON. ADC ON but no conversion except 2 analog watchdogs.
7. Only for the “P” classification: No clock, FIRC (16 MHz) off, SIRC (128 kHz) on, PLL off, HPVreg off, ULPVreg/LPVreg on. All possible peripherals off and clock gated. Flash in power down mode.
8. When going from RUN to STOP mode and the core consumption is > 6 mA, it is normal operation for the main regulator module to be kept on by the on-chip current monitoring circuit. This is most likely to occur with junction temperatures exceeding 125°C and under these circumstances, it is possible for the current to initially exceed the maximum STOP specification by up to 2 mA. After entering stop, the application junction temperature will reduce to the ambient level and the main regulator will be automatically switched off when the load current is below 6 mA.
9. Only for the “P” classification: ULPVreg on, HP/LPVreg off, 16 KB SRAM on, device configured for minimum consumption, all possible modules switched off.

## 4.11 Flash memory electrical characteristics

The data flash operation depends strongly on the code flash operation. If code flash is switched-off, the data flash is disabled.

### 4.11.1 Program/Erase characteristics

[Table 27](#) shows the program and erase characteristics.

Table 27. Program and erase specifications (code flash)

| Symbol                   |    | C | Parameter                                         | Value |                    |                            |                    | Unit |
|--------------------------|----|---|---------------------------------------------------|-------|--------------------|----------------------------|--------------------|------|
|                          |    |   |                                                   | Min   | Typ <sup>(1)</sup> | Initial max <sup>(2)</sup> | Max <sup>(3)</sup> |      |
| t <sub>dwp</sub> program | CC | C | Double word (64-bits) program time <sup>(4)</sup> | —     | 22                 | 50                         | 500                | μs   |
| t <sub>16Kp</sub> perase | CC | C | 16 KB block preprogram and erase time             | —     | 300                | 500                        | 5000               | ms   |

Table 27. Program and erase specifications (code flash) (continued)

| Symbol                   |    | C | Parameter                              | Value |                    |                            |                    | Unit |
|--------------------------|----|---|----------------------------------------|-------|--------------------|----------------------------|--------------------|------|
|                          |    |   |                                        | Min   | Typ <sup>(1)</sup> | Initial max <sup>(2)</sup> | Max <sup>(3)</sup> |      |
| t <sub>32Kpperase</sub>  | CC | C | 32 KB block preprogram and erase time  | —     | 400                | 600                        | 5000               | ms   |
| t <sub>128Kpperase</sub> | CC | C | 128 KB block preprogram and erase time | —     | 800                | 1300                       | 7500               | ms   |
| t <sub>esus</sub>        | CC | C | Erase suspend latency                  | —     | —                  | 30                         | 30                 | μs   |

1. Typical program and erase times assume nominal supply values and operation at 25 °C. All times are subject to change pending device characterization.
2. Initial factory condition: < 100 program/erase cycles, 25 °C, typical supply voltage.
3. The maximum program and erase times occur after the specified number of program/erase cycles. These maximum values are characterized but not guaranteed.
4. Actual hardware programming times. This does not include software overhead.

Table 28. Program and erase specifications (data flash)

| Symbol                  |    | C | Parameter                                         | Value |                    |                            |                    | Unit |
|-------------------------|----|---|---------------------------------------------------|-------|--------------------|----------------------------|--------------------|------|
|                         |    |   |                                                   | Min   | Typ <sup>(1)</sup> | Initial max <sup>(2)</sup> | Max <sup>(3)</sup> |      |
| t <sub>swprogram</sub>  | CC | C | Single word (32-bits) program time <sup>(4)</sup> | —     | 30                 | 70                         | 300                | μs   |
| t <sub>16Kpperase</sub> | CC | C | 16 KB block preprogram and erase time             | —     | 700                | 800                        | 1500               | ms   |
| t <sub>Bank_D</sub>     | CC | C | 64 KB block preprogram and erase time             | —     | 1900               | 2300                       | 4800               | ms   |

1. Typical program and erase times assume nominal supply values and operation at 25 °C. All times are subject to change pending device characterization.
2. Initial factory condition: < 100 program/erase cycles, 25 °C, typical supply voltage.
3. The maximum program and erase times occur after the specified number of program/erase cycles. These maximum values are characterized but not guaranteed.
4. Actual hardware programming times. This does not include software overhead.

Table 29. Flash module life

| Symbol    |    | C | Parameter                                                                                       | Conditions                          | Value  |        |     | Unit   |
|-----------|----|---|-------------------------------------------------------------------------------------------------|-------------------------------------|--------|--------|-----|--------|
|           |    |   |                                                                                                 |                                     | Min    | Typ    | Max |        |
| P/E       | CC | C | Number of program/erase cycles per block over the operating temperature range (T <sub>J</sub> ) | 16 KB blocks                        | 100000 | —      | —   | cycles |
|           |    |   |                                                                                                 | 32 KB blocks                        | 10000  | 100000 | —   | cycles |
|           |    |   |                                                                                                 | 128 KB blocks                       | 1000   | 100000 | —   | cycles |
| Retention | CC | C | Minimum data retention at 85 °C average ambient temperature <sup>(1)</sup>                      | Blocks with 0–1000 P/E cycles       | 20     | —      | —   | years  |
|           |    |   |                                                                                                 | Blocks with 1001–10000 P/E cycles   | 10     | —      | —   |        |
|           |    |   |                                                                                                 | Blocks with 10001–100000 P/E cycles | 5      | —      | —   |        |

1. Ambient temperature averaged over application duration. It is recommended not to exceed the product operating temperature range.

ECC circuitry provides correction of single bit faults and is used to improve further automotive reliability results. Some units will experience single bit corrections throughout the life of the product with no impact to product reliability.

**Table 30. Flash memory read access timing**

| Symbol              |    | C | Parameter                                                                                                  | Conditions <sup>(1)</sup> | Max | Unit |
|---------------------|----|---|------------------------------------------------------------------------------------------------------------|---------------------------|-----|------|
| f <sub>CFREAD</sub> | CC | P | Maximum working frequency for reading code flash memory at given number of wait states in worst conditions | 2 wait states             | 48  | MHz  |
|                     |    | C |                                                                                                            | 0 wait states             | 20  |      |
| f <sub>DFREAD</sub> | CC | P | Maximum working frequency for reading data flash memory at given number of wait states in worst conditions | 6 wait states             | 48  | MHz  |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

#### 4.11.2 Flash power supply DC characteristics

*Table 31* shows the power supply DC characteristics on external supply.

*Note:* Power supply for data flash is actually provided by code flash; this means that data flash cannot work if code flash is not powered.

**Table 31. Flash power supply DC electrical characteristics**

| Symbol              |    | C | Parameter                                                                                                        | Conditions <sup>(1)</sup>                                                       |            | Value |     |     | Unit |
|---------------------|----|---|------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------|------------|-------|-----|-----|------|
|                     |    |   |                                                                                                                  |                                                                                 |            | Min   | Typ | Max |      |
| I <sub>CFREAD</sub> | CC | D | Sum of the current consumption on V <sub>DDHV</sub> and V <sub>DDBV</sub> on read access                         | Flash module read<br>f <sub>CPU</sub> = 48 MHz                                  | Code flash | —     | —   | 33  | mA   |
| I <sub>DFREAD</sub> | CC | D |                                                                                                                  |                                                                                 | Data flash | —     | —   | 4   | mA   |
| I <sub>CFMOD</sub>  | CC | D | Sum of the current consumption on V <sub>DDHV</sub> and V <sub>DDBV</sub> on matrix modification (program/erase) | Program/Erase on-going while reading flash registers, f <sub>CPU</sub> = 48 MHz | Code flash | —     | —   | 33  | mA   |
| I <sub>DFMOD</sub>  | CC | D |                                                                                                                  |                                                                                 | Data flash | —     | —   | 6   | mA   |
| I <sub>FLPW</sub>   | CC | D | Sum of the current consumption on V <sub>DDHV</sub> and V <sub>DDBV</sub> during flash low-power mode            | —                                                                               | Code flash | —     | —   | 910 | μA   |
| I <sub>CFPWD</sub>  | CC | D | Sum of the current consumption on V <sub>DDHV</sub> and V <sub>DDBV</sub> during flash power-down mode           | —                                                                               | Code flash | —     | —   | 125 | μA   |
| I <sub>DFPWD</sub>  | CC | D |                                                                                                                  |                                                                                 | Data flash | —     | —   | 25  | μA   |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

### 4.11.3 Start-up/Switch-off timings

Table 32. Start-up time/Switch-off time

| Symbol                  | C  | T | Parameter                                                    | Conditions <sup>(1)</sup> | Value |     |                   | Unit |
|-------------------------|----|---|--------------------------------------------------------------|---------------------------|-------|-----|-------------------|------|
|                         |    |   |                                                              |                           | Min   | Typ | Max               |      |
| t <sub>FLARSTEXIT</sub> | CC | T | Delay for flash module to exit reset mode                    | Code flash                | —     | —   | 125               | μs   |
|                         |    |   |                                                              | Data flash                | —     | —   | 150               | μs   |
| t <sub>FLALPEXIT</sub>  | CC | T | Delay for flash module to exit low-power mode <sup>(2)</sup> | Code flash                | —     | —   | 0.5               | μs   |
| t <sub>FLAPDEXIT</sub>  | CC | T | Delay for flash module to exit power-down mode               | Code flash                | —     | —   | 30                | μs   |
|                         |    |   |                                                              | Data flash                | —     | —   | 30 <sup>(3)</sup> | μs   |
| t <sub>FLALPENTRY</sub> | CC | T | Delay for flash module to enter low-power mode               | Code flash                | —     | —   | 0.5               | μs   |
| t <sub>FLAPDENTRY</sub> | CC | T | Delay for flash module to enter power-down mode              | Code flash                | —     | —   | 1.5               | μs   |
|                         |    |   |                                                              | Data flash                | —     | —   | 4 <sup>(3)</sup>  | μs   |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^{\circ}\text{C}$ , unless otherwise specified.

2. Data flash does not support low-power mode.

3. If code flash is already switched-on.

## 4.12 Electromagnetic compatibility (EMC) characteristics

Susceptibility tests are performed on a sample basis during product characterization.

### 4.12.1 Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user apply EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

- Software recommendations – The software flowchart must include the management of runaway conditions such as:
  - Corrupted program counter
  - Unexpected reset
  - Critical data corruption (control registers...)
- Prequalification trials – Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the reset pin or the oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see the application note *Software Techniques For Improving Microcontroller EMC Performance* (AN1015)).



### 4.12.2 Electromagnetic interference (EMI)

The product is monitored in terms of emission based on a typical application. This emission test conforms to the IEC 61967-1 standard, which specifies the general conditions for EMI measurements.

**Table 33. EMI radiated emission measurement**

| Symbol             |    | C | Parameter             | Conditions                                                                                                                                              |                               | Value |      |      | Unit |
|--------------------|----|---|-----------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------|-------|------|------|------|
|                    |    |   |                       |                                                                                                                                                         |                               | Min   | Typ  | Max  |      |
| —                  | SR | — | Scan range            | —                                                                                                                                                       |                               | 0.150 | —    | 1000 | MHz  |
| f <sub>CPU</sub>   | SR | — | Operating frequency   | —                                                                                                                                                       |                               | —     | 48   | —    | MHz  |
| V <sub>DD_LV</sub> | SR | — | LV operating voltages | —                                                                                                                                                       |                               | —     | 1.28 | —    | V    |
| S <sub>EMI</sub>   | CC | T | Peak level            | V <sub>DD</sub> = 5 V, T <sub>A</sub> = 25 °C,<br>LQFP100 package<br>Test conforming to IEC 61967-2, f <sub>OSC</sub> = 8 MHz/f <sub>CPU</sub> = 48 MHz | No PLL frequency modulation   | —     | —    | 18   | dBμV |
|                    |    |   |                       |                                                                                                                                                         | ± 2% PLL frequency modulation | —     | —    | 14   | dBμV |

**Note:** EMI testing and I/O port waveforms per IEC 61967-1, -2, -4  
For information on conducted emission and susceptibility measurement (norm IEC 61967-4), please contact your local marketing representative.

### 4.12.3 Absolute maximum ratings (electrical sensitivity)

Based on two different tests (ESD and LU) using specific measurement methods, the product is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to the each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n + 1) supply pin). This test conforms to the AEC-Q100-002/-003/-011 standard. For more details, refer to the application note *Electrostatic Discharge Sensitivity Measurement* (AN1181).

**Table 34. ESD absolute maximum ratings**

| Symbol                |    | C | Ratings                                                | Conditions                                           | Class | Max value     | Unit |
|-----------------------|----|---|--------------------------------------------------------|------------------------------------------------------|-------|---------------|------|
| V <sub>ESD(HBM)</sub> | CC | T | Electrostatic discharge voltage (Human Body Model)     | T <sub>A</sub> = 25 °C<br>conforming to AEC-Q100-002 | H1C   | 2000          | V    |
| V <sub>ESD(MM)</sub>  | CC | T | Electrostatic discharge voltage (Machine Model)        | T <sub>A</sub> = 25 °C<br>conforming to AEC-Q100-003 | M2    | 200           | V    |
| V <sub>ESD(CDM)</sub> | CC | T | Electrostatic discharge voltage (Charged Device Model) | T <sub>A</sub> = 25 °C<br>conforming to AEC-Q100-011 | C3A   | 500           | V    |
|                       |    |   |                                                        |                                                      |       | 750 (corners) | V    |

**Note:** All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.  
 A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements. Complete DC parametric and functional testing shall be performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

### Static latch-up (LU)

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin.
- A current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with the EIA/JESD 78 IC latch-up standard.

**Table 35. Latch-up results**

| Symbol |    | C | Parameter             | Conditions                                       | Class      |
|--------|----|---|-----------------------|--------------------------------------------------|------------|
| LU     | CC | T | Static latch-up class | T <sub>A</sub> = 125 °C<br>conforming to JESD 78 | II level A |

## 4.13 Fast external crystal oscillator (4 to 16 MHz) electrical characteristics

The device provides an oscillator/resonator driver. [Figure 9](#) describes a simple model of the internal oscillator driver and provides an example of a connection for an oscillator or a resonator.

[Table 36](#) provides the parameter description of 4 MHz to 16 MHz crystals used for the design simulations.

Figure 9. Crystal oscillator and resonator connection scheme

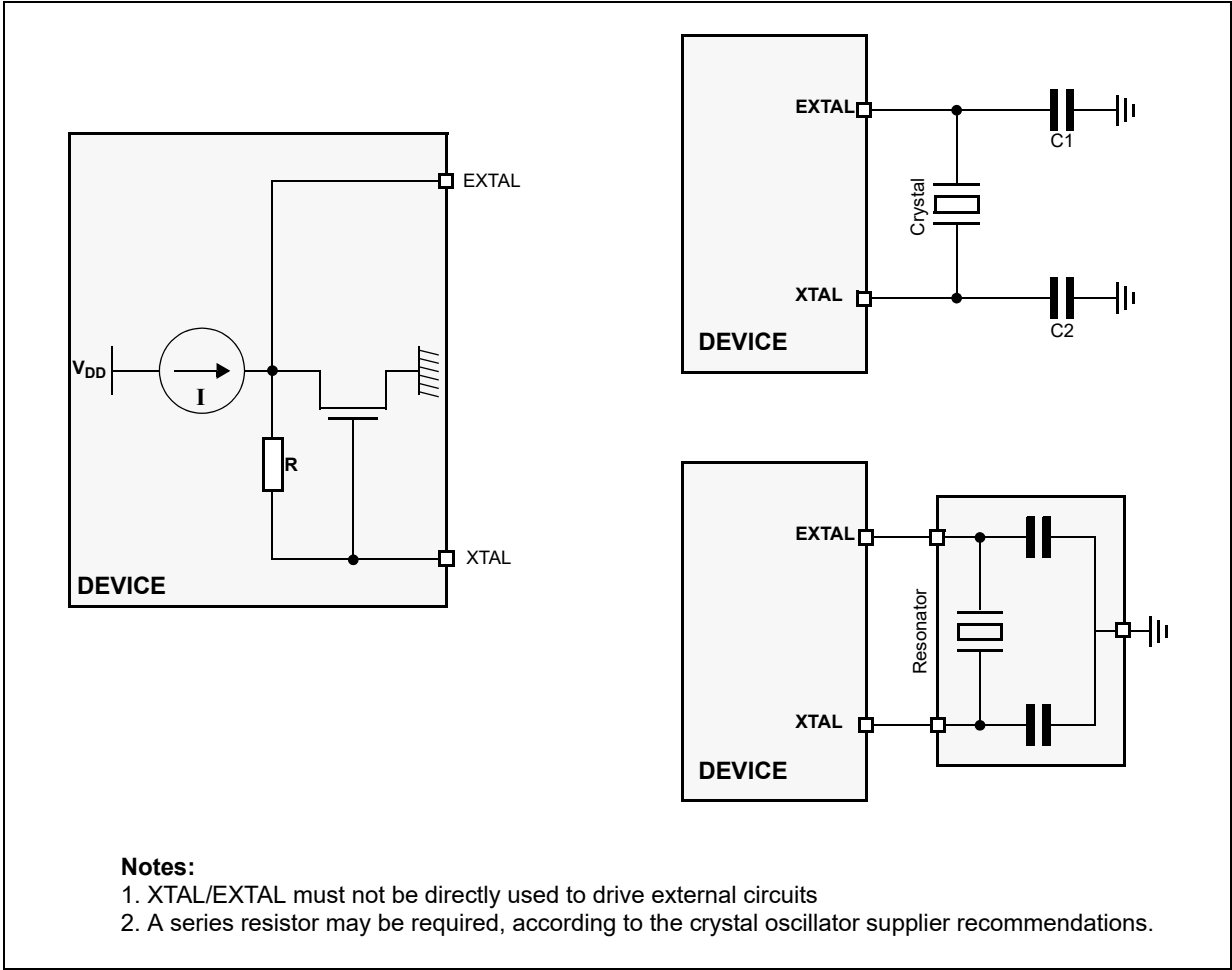


Table 36. Crystal description

| Nominal frequency (MHz) | NDK crystal reference | Crystal equivalent series resistance (ESR) $\Omega$ | Crystal motional capacitance ( $C_m$ ) fF | Crystal motional inductance ( $L_m$ ) mH | Load on xtalín/xtalout $C_1 = C_2$ (pF) <sup>(1)</sup> | Shunt capacitance between xtalout and xtalín $C_0$ <sup>(2)</sup> (pF) |
|-------------------------|-----------------------|-----------------------------------------------------|-------------------------------------------|------------------------------------------|--------------------------------------------------------|------------------------------------------------------------------------|
| 4                       | NX8045GB              | 300                                                 | 2.68                                      | 591.0                                    | 21                                                     | 2.93                                                                   |
| 8                       | NX5032GA              | 300                                                 | 2.46                                      | 160.7                                    | 17                                                     | 3.01                                                                   |
| 10                      |                       | 150                                                 | 2.93                                      | 86.6                                     | 15                                                     | 2.91                                                                   |
| 12                      |                       | 120                                                 | 3.11                                      | 56.5                                     | 15                                                     | 2.93                                                                   |
| 16                      |                       | 120                                                 | 3.90                                      | 25.3                                     | 10                                                     | 3.00                                                                   |

1. The values specified for  $C_1$  and  $C_2$  are the same as used in simulations. It should be ensured that the testing includes all the parasitics (from the board, probe, crystal, etc.) as the AC / transient behavior depends upon them.
2. The value of  $C_0$  specified here includes 2 pF additional capacitance for parasitics (to be seen with bond-pads, package, etc.).

Figure 10. Fast external crystal oscillator (4 to 16 MHz) timing diagram

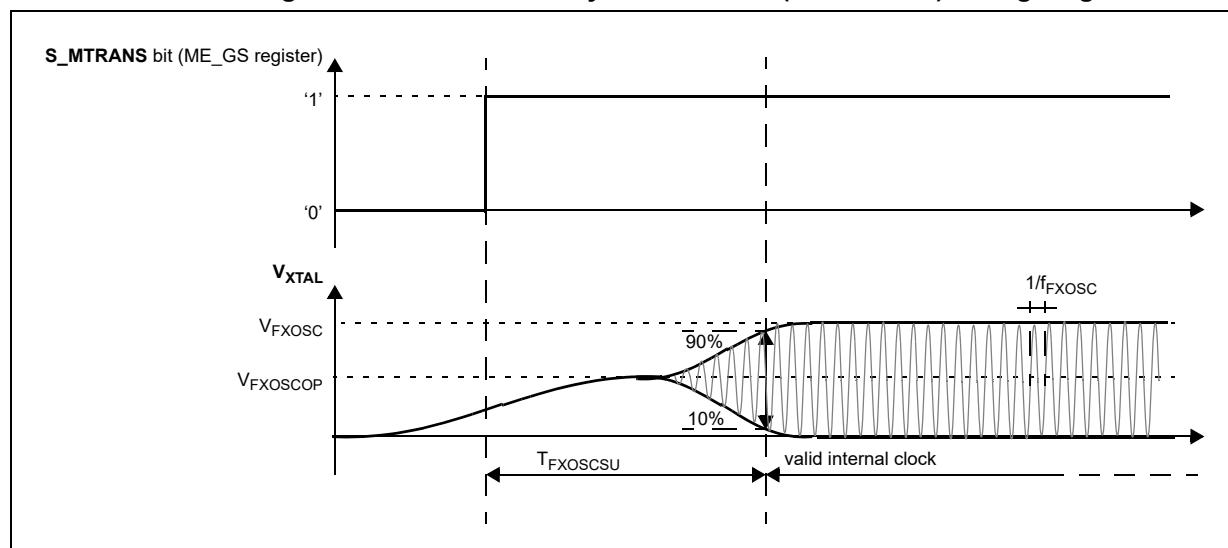


Table 37. Fast external crystal oscillator (4 to 16 MHz) electrical characteristics

| Symbol                            | C  | Parameter | Conditions <sup>(1)</sup>                                              | Value |      |      | Unit |
|-----------------------------------|----|-----------|------------------------------------------------------------------------|-------|------|------|------|
|                                   |    |           |                                                                        | Min   | Typ  | Max  |      |
| f <sub>FXOSC</sub>                | SR | —         | —                                                                      | 4.0   | —    | 16.0 | MHz  |
| g <sub>mFXOSC</sub>               | CC | C         | V <sub>DD</sub> = 3.3 V ± 10%,<br>PAD3V5V = 1<br>OSCILLATOR_MARGIN = 0 | 2.2   | —    | 8.2  | mA/V |
|                                   | CC | P         | V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0<br>OSCILLATOR_MARGIN = 0 | 2.0   | —    | 7.4  |      |
|                                   | CC | C         | V <sub>DD</sub> = 3.3 V ± 10%,<br>PAD3V5V = 1<br>OSCILLATOR_MARGIN = 1 | 2.7   | —    | 9.7  |      |
|                                   | CC | C         | V <sub>DD</sub> = 5.0 V ± 10%,<br>PAD3V5V = 0<br>OSCILLATOR_MARGIN = 1 | 2.5   | —    | 9.2  |      |
| V <sub>FXOSC</sub>                | CC | T         | f <sub>OSC</sub> = 4 MHz,<br>OSCILLATOR_MARGIN = 0                     | 1.3   | —    | —    | V    |
|                                   |    |           | f <sub>OSC</sub> = 16 MHz,<br>OSCILLATOR_MARGIN = 1                    | 1.3   | —    | —    |      |
| V <sub>FXOSCOP</sub>              | CC | P         | Oscillation operating point                                            | —     | 0.95 | —    | V    |
| I <sub>FXOSC</sub> <sup>(2)</sup> | CC | T         | Fast external crystal oscillator consumption                           | —     | 2    | 3    | mA   |

Table 37. Fast external crystal oscillator (4 to 16 MHz) electrical characteristics (continued)

| Symbol               |    | C | Parameter                                      | Conditions <sup>(1)</sup>                           | Value               |     |                      | Unit |
|----------------------|----|---|------------------------------------------------|-----------------------------------------------------|---------------------|-----|----------------------|------|
|                      |    |   |                                                |                                                     | Min                 | Typ | Max                  |      |
| t <sub>FXOSCSU</sub> | CC | T | Fast external crystal oscillator start-up time | f <sub>OSC</sub> = 4 MHz,<br>OSCILLATOR_MARGIN = 0  | —                   | —   | 6                    | ms   |
|                      |    |   |                                                | f <sub>OSC</sub> = 16 MHz,<br>OSCILLATOR_MARGIN = 1 | —                   | —   | 1.8                  |      |
| V <sub>IH</sub>      | SR | P | Input high level CMOS (Schmitt Trigger)        | Oscillator bypass mode                              | 0.65V <sub>DD</sub> | —   | V <sub>DD</sub> +0.4 | V    |
| V <sub>IL</sub>      | SR | P | Input low level CMOS (Schmitt Trigger)         | Oscillator bypass mode                              | −0.4                | —   | 0.35V <sub>DD</sub>  | V    |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = −40 to 125 °C, unless otherwise specified.

2. Stated values take into account only analog module consumption but not the digital contributor (clock tree and enabled peripherals).

## 4.14 FMPLL electrical characteristics

The device provides a frequency-modulated phase-locked loop (FMPLL) module to generate a fast system clock from the main oscillator driver.

Table 38. FMPLL electrical characteristics

| Symbol                          |    | C | Parameter                                       | Conditions <sup>(1)</sup>                                                              | Value |     |     | Unit |
|---------------------------------|----|---|-------------------------------------------------|----------------------------------------------------------------------------------------|-------|-----|-----|------|
|                                 |    |   |                                                 |                                                                                        | Min   | Typ | Max |      |
| f <sub>PLLIN</sub>              | SR | — | FMPLL reference clock <sup>(2)</sup>            | —                                                                                      | 4     | —   | 48  | MHz  |
| Δ <sub>PLLIN</sub>              | SR | — | FMPLL reference clock duty cycle <sup>(2)</sup> | —                                                                                      | 40    | —   | 60  | %    |
| f <sub>PLLOUT</sub>             | CC | D | FMPLL output clock frequency                    | —                                                                                      | 16    | —   | 48  | MHz  |
| f <sub>VCO</sub> <sup>(3)</sup> | CC | P | VCO frequency without frequency modulation      | —                                                                                      | 256   | —   | 512 | MHz  |
|                                 |    |   | VCO frequency with frequency modulation         | —                                                                                      | 245   | —   | 533 |      |
| f <sub>CPU</sub>                | SR | — | System clock frequency                          | —                                                                                      | —     | —   | 48  | MHz  |
| f <sub>FREE</sub>               | CC | P | Free-running frequency                          |                                                                                        | 20    | —   | 150 | MHz  |
| t <sub>LOCK</sub>               | CC | P | FMPLL lock time                                 | Stable oscillator (f <sub>PLLIN</sub> = 16 MHz)                                        | —     | 40  | 100 | μs   |
| Δt <sub>LTJIT</sub>             | CC | — | FMPLL long term jitter                          | f <sub>PLLIN</sub> = 16 MHz (resonator),<br>f <sub>PLLCLK</sub> at 48 MHz, 4000 cycles | —     | —   | 10  | ns   |
| I <sub>PLL</sub>                | CC | C | FMPLL consumption                               | T <sub>A</sub> = 25 °C                                                                 | —     | —   | 4   | mA   |

1. V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = −40 to 125 °C, unless otherwise specified.

2. PLLIN clock retrieved directly from FXOSC clock. Input characteristics are granted when oscillator is used in functional mode. When bypass mode is used, oscillator input clock should verify f<sub>PLLIN</sub> and Δ<sub>PLLIN</sub>.

3. Frequency modulation is considered ±4%.

## 4.15 Fast internal RC oscillator (16 MHz) electrical characteristics

The device provides a 16 MHz fast internal RC oscillator (FIRC). This is used as the default clock at the power-up of the device.

**Table 39. Fast internal RC oscillator (16 MHz) electrical characteristics**

| Symbol                      |    | C | Parameter                                                                                                                                                             | Conditions <sup>(1)</sup>                  | Value           |     |      | Unit          |
|-----------------------------|----|---|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------|-----------------|-----|------|---------------|
|                             |    |   |                                                                                                                                                                       |                                            | Min             | Typ | Max  |               |
| $f_{\text{FIRC}}$           | CC | P | Fast internal RC oscillator high frequency                                                                                                                            | $T_A = 25\text{ }^\circ\text{C}$ , trimmed | —               | 16  | —    | MHz           |
|                             | SR | — |                                                                                                                                                                       | —                                          | 12              | —   | 20   |               |
| $I_{\text{FIRC RUN}}^{(2)}$ | CC | T | Fast internal RC oscillator high frequency current in running mode                                                                                                    | $T_A = 25\text{ }^\circ\text{C}$ , trimmed | —               | —   | 200  | $\mu\text{A}$ |
| $I_{\text{FIRC PWD}}$       | CC | D | Fast internal RC oscillator high frequency current in power down mode                                                                                                 | $T_A = 25\text{ }^\circ\text{C}$           | —               | —   | 10   | $\mu\text{A}$ |
| $I_{\text{FIRC STOP}}$      | CC | T | Fast internal RC oscillator high frequency and system clock current in stop mode                                                                                      | $T_A = 25\text{ }^\circ\text{C}$           | sysclk = off    | —   | 500  | $\mu\text{A}$ |
|                             |    |   |                                                                                                                                                                       |                                            | sysclk = 2 MHz  | —   | 600  |               |
|                             |    |   |                                                                                                                                                                       |                                            | sysclk = 4 MHz  | —   | 700  |               |
|                             |    |   |                                                                                                                                                                       |                                            | sysclk = 8 MHz  | —   | 900  |               |
|                             |    |   |                                                                                                                                                                       |                                            | sysclk = 16 MHz | —   | 1250 |               |
| $t_{\text{FIRC SU}}$        | CC | C | Fast internal RC oscillator start-up time                                                                                                                             | $V_{\text{DD}} = 5.0\text{ V} \pm 10\%$    | —               | 1.1 | 2.0  | $\mu\text{s}$ |
| $\Delta_{\text{FIRC PRE}}$  | CC | C | Fast internal RC oscillator precision after software trimming of $f_{\text{FIRC}}$                                                                                    | $T_A = 25\text{ }^\circ\text{C}$           | −1              | —   | 1    | %             |
| $\Delta_{\text{FIRC TRIM}}$ | CC | C | Fast internal RC oscillator trimming step                                                                                                                             | $T_A = 25\text{ }^\circ\text{C}$           | —               | 1.6 | —    | %             |
| $\Delta_{\text{FIRC VAR}}$  | CC | C | Fast internal RC oscillator variation in temperature and supply with respect to $f_{\text{FIRC}}$ at $T_A = 55\text{ }^\circ\text{C}$ in high-frequency configuration | —                                          | −5              | —   | 5    | %             |

1.  $V_{\text{DD}} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40\text{ to }125\text{ }^\circ\text{C}$ , unless otherwise specified.

2. This does not include consumption linked to clock tree toggling and peripherals consumption when RC oscillator is ON.

## 4.16 Slow internal RC oscillator (128 kHz) electrical characteristics

The device provides a 128 kHz slow internal RC oscillator (SIRC). This can be used as the reference clock for the RTC module.

Table 40. Slow internal RC oscillator (128 kHz) electrical characteristics

| Symbol             | C  | Parameter                                 | Conditions <sup>(1)</sup>                                                                                                                                | Value                                                                 |     |     | Unit          |
|--------------------|----|-------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------|-----|-----|---------------|
|                    |    |                                           |                                                                                                                                                          | Min                                                                   | Typ | Max |               |
| $f_{SIRC}$         | CC | Slow internal RC oscillator low frequency | $T_A = 25\text{ }^{\circ}\text{C}$ , trimmed                                                                                                             | —                                                                     | 128 | —   | kHz           |
|                    | SR |                                           | —                                                                                                                                                        | 100                                                                   | —   | 150 |               |
| $I_{SIRC}^{(2)}$   | CC | C                                         | Slow internal RC oscillator low frequency current                                                                                                        | $T_A = 25\text{ }^{\circ}\text{C}$ , trimmed                          | —   | 5   | $\mu\text{A}$ |
| $t_{SIRCSU}$       | CC | P                                         | Slow internal RC oscillator start-up time                                                                                                                | $T_A = 25\text{ }^{\circ}\text{C}$ , $V_{DD} = 5.0\text{ V} \pm 10\%$ | 8   | 12  | $\mu\text{s}$ |
| $\Delta_{SIRCPRE}$ | CC | C                                         | Slow internal RC oscillator precision after software trimming of $f_{SIRC}$                                                                              | $T_A = 25\text{ }^{\circ}\text{C}$                                    | —2  | 2   | %             |
| $\Delta_{SIRCTRM}$ | CC | C                                         | Slow internal RC oscillator trimming step                                                                                                                | —                                                                     | 2.7 | —   |               |
| $\Delta_{SIRCVAR}$ | CC | P                                         | Slow internal RC oscillator variation in temperature and supply with respect to $f_{SIRC}$ at $T_A = 55^{\circ}\text{C}$ in high frequency configuration | High frequency configuration                                          | —10 | 10  | %             |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40\text{ to }125\text{ }^{\circ}\text{C}$ , unless otherwise specified.

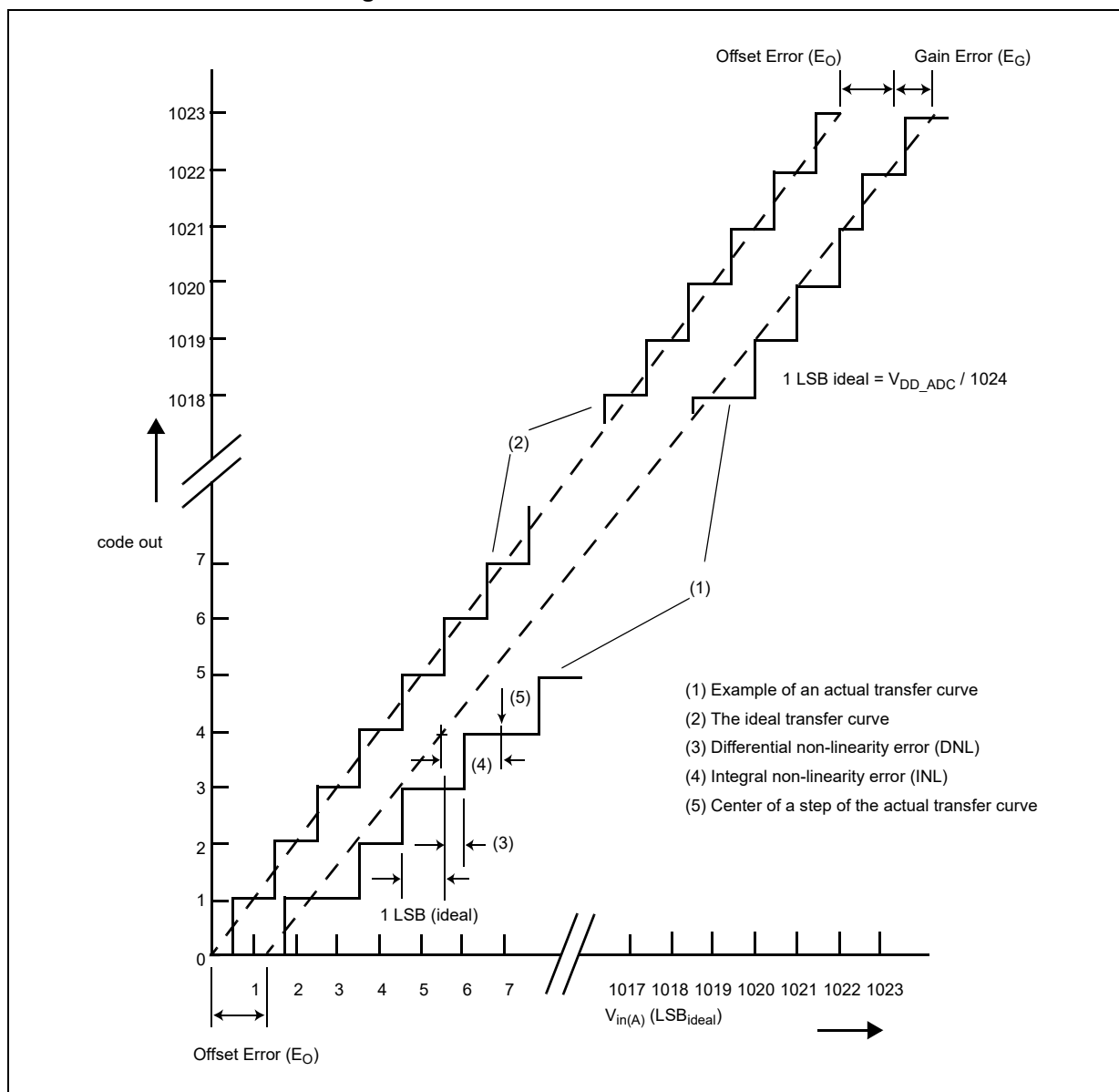
2. This does not include consumption linked to clock tree toggling and peripherals consumption when RC oscillator is ON.

## 4.17 ADC electrical characteristics

### 4.17.1 Introduction

The device provides a 12-bit Successive Approximation Register (SAR) analog-to-digital converter.

Figure 11. ADC characteristics and error definitions



#### 4.17.2 Input impedance and ADC accuracy

In the following analysis, the input circuit corresponding to the precise channels is considered.

To preserve the accuracy of the A/D converter, it is necessary that analog input pins have low AC impedance. Placing a capacitor with good high frequency characteristics at the input pin of the device can be effective: the capacitor should be as large as possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; furthermore, it sources charge during the sampling phase, when the analog signal source is a high-impedance source.

A real filter can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC filter). The RC filtering may be limited according to the value of source



impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: being  $C_S$  and  $C_{p2}$  substantially two switched capacitances, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive path to ground. For instance, assuming a conversion rate of 1 MHz, with  $C_S + C_{p2}$  equal to 3 pF, a resistance of 330 k $\Omega$  is obtained ( $R_{EQ} = 1 / (f_c \times (C_S + C_{p2}))$ ), where  $f_c$  represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on  $C_S + C_{p2}$ ) and the sum of  $R_S + R_F$ , the external circuit must be designed to respect the [Equation 4](#):

#### Equation 4

$$V_A \cdot \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} \text{ LSB}$$

[Equation 4](#) generates a constraint for external network design, in particular on a resistive path.

Figure 12. Input equivalent circuit (precise channels)

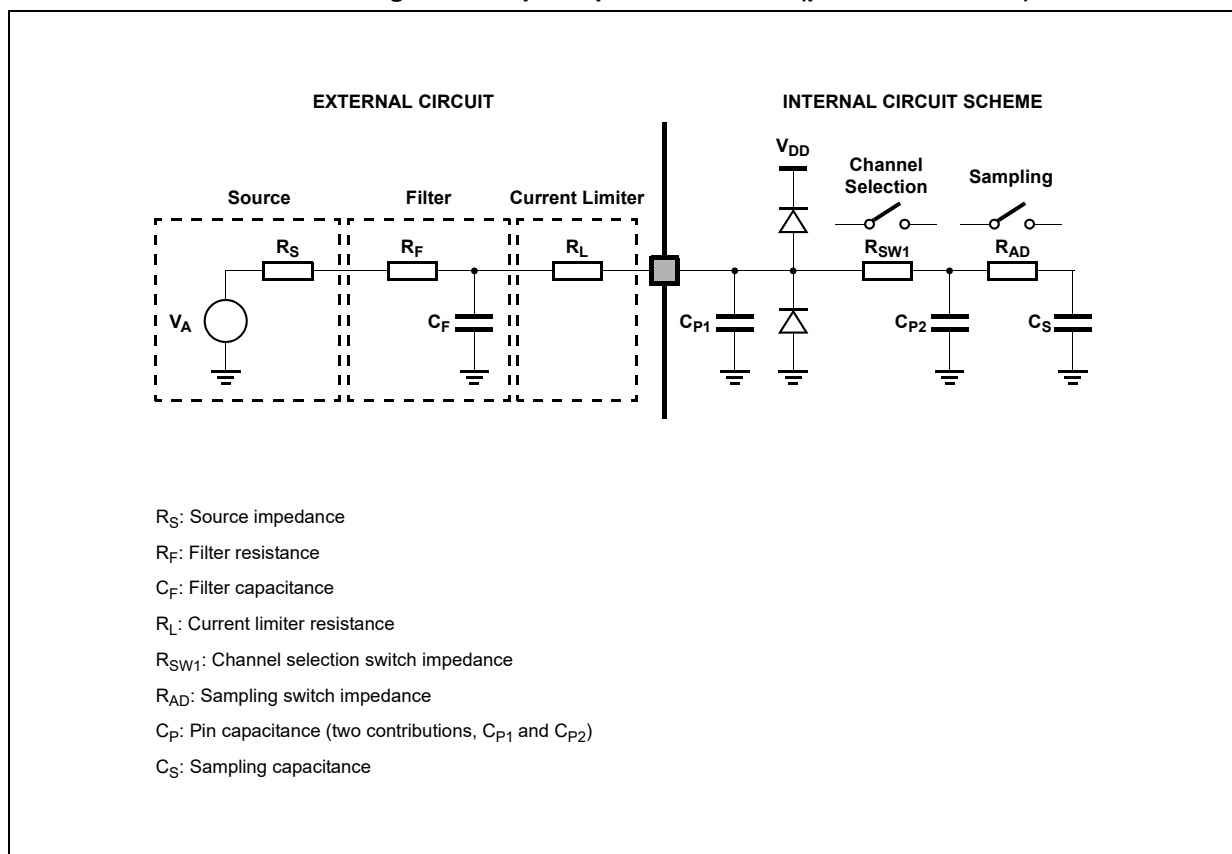
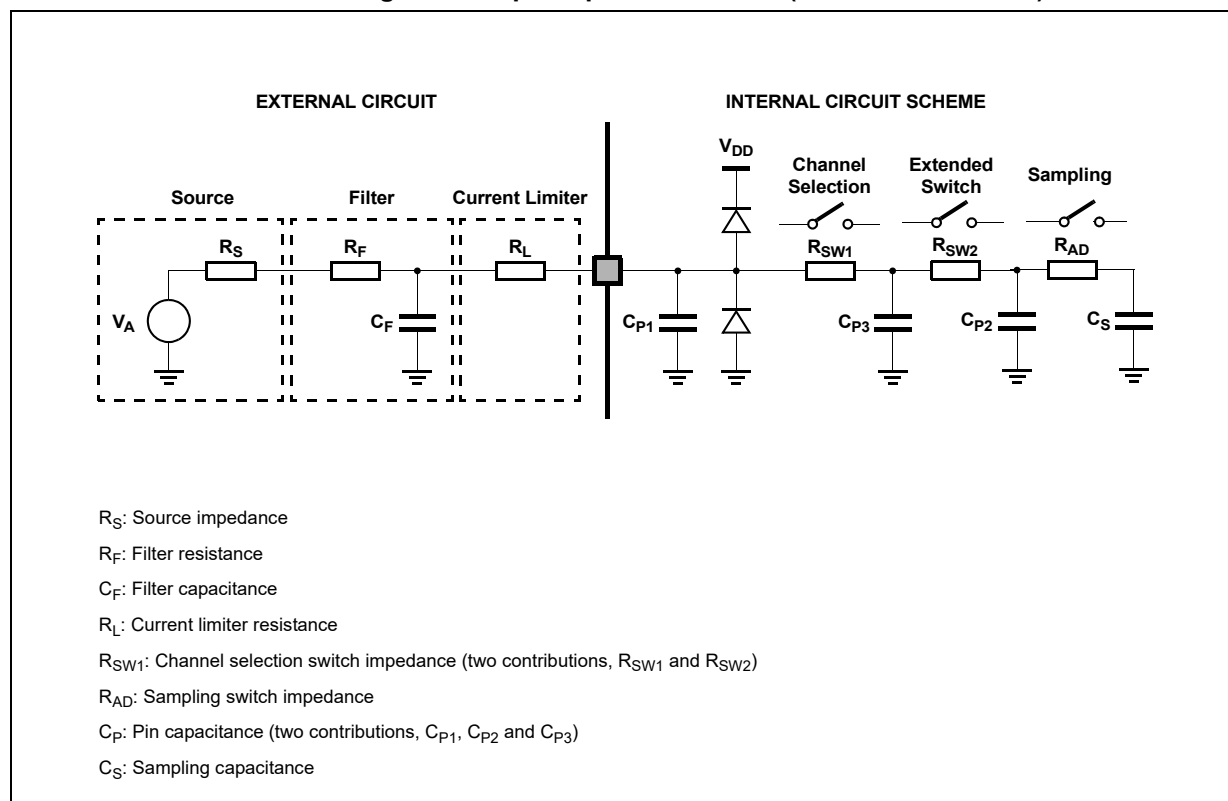
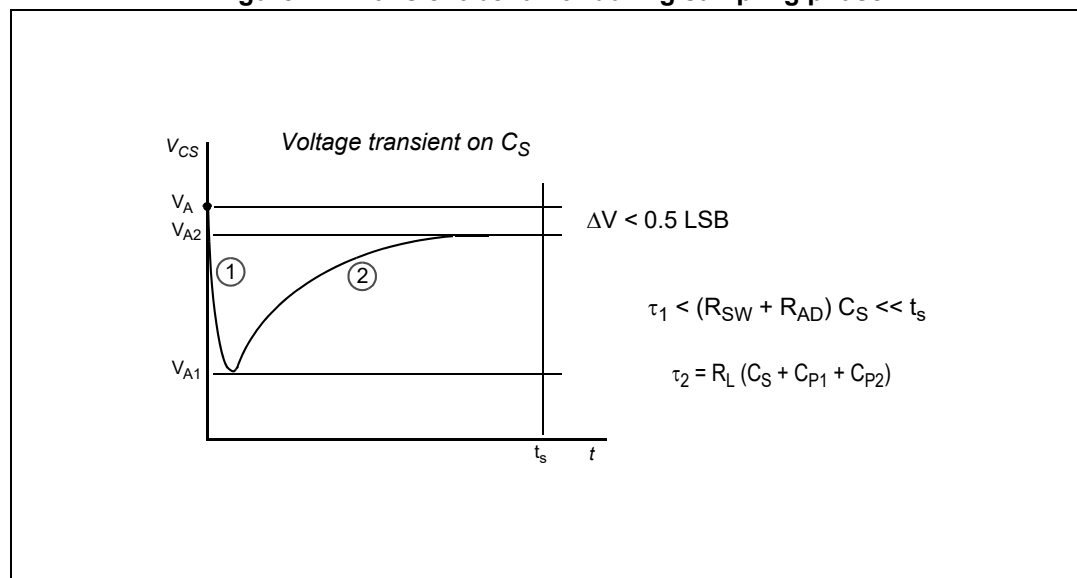


Figure 13. Input equivalent circuit (extended channels)



A second aspect involving the capacitance network shall be considered. Assuming the three capacitances  $C_F$ ,  $C_{P1}$  and  $C_{P2}$  are initially charged at the source voltage  $V_A$  (refer to the equivalent circuit in [Figure 13](#)): A charge sharing phenomenon is installed when the sampling phase is started (A/D switch close).

Figure 14. Transient behavior during sampling phase



In particular two different transient periods can be distinguished:

1. A first and quick charge transfer from the internal capacitance  $C_{P1}$  and  $C_{P2}$  to the sampling capacitance  $C_S$  occurs ( $C_S$  is supposed initially completely discharged): considering a worst case (since the time constant in reality would be faster) in which  $C_{P2}$  is reported in parallel to  $C_{P1}$  (call  $C_P = C_{P1} + C_{P2}$ ), the two capacitances  $C_P$  and  $C_S$  are in series, and the time constant is

**Equation 5**

$$\tau_1 = (R_{SW} + R_{AD}) \cdot \frac{C_P \cdot C_S}{C_P + C_S}$$

[Equation 5](#) can again be simplified considering only  $C_S$  as an additional worst condition. In reality, the transient is faster, but the A/D converter circuitry has been designed to be robust also in the very worst case: the sampling time  $t_s$  is always much longer than the internal time constant:

**Equation 6**

$$\tau_1 < (R_{SW} + R_{AD}) \cdot C_S \ll t_s$$

The charge of  $C_{P1}$  and  $C_{P2}$  is redistributed also on  $C_S$ , determining a new value of the voltage  $V_{A1}$  on the capacitance according to the [Equation 7](#):

**Equation 7**

$$V_{A1} \cdot (C_S + C_{P1} + C_{P2}) = V_A \cdot (C_{P1} + C_{P2})$$

2. A second charge transfer involves also  $C_F$  (that is typically bigger than the on-chip capacitance) through the resistance  $R_L$ : again considering the worst case in which  $C_{P2}$  and  $C_S$  were in parallel to  $C_{P1}$  (since the time constant in reality would be faster), the time constant is:

**Equation 8**

$$\tau_2 < R_L \cdot (C_S + C_{P1} + C_{P2})$$

In this case, the time constant depends on the external circuit: in particular imposing that the transient is completed well before the end of sampling time  $t_s$ , a constraints on  $R_L$  sizing is obtained:

**Equation 9**

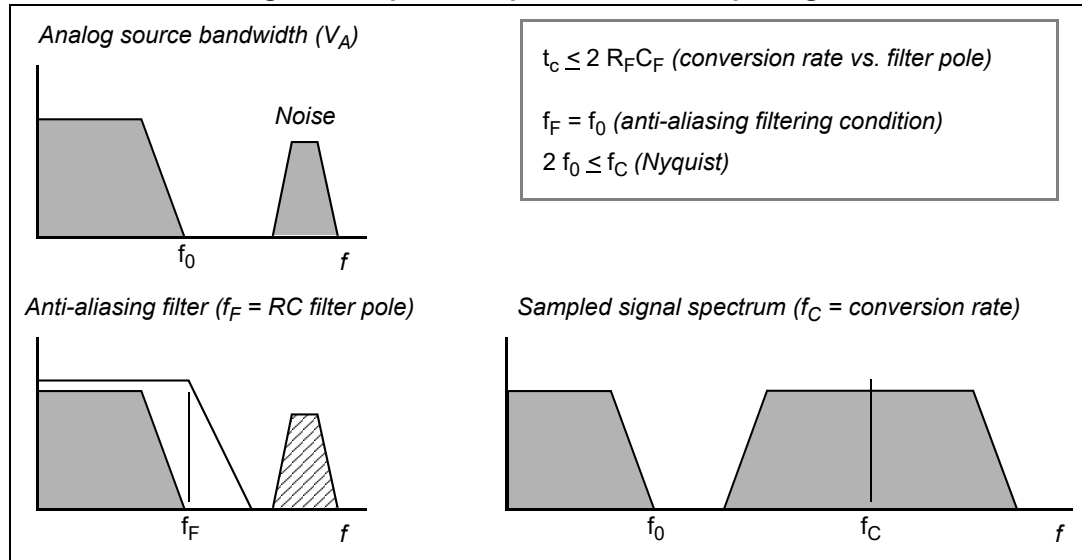
$$10 \cdot \tau_2 = 10 \cdot R_L \cdot (C_S + C_{P1} + C_{P2}) < t_s$$

Of course,  $R_L$  shall be sized also according to the current limitation constraints, in combination with  $R_S$  (source impedance) and  $R_F$  (filter resistance). Being  $C_F$  definitively bigger than  $C_{P1}$ ,  $C_{P2}$  and  $C_S$ , then the final voltage  $V_{A2}$  (at the end of the charge transfer transient) will be much higher than  $V_{A1}$ . [Equation 10](#) must be respected (charge balance assuming now  $C_S$  already charged at  $V_{A1}$ ):

**Equation 10**

$$V_{A2} \cdot (C_S + C_{P1} + C_{P2} + C_F) = V_A \cdot C_F + V_{A1} \cdot (C_{P1} + C_{P2} + C_S)$$

The two transients above are not influenced by the voltage source that, due to the presence of the  $R_F C_F$  filter, is not able to provide the extra charge to compensate the voltage drop on  $C_S$  with respect to the ideal source  $V_A$ ; the time constant  $R_F C_F$  of the filter is very high with respect to the sampling time ( $t_s$ ). The filter is typically designed to act as anti-aliasing.

**Figure 15. Spectral representation of input signal**

Calling  $f_0$  the bandwidth of the source signal (and as a consequence the cut-off frequency of the anti-aliasing filter,  $f_F$ ), according to the Nyquist theorem the conversion rate  $f_C$  must be at least  $2f_0$ ; it means that the constant time of the filter is greater than or at least equal to twice the conversion period ( $t_c$ ). Again the conversion period  $t_c$  is longer than the sampling time  $t_s$ , which is just a portion of it, even when fixed channel continuous conversion mode is selected (fastest conversion rate at a specific channel): in conclusion it is evident that the time constant of the filter  $R_F C_F$  is definitively much higher than the sampling time  $t_s$ , so the charge level on  $C_S$  cannot be modified by the analog signal source during the time in which the sampling switch is closed.

The considerations above lead to impose new constraints on the external circuit, to reduce the accuracy error due to the voltage drop on  $C_S$ ; from the two charge balance equations above, it is simple to derive [Equation 11](#) between the ideal and real sampled voltage on  $C_S$ :

**Equation 11**

$$\frac{V_{A2}}{V_A} = \frac{C_{P1} + C_{P2} + C_F}{C_{P1} + C_{P2} + C_F + C_S}$$

From this formula, in the worst case (when  $V_A$  is maximum, that is for instance 5 V), assuming to accept a maximum error of half a count, a constraint is evident on  $C_F$  value:

**Equation 12**

$$C_F > 2048 \cdot C_S$$

## 4.17.3 ADC electrical characteristics

Table 41. ADC input leakage current

| Symbol           | C  | Parameter             | Conditions              | Value |     |     | Unit |
|------------------|----|-----------------------|-------------------------|-------|-----|-----|------|
|                  |    |                       |                         | Min   | Typ | Max |      |
| I <sub>LKG</sub> | CC | Input leakage current | T <sub>A</sub> = -40 °C | —     | 1   | —   | nA   |
|                  |    |                       | T <sub>A</sub> = 25 °C  | —     | 1   | —   |      |
|                  |    |                       | T <sub>A</sub> = 105 °C | —     | 8   | 200 |      |
|                  |    |                       | T <sub>A</sub> = 125 °C | —     | 45  | 400 |      |

Table 42. ADC conversion characteristics

| Symbol               |    | C | Parameter                                                                                          | Conditions <sup>(1)</sup>                     | Value                     |     |                           | Unit |
|----------------------|----|---|----------------------------------------------------------------------------------------------------|-----------------------------------------------|---------------------------|-----|---------------------------|------|
|                      |    |   |                                                                                                    |                                               | Min                       | Typ | Max                       |      |
| V <sub>SS_ADC</sub>  | SR | — | Voltage on VSS_HV_ADC (ADC reference) pin with respect to ground (V <sub>SS</sub> ) <sup>(2)</sup> | —                                             | −0.1                      | —   | 0.1                       | V    |
| V <sub>DD_ADC</sub>  | SR | — | Voltage on VDD_HV_ADC pin (ADC reference) with respect to ground (V <sub>SS</sub> )                | —                                             | V <sub>DD</sub> − 0.1     | —   | V <sub>DD</sub> + 0.1     | V    |
| V <sub>AINx</sub>    | SR | — | Analog input voltage <sup>(3)</sup>                                                                | —                                             | V <sub>SS_ADC</sub> − 0.1 | —   | V <sub>DD_ADC</sub> + 0.1 | V    |
| f <sub>ADC</sub>     | SR | — | ADC analog frequency                                                                               | V <sub>DD</sub> = 5.0 V                       | 3.33                      | —   | 32 + 4%                   | MHz  |
|                      |    |   |                                                                                                    | V <sub>DD</sub> = 3.3 V                       | 3.33                      | —   | 20 + 4%                   |      |
| Δ <sub>ADC_SYS</sub> | SR | — | ADC clock duty cycle (ipg_clk)                                                                     | ADCLKSEL = 1 <sup>(4)</sup>                   | 45                        | —   | 55                        | %    |
| t <sub>ADC_PU</sub>  | SR | — | ADC power up delay                                                                                 | —                                             | —                         | —   | 1.5                       | μs   |
| t <sub>s</sub>       | CC | T | Sampling time <sup>(5)</sup><br>V <sub>DD</sub> = 3.3 V                                            | f <sub>ADC</sub> = 20 MHz,<br>INPSAMP = 12    | 600                       | —   | —                         | ns   |
|                      |    |   |                                                                                                    | f <sub>ADC</sub> = 3.33 MHz,<br>INPSAMP = 255 | —                         | —   | 76.2                      | μs   |
|                      |    | T | Sampling time <sup>(5)</sup><br>V <sub>DD</sub> = 5.0 V                                            | f <sub>ADC</sub> = 24 MHz,<br>INPSAMP = 13    | 500                       | —   | —                         | ns   |
|                      |    |   |                                                                                                    | f <sub>ADC</sub> = 3.33 MHz,<br>INPSAMP = 255 | —                         | —   | 76.2                      | μs   |

Table 42. ADC conversion characteristics (continued)

| Symbol    | C  | Parameter | Conditions <sup>(1)</sup>                                 |                                                                      | Value                            |     |     | Unit          |
|-----------|----|-----------|-----------------------------------------------------------|----------------------------------------------------------------------|----------------------------------|-----|-----|---------------|
|           |    |           |                                                           |                                                                      | Min                              | Typ | Max |               |
| $t_c$     | CC | P         | Conversion time <sup>(6)</sup><br>$V_{DD} = 3.3\text{ V}$ | $f_{ADC} = 20\text{ MHz}$ ,<br>INPCMP = 0                            | 2.4                              | —   | —   | $\mu\text{s}$ |
|           |    |           |                                                           | $f_{ADC} = 13.33\text{ MHz}$ ,<br>INPCMP = 0                         | —                                | —   | 3.6 |               |
|           |    | P         | Conversion time <sup>(6)</sup><br>$V_{DD} = 5.0\text{ V}$ | $f_{ADC} = 32\text{ MHz}$ ,<br>INPCMP = 0                            | 1.5                              | —   | —   | $\mu\text{s}$ |
|           |    |           |                                                           | $f_{ADC} = 13.33\text{ MHz}$ ,<br>INPCMP = 0                         | —                                | —   | 3.6 |               |
| $C_S$     | CC | D         | ADC input sampling capacitance                            | —                                                                    | 5                                |     |     | pF            |
| $C_{P1}$  | CC | D         | ADC input pin capacitance 1                               | —                                                                    | 3                                |     |     | pF            |
| $C_{P2}$  | CC | D         | ADC input pin capacitance 2                               | —                                                                    | 1                                |     |     | pF            |
| $C_{P3}$  | CC | D         | ADC input pin capacitance 3                               | —                                                                    | 1.5                              |     |     | pF            |
| $R_{SW1}$ | CC | D         | Internal resistance of analog source                      | —                                                                    | —                                | —   | 1   | k $\Omega$    |
| $R_{SW2}$ | CC | D         | Internal resistance of analog source                      | —                                                                    | —                                | —   | 2   | k $\Omega$    |
| $R_{AD}$  | CC | D         | Internal resistance of analog source                      | —                                                                    | —                                | —   | 0.3 | k $\Omega$    |
| $I_{INJ}$ | SR | —         | Input current injection                                   | Current injection on one ADC input, different from the converted one | $V_{DD} = 3.3\text{ V} \pm 10\%$ | —   | 5   | mA            |
|           |    |           |                                                           |                                                                      | $V_{DD} = 5.0\text{ V} \pm 10\%$ | —   | 5   |               |
| INLP      | CC | T         | Absolute integral non-linearity-precise channels          | No overload                                                          | —                                | 1   | 3   | LSB           |
| INLX      | CC | T         | Absolute integral non-linearity-extended channels         | No overload                                                          | —                                | 1.5 | 5   | LSB           |
| DNL       | CC | T         | Absolute differential non-linearity                       | No overload                                                          | —                                | 0.5 | 1   | LSB           |
| $E_O$     | CC | T         | Absolute offset error                                     | —                                                                    | —                                | 2   | —   | LSB           |
| $E_G$     | CC | T         | Absolute gain error                                       | —                                                                    | —                                | 2   | —   | LSB           |

1.  $V_{DD} = 3.3\text{ V} \pm 10\% / 5.0\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125\text{ }^\circ\text{C}$ , unless otherwise specified.

2. Analog and digital  $V_{SS}$  **must** be common (to be tied together externally).
3.  $V_{AINx}$  may exceed  $V_{SS\_ADC}$  and  $V_{DD\_ADC}$  limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0xFF.
4. Duty cycle is ensured by using system clock without prescaling. When ADCLKSEL = 0, the duty cycle is ensured by internal divider by 2.
5. During the sampling time the input capacitance  $C_S$  can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within  $t_S$ . After the end of the sampling time  $t_S$ , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock  $t_S$  depend on programming.
6. This parameter does not include the sampling time  $t_S$ , but only the time for determining the digital result and the time to load the result's register with the conversion result.

## 4.18 On-chip peripherals

### 4.18.1 Current consumption

Table 43. On-chip peripherals current consumption

| Symbol                    |    | C | Parameter                                          | Conditions                                                                                                                       |                                                                                                                                                               | Typical value <sup>(1)</sup> | Unit |
|---------------------------|----|---|----------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------|------|
| I <sub>DD_BV(CAN)</sub>   | CC | T | CAN (FlexCAN) supply current on V <sub>DD_BV</sub> | 500 Kbyte/s                                                                                                                      | Total (static + dynamic) consumption:<br>– FlexCAN in loop-back mode<br>– XTAL at 8 MHz used as CAN engine clock source<br>– Message sending period is 580 μs | 8 × f <sub>periph</sub> + 85 | μA   |
|                           |    |   |                                                    | 125 Kbyte/s                                                                                                                      |                                                                                                                                                               | 8 × f <sub>periph</sub> + 27 | μA   |
| I <sub>DD_BV(eMIOS)</sub> | CC | T | eMIOS supply current on V <sub>DD_BV</sub>         | Static consumption:<br>– eMIOS channel OFF<br>– Global prescaler enabled                                                         |                                                                                                                                                               | 29 × f <sub>periph</sub>     | μA   |
|                           |    |   |                                                    | Dynamic consumption:<br>– It does not change varying the frequency (0.003 mA)                                                    |                                                                                                                                                               | 3                            | μA   |
| I <sub>DD_BV(SCI)</sub>   | CC | T | SCI (LINFlex) supply current on V <sub>DD_BV</sub> | Total (static + dynamic) consumption:<br>– LIN mode<br>– Baudrate: 20 Kbyte/s                                                    |                                                                                                                                                               | 5 × f <sub>periph</sub> + 31 | μA   |
| I <sub>DD_BV(SPI)</sub>   | CC | T | SPI (DSPI) supply current on V <sub>DD_BV</sub>    | Ballast static consumption (only clocked)                                                                                        |                                                                                                                                                               | 1                            | μA   |
|                           |    |   |                                                    | Ballast dynamic consumption (continuous communication):<br>– Baudrate: 2 Mbit/s<br>– Transmission every 8 μs<br>– Frame: 16-bits |                                                                                                                                                               | 16 × f <sub>periph</sub>     | μA   |
| I <sub>DD_BV(ADC)</sub>   | CC | T | ADC supply current on V <sub>DD_BV</sub>           | V <sub>DD</sub> = 5.5 V                                                                                                          | Ballast static consumption (no conversion)                                                                                                                    | 41 × f <sub>periph</sub>     | μA   |
|                           |    |   |                                                    |                                                                                                                                  | Ballast dynamic consumption (continuous conversion) <sup>(2)</sup>                                                                                            | 5 × f <sub>periph</sub>      | μA   |

Table 43. On-chip peripherals current consumption (continued)

| Symbol                      |    | C | Parameter                                            | Conditions              |                                                    | Typical value <sup>(1)</sup>  | Unit |
|-----------------------------|----|---|------------------------------------------------------|-------------------------|----------------------------------------------------|-------------------------------|------|
| I <sub>DD_HV_ADC(ADC)</sub> | CC | T | ADC supply current on V <sub>DD_HV_ADC</sub>         | V <sub>DD</sub> = 5.5 V | Analog static consumption (no conversion)          | 2 × f <sub>periph</sub>       | μA   |
|                             |    |   |                                                      |                         | Analog dynamic consumption (continuous conversion) | 75 × f <sub>periph</sub> + 32 | μA   |
| I <sub>DD_HV(FLASH)</sub>   | CC | T | CFlash + DFlash supply current on V <sub>DD_HV</sub> | V <sub>DD</sub> = 5.5 V | —                                                  | 8.21                          | mA   |
| I <sub>DD_HV(PLL)</sub>     | CC | T | PLL supply current on V <sub>DD_HV</sub>             | V <sub>DD</sub> = 5.5 V | —                                                  | 30 × f <sub>periph</sub>      | μA   |

1.  $f_{periph}$  is an absolute value.

2. During the conversion, the total current consumption is given from the sum of the static and dynamic consumption, i.e.,  $(41 + 5) \times f_{periph}$ .

Note: Operating conditions:  $T_A = 25\text{ }^\circ\text{C}$ ,  $f_{periph} = 8\text{ MHz to }48\text{ MHz}$

#### 4.18.2 DSPI characteristics

Table 44. DSPI characteristics

| No. | Symbol             |    | C | Parameter                                                                                        |                        | DSPI0/DSPI1      |             |                    | Unit |
|-----|--------------------|----|---|--------------------------------------------------------------------------------------------------|------------------------|------------------|-------------|--------------------|------|
|     |                    |    |   |                                                                                                  |                        | Min              | Typ         | Max                |      |
| 1   | $t_{SCK}$          | SR | D | SCK cycle time                                                                                   | Master mode (MTFE = 0) | 125              | —           | —                  | ns   |
|     |                    |    | D |                                                                                                  | Slave mode (MTFE = 0)  | 125              | —           | —                  |      |
|     |                    |    | D |                                                                                                  | Master mode (MTFE = 1) | 83               | —           | —                  |      |
|     |                    |    | D |                                                                                                  | Slave mode (MTFE = 1)  | 83               | —           | —                  |      |
| —   | $f_{DSPI}$         | SR | D | DSPI digital controller frequency                                                                |                        | —                | —           | $f_{CPU}$          | MHz  |
| —   | $\Delta t_{CSC}$   | CC | D | Internal delay between pad associated to SCK and pad associated to CSn in master mode            | Master mode            | —                | —           | 130 <sup>(1)</sup> | ns   |
| —   | $\Delta t_{ASC}$   | CC | D | Internal delay between pad associated to SCK and pad associated to CSn in master mode for CSn1→1 | Master mode            | —                | —           | 130 <sup>(1)</sup> | ns   |
| 2   | $t_{CSCext}^{(2)}$ | SR | D | CS to SCK delay                                                                                  | Slave mode             | 32               | —           | —                  | ns   |
| 3   | $t_{ASCext}^{(3)}$ | SR | D | After SCK delay                                                                                  | Slave mode             | $1/f_{DSPI} + 5$ | —           | —                  | ns   |
| 4   | $t_{SDC}$          | CC | D | SCK duty cycle                                                                                   | Master mode            | —                | $t_{SCK}/2$ | —                  | ns   |
|     |                    | SR | D |                                                                                                  | Slave mode             | $t_{SCK}/2$      | —           | —                  |      |



Table 44. DSPI characteristics (continued)

| No. | Symbol          | C  | D | Parameter                  | DSPI0/DSPI1 |                          |     | Unit |
|-----|-----------------|----|---|----------------------------|-------------|--------------------------|-----|------|
|     |                 |    |   |                            | Min         | Typ                      | Max |      |
| 5   | $t_A$           | SR | D | Slave access time          | —           | $1/f_{\text{DSPI}} + 70$ | —   | ns   |
| 6   | $t_{DI}$        | SR | D | Slave SOUT disable time    | —           | 7                        | —   | ns   |
| 7   | $t_{PCSC}$      | SR | D | PCSx to PCSS time          | —           | 0                        | —   | ns   |
| 8   | $t_{PASC}$      | SR | D | PCSS to PCSx time          | —           | 0                        | —   | ns   |
| 9   | $t_{SUI}$       | SR | D | Data setup time for inputs | Master mode | 43                       | —   | ns   |
|     |                 |    |   |                            | Slave mode  | 5                        | —   |      |
| 10  | $t_{HI}$        | SR | D | Data hold time for inputs  | Master mode | 0                        | —   | ns   |
|     |                 |    |   |                            | Slave mode  | 2 <sup>(4)</sup>         | —   |      |
| 11  | $t_{SUO}^{(5)}$ | CC | D | Data valid after SCK edge  | Master mode | —                        | —   | ns   |
|     |                 |    |   |                            | Slave mode  | —                        | —   |      |
| 12  | $t_{HO}^{(5)}$  | CC | D | Data hold time for outputs | Master mode | 0                        | —   | ns   |
|     |                 |    |   |                            | Slave mode  | 8                        | —   |      |

1. Maximum is reached when CSn pad is configured as SLOW pad while SCK pad is configured as MEDIUM pad.
2. The  $t_{CSC}$  delay value is configurable through a register. When configuring  $t_{CSC}$  (using PCSSCK and CSSCK fields in DSPI\_CTARx registers), delay between internal CS and internal SCK must be higher than  $\Delta t_{CSC}$  to ensure positive  $t_{CSCext}$ .
3. The  $t_{ASC}$  delay value is configurable through a register. When configuring  $t_{ASC}$  (using PASC and ASC fields in DSPI\_CTARx registers), delay between internal CS and internal SCK must be higher than  $\Delta t_{ASC}$  to ensure positive  $t_{ASCext}$ .
4. This delay value corresponds to SMPL\_PT = 00b which is bit field 9 and 8 of DSPI\_MCR.
5. SCK and SOUT configured as MEDIUM pad.

**Note:** Operating conditions:  $C_{OUT} = 10$  to  $50$  pF,  $Slew_{IN} = 3.5$  to  $15$  ns

Figure 16. DSPI classic SPI timing – master, CPHA = 0

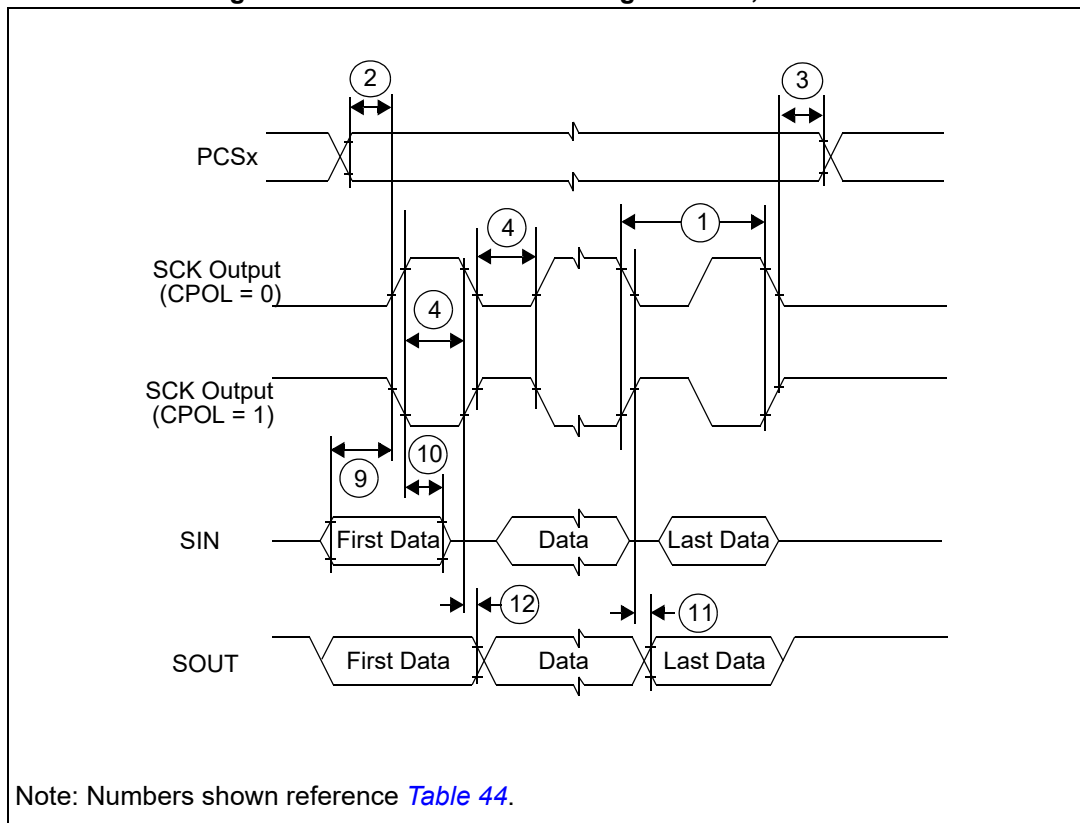


Figure 17. DSPI classic SPI timing – master, CPHA = 1

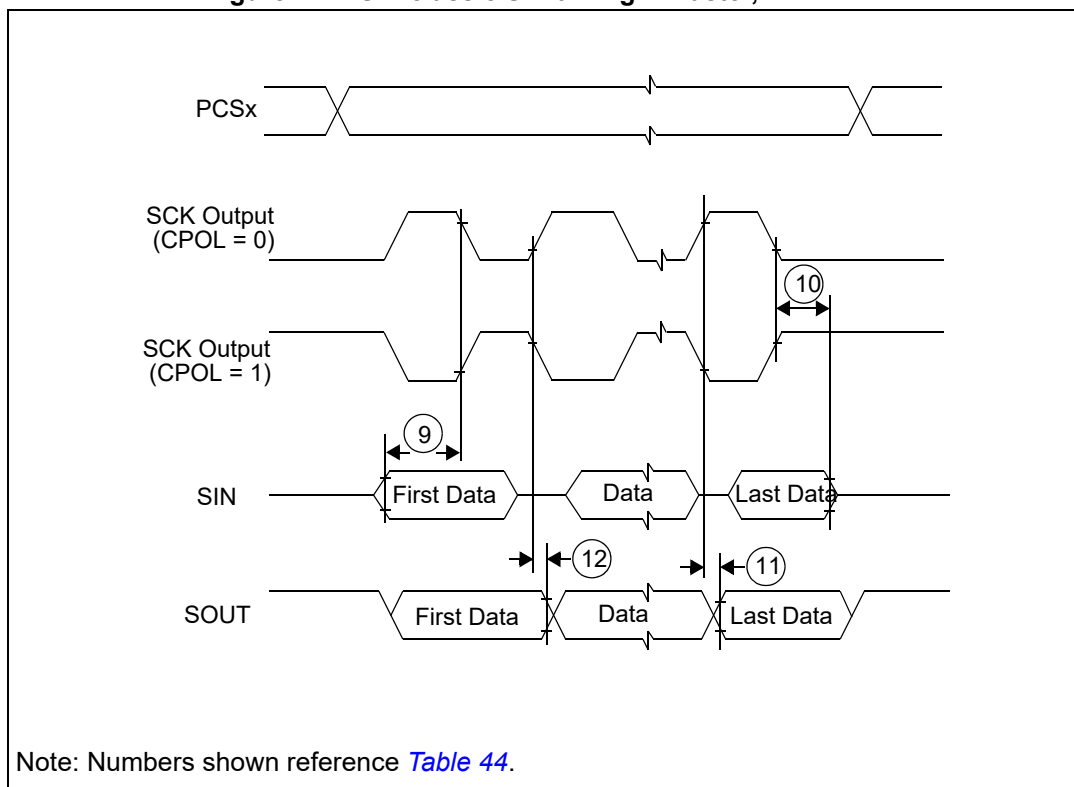


Figure 18. DSPI classic SPI timing – slave, CPHA = 0

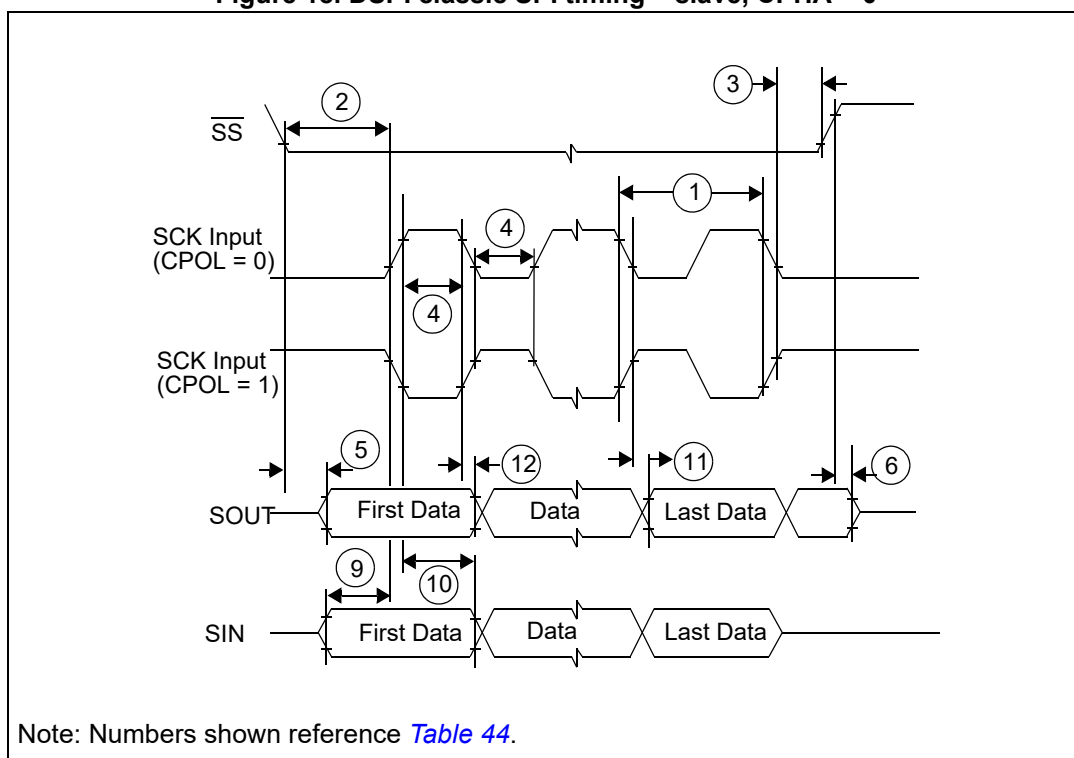


Figure 19. DSPI classic SPI timing – slave, CPHA = 1

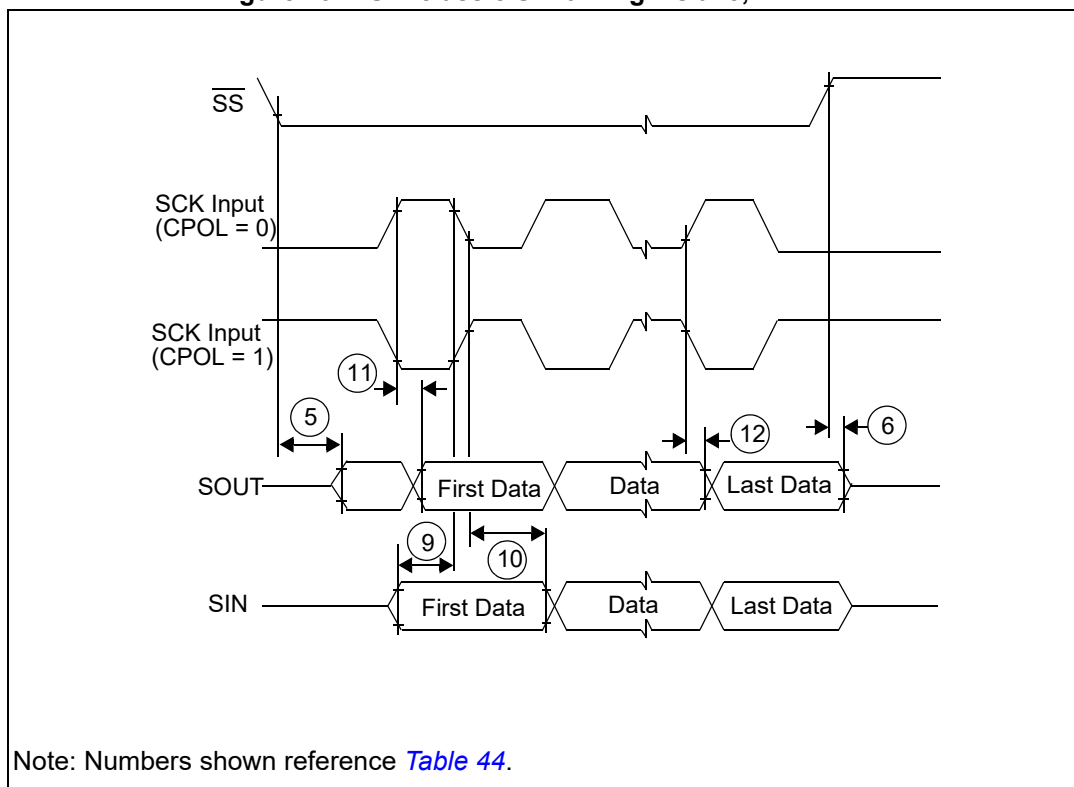
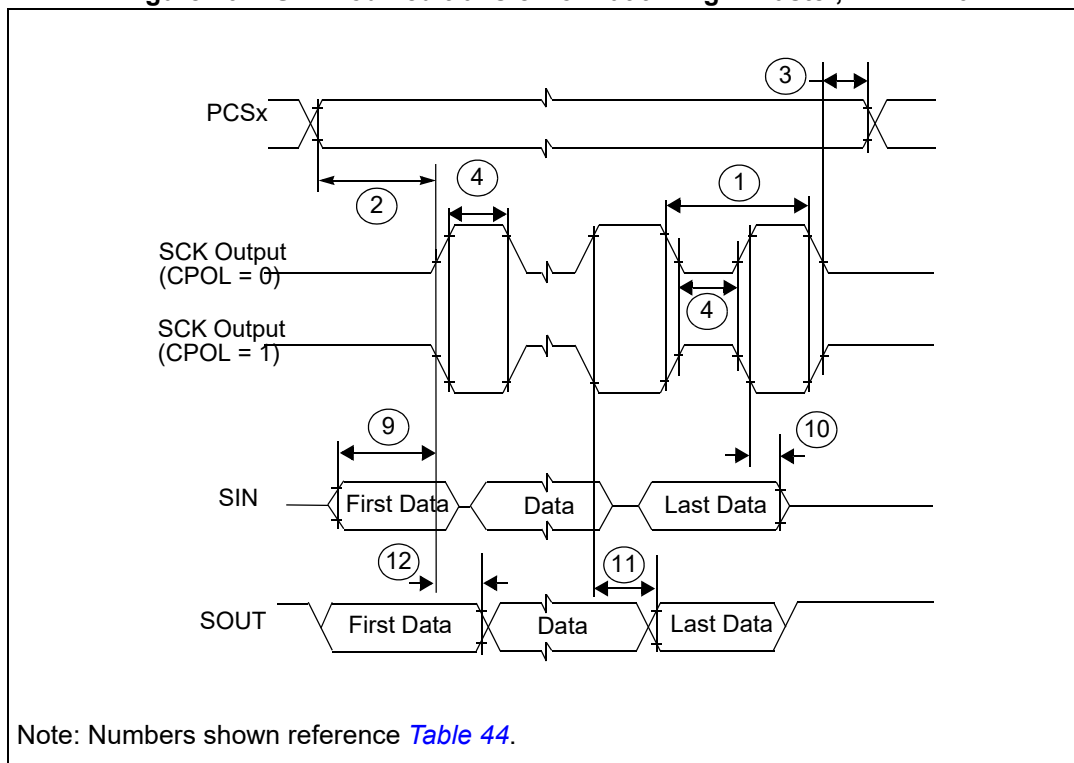


Figure 20. DSPI modified transfer format timing – master, CPHA = 0



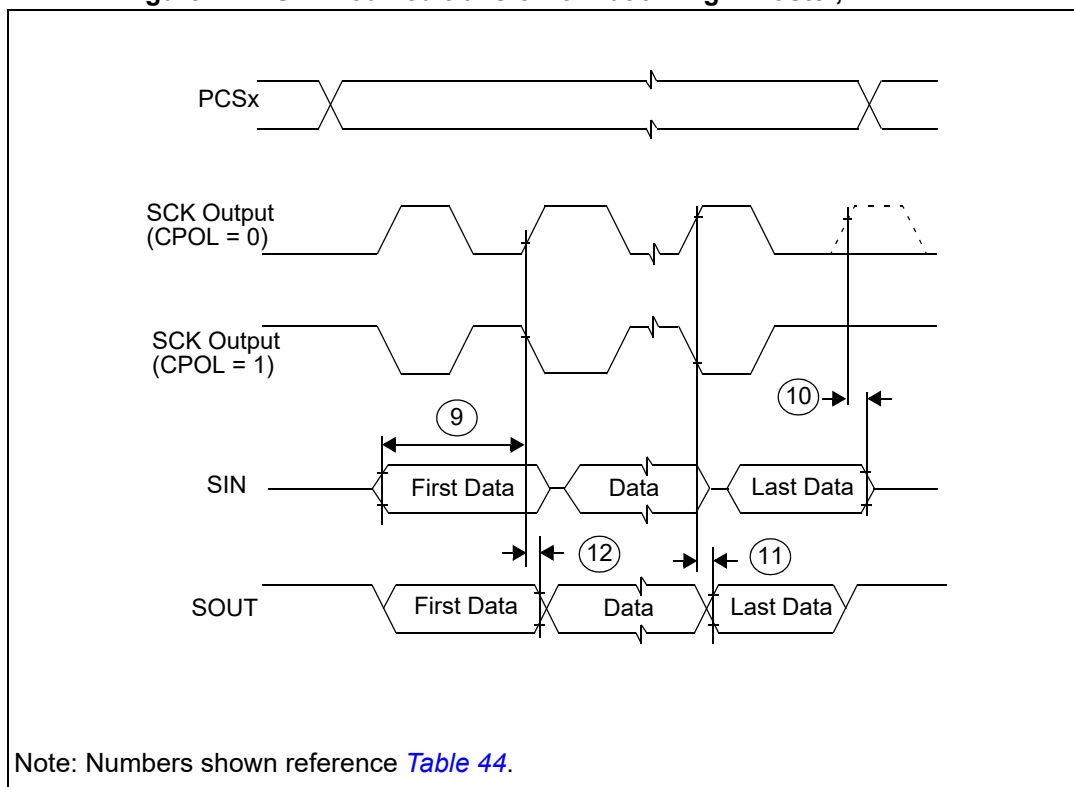
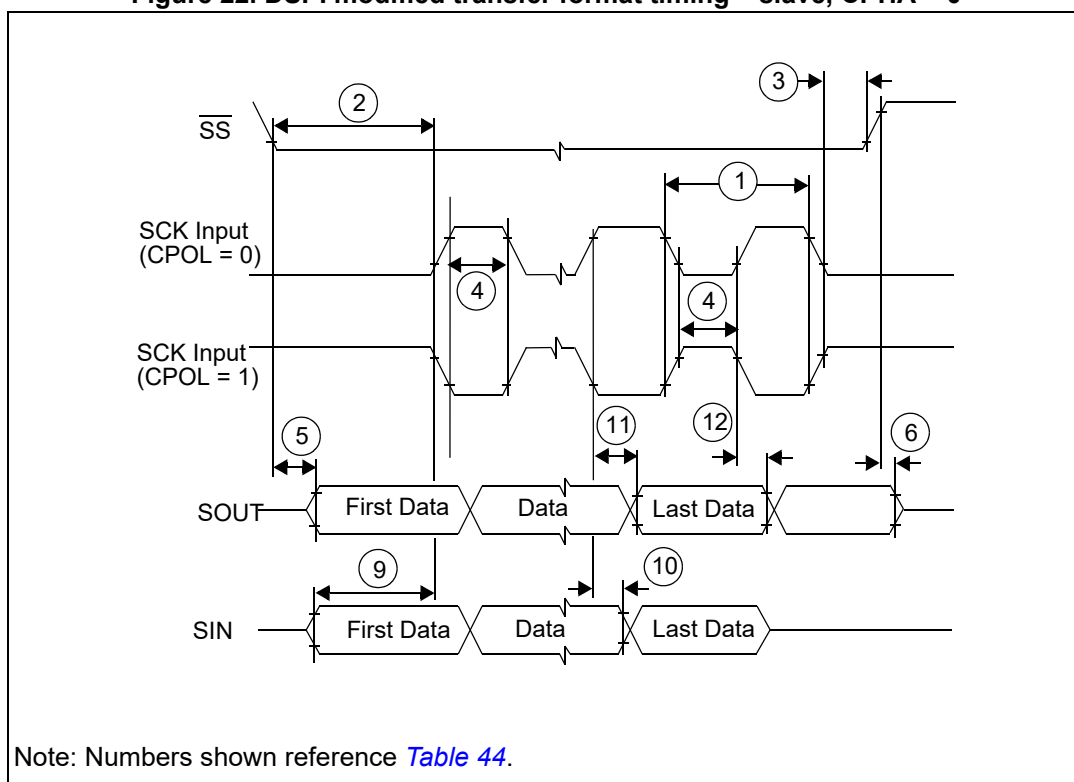
**Figure 21. DSPI modified transfer format timing – master, CPHA = 1****Figure 22. DSPI modified transfer format timing – slave, CPHA = 0**

Figure 23. DSPI modified transfer format timing – slave, CPHA = 1

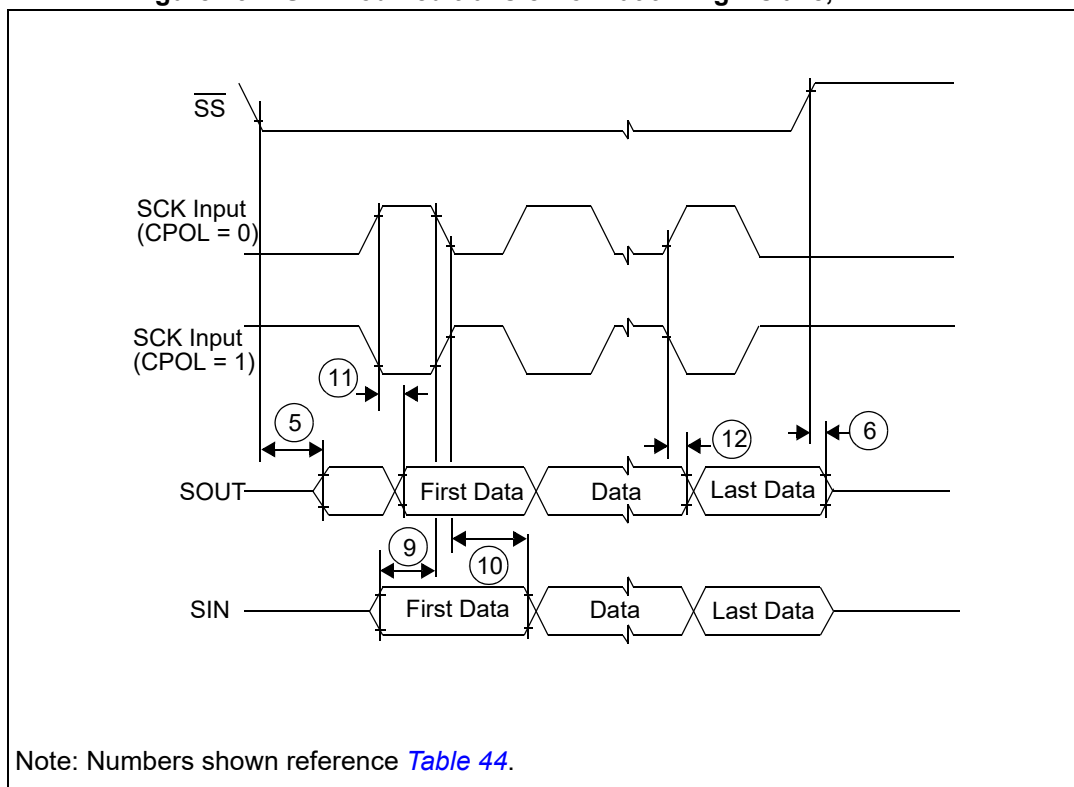
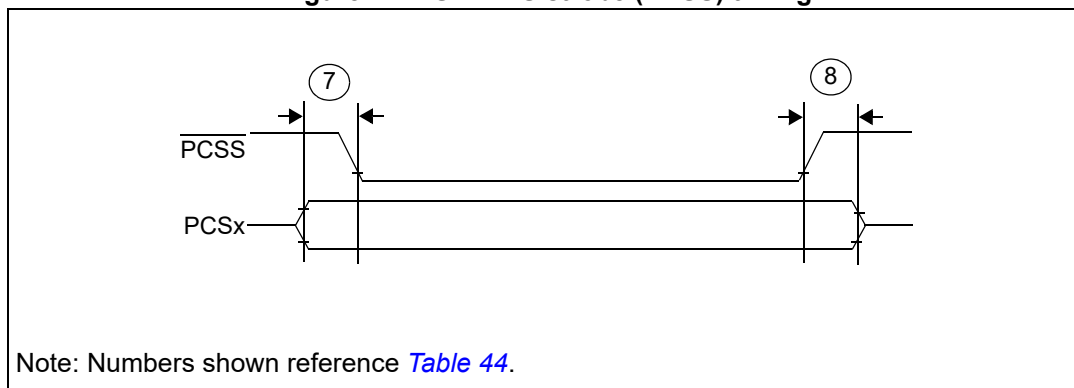


Figure 24. DSPI PCS strobe (PCSS) timing



#### 4.18.3 JTAG characteristics

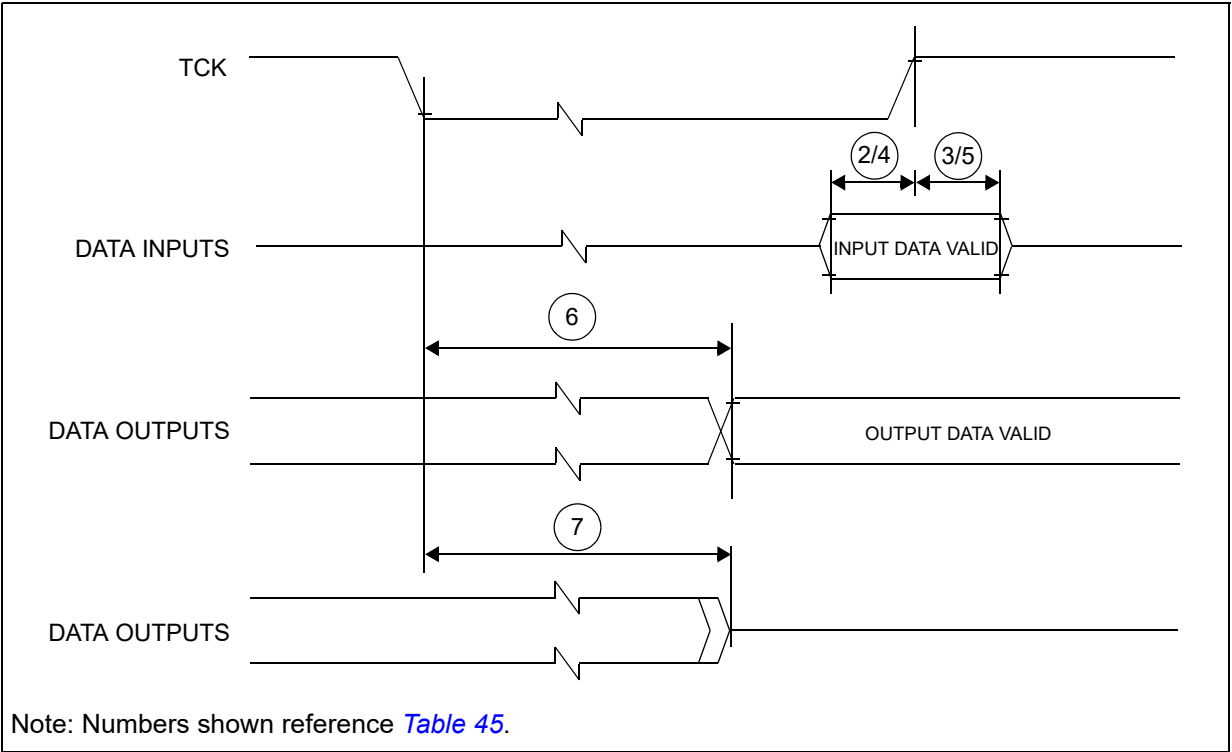
Table 45. JTAG characteristics

| No. | Symbol     | C  | D | Parameter      | Value |     |     | Unit |
|-----|------------|----|---|----------------|-------|-----|-----|------|
|     |            |    |   |                | Min   | Typ | Max |      |
| 1   | $t_{JCYC}$ | CC | D | TCK cycle time | 83.33 | —   | —   | ns   |
| 2   | $t_{TDIS}$ | CC | D | TDI setup time | 15    | —   | —   | ns   |
| 3   | $t_{TDIH}$ | CC | D | TDI hold time  | 5     | —   | —   | ns   |

Table 45. JTAG characteristics (continued)

| No. | Symbol     | C  | D | Parameter              | Value |     |     | Unit |
|-----|------------|----|---|------------------------|-------|-----|-----|------|
|     |            |    |   |                        | Min   | Typ | Max |      |
| 4   | $t_{TMSS}$ | CC | D | TMS setup time         | 15    | —   | —   | ns   |
| 5   | $t_{TMSH}$ | CC | D | TMS hold time          | 5     | —   | —   | ns   |
| 6   | $t_{TDOV}$ | CC | D | TCK low to TDO valid   | —     | —   | 49  | ns   |
| 7   | $t_{TDOI}$ | CC | D | TCK low to TDO invalid | 6     | —   | —   | ns   |

Figure 25. Timing diagram – JTAG boundary scan



## 5 Package characteristics

### 5.1 ECOPACK®

In order to meet environmental requirements, ST offers the devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 5.2 Package mechanical data

#### 5.2.1 LQFP100

Figure 26. LQFP100 mechanical drawing

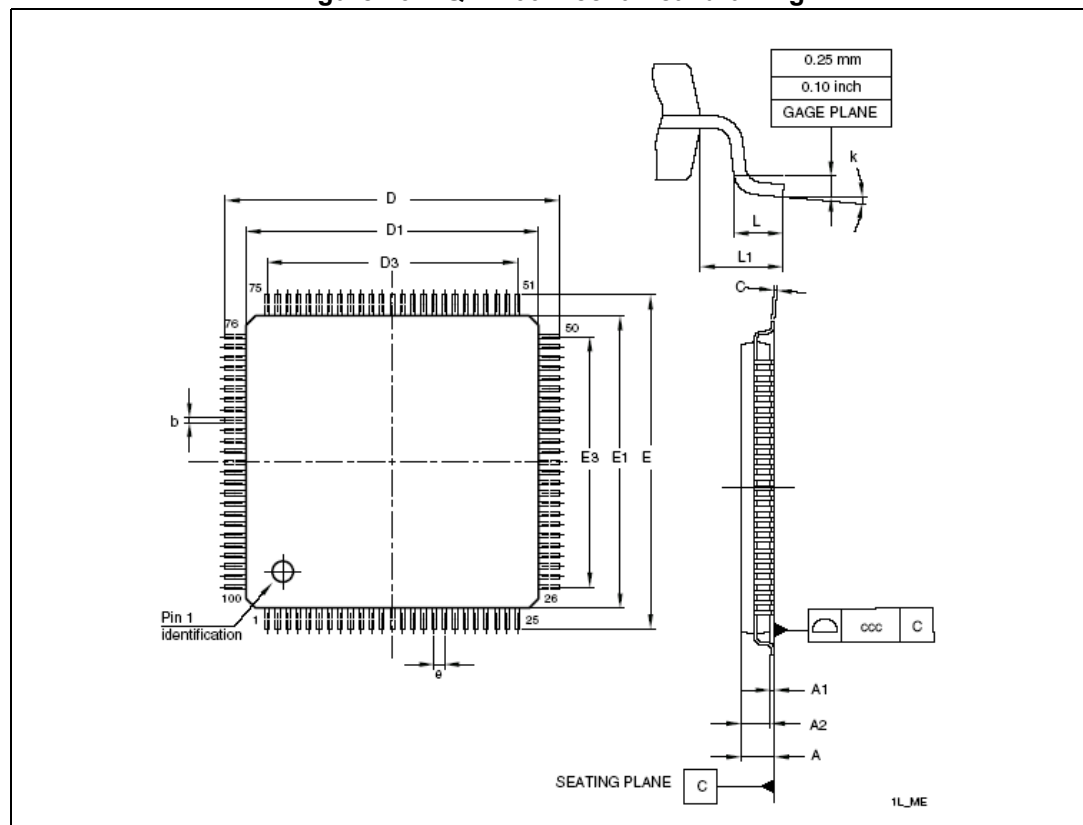




Table 46. LQFP100 mechanical data

| Symbol    | mm     |        |        | inches <sup>(1)</sup> |        |        |
|-----------|--------|--------|--------|-----------------------|--------|--------|
|           | Min    | Typ    | Max    | Min                   | Typ    | Max    |
| A         | —      | —      | 1.600  | —                     | —      | 0.0630 |
| A1        | 0.050  | —      | 0.150  | 0.0020                | —      | 0.0059 |
| A2        | 1.350  | 1.400  | 1.450  | 0.0531                | 0.0551 | 0.0571 |
| b         | 0.170  | 0.220  | 0.270  | 0.0067                | 0.0087 | 0.0106 |
| c         | 0.090  | —      | 0.200  | 0.0035                | —      | 0.0079 |
| D         | 15.800 | 16.000 | 16.200 | 0.6220                | 0.6299 | 0.6378 |
| D1        | 13.800 | 14.000 | 14.200 | 0.5433                | 0.5512 | 0.5591 |
| D3        | —      | 12.000 | —      | —                     | 0.4724 | —      |
| E         | 15.800 | 16.000 | 16.200 | 0.6220                | 0.6299 | 0.6378 |
| E1        | 13.800 | 14.000 | 14.200 | 0.5433                | 0.5512 | 0.5591 |
| E3        | —      | 12.000 | —      | —                     | 0.4724 | —      |
| e         | —      | 0.500  | —      | —                     | 0.0197 | —      |
| L         | 0.450  | 0.600  | 0.750  | 0.0177                | 0.0236 | 0.0295 |
| L1        | —      | 1.000  | —      | —                     | 0.0394 | —      |
| k         | 0.0°   | 3.5°   | 7.0°   | 0.0°                  | 3.5°   | 7.0°   |
| Tolerance | mm     |        |        | inches                |        |        |
| ccc       | 0.080  |        |        | 0.0031                |        |        |

1. Values in inches are converted from mm and rounded to four decimal digits.

## 5.2.2 LQFP64

Figure 27. LQFP64 mechanical drawing

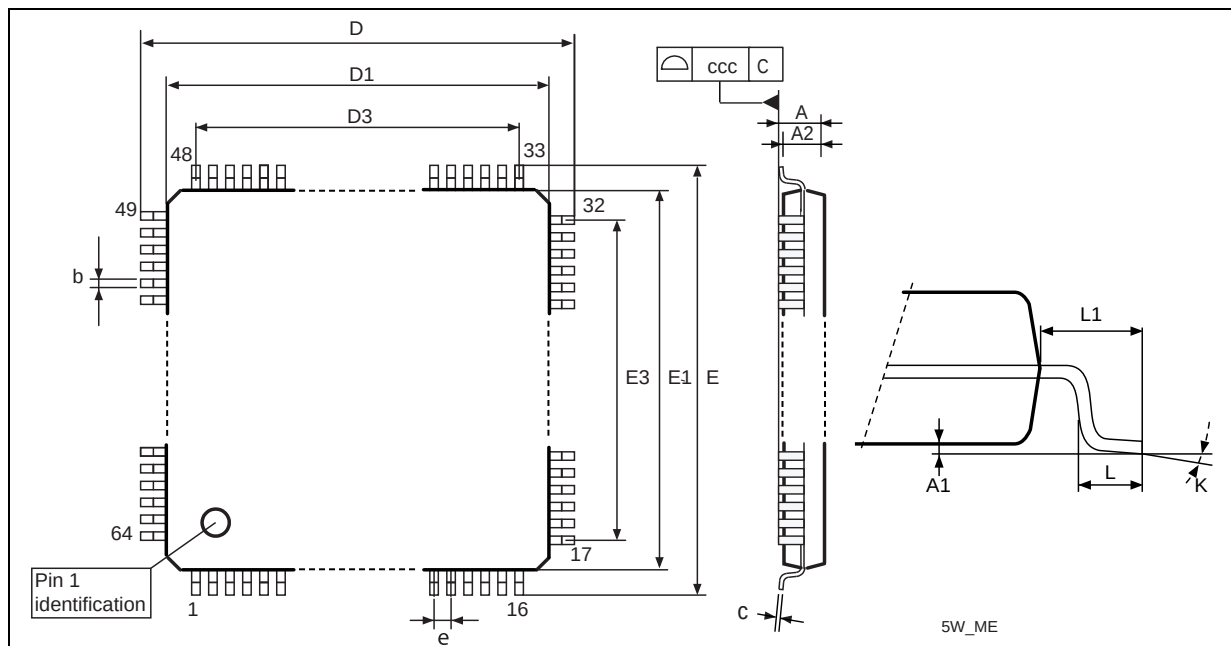


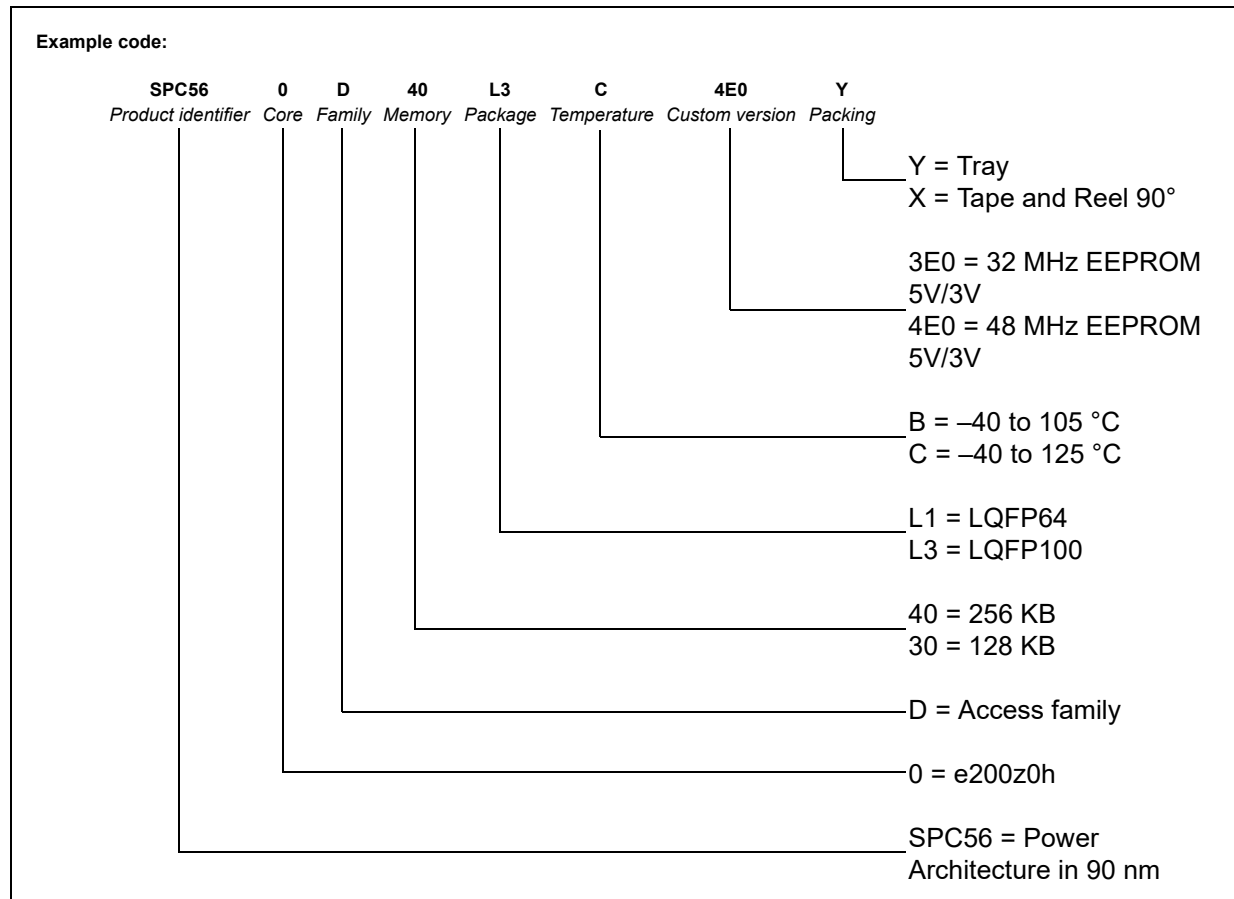
Table 47. LQFP64 mechanical data

| Symbol | mm   |      |      | inches <sup>(1)</sup> |        |        |
|--------|------|------|------|-----------------------|--------|--------|
|        | Min  | Typ  | Max  | Min                   | Typ    | Max    |
| A      | —    | —    | 1.6  | —                     | —      | 0.0630 |
| A1     | 0.05 | —    | 0.15 | 0.0020                | —      | 0.0059 |
| A2     | 1.35 | 1.4  | 1.45 | 0.0531                | 0.0551 | 0.0571 |
| b      | 0.17 | 0.22 | 0.27 | 0.0067                | 0.0087 | 0.0106 |
| c      | 0.09 | —    | 0.2  | 0.0035                | —      | 0.0079 |
| D      | 11.8 | 12   | 12.2 | 0.4646                | 0.4724 | 0.4803 |
| D1     | 9.8  | 10   | 10.2 | 0.3858                | 0.3937 | 0.4016 |
| D3     | —    | 7.5  | —    | —                     | 0.2953 | —      |
| E      | 11.8 | 12   | 12.2 | 0.4646                | 0.4724 | 0.4803 |
| E1     | 9.8  | 10   | 10.2 | 0.3858                | 0.3937 | 0.4016 |
| E3     | —    | 7.5  | —    | —                     | 0.2953 | —      |
| e      | —    | 0.5  | —    | —                     | 0.0197 | —      |
| L      | 0.45 | 0.6  | 0.75 | 0.0177                | 0.0236 | 0.0295 |
| L1     | —    | 1    | —    | —                     | 0.0394 | —      |
| k      | 0.0° | 3.5° | 7.0° | 0.0°                  | 3.5°   | 7.0°   |
| ccc    | —    | —    | 0.08 | —                     | —      | 0.0031 |

1. Values in inches are converted from mm and rounded to four decimal digits.

## 6 Ordering information

Figure 28. Commercial product code structure



## Appendix A Acronyms and abbreviations

[Table 48](#) lists acronyms and abbreviations used in this document.

**Table 48. Acronyms and abbreviations**

| Term   | Meaning                                                              |
|--------|----------------------------------------------------------------------|
| APU    | Auxilliary processing unit                                           |
| CMOS   | Complementary metal–oxide–semiconductor                              |
| CPHA   | Clock phase                                                          |
| CPOL   | Clock polarity                                                       |
| CS     | Peripheral chip select                                               |
| DAOC   | Double action output compare                                         |
| ECC    | Error code correction                                                |
| EVTO   | Event out                                                            |
| GPIO   | General purpose input/output                                         |
| IPM    | Input period measurement                                             |
| IPWM   | Input pulse width measurement                                        |
| MB     | Message buffer                                                       |
| MC     | Modulus counter                                                      |
| MCB    | Modulus counter buffered (up/down)                                   |
| MCKO   | Message clock out                                                    |
| MDO    | Message data out                                                     |
| MSEO   | Message start/end out                                                |
| MTFE   | Modified timing format enable                                        |
| NVUSRO | Non-volatile user options register                                   |
| OPWFMB | Output pulse width and frequency modulation buffered                 |
| OPWMB  | Output pulse width modulation buffered                               |
| OPWMCB | Center aligned output pulse width modulation buffered with dead time |
| OPWMT  | Output pulse width modulation trigger                                |
| PWM    | Pulse width modulation                                               |
| SAIC   | Single action input capture                                          |
| SAOC   | Single action output compare                                         |
| SCK    | Serial communications clock                                          |
| SOUT   | Serial data out                                                      |
| TCK    | Test clock input                                                     |
| TDI    | Test data input                                                      |

**Table 48. Acronyms and abbreviations**

| <b>Term</b> | <b>Meaning</b>   |
|-------------|------------------|
| TDO         | Test data output |
| TMS         | Test mode select |

## Revision history

[Table 49](#) summarizes revisions to this document.

**Table 49. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 09-Jul-2009 | 1        | Initial release.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| 18-Feb-2010 | 2        | Updated the following tables: <ul style="list-style-type: none"> <li>- Absolute maximum ratings</li> <li>- Low voltage power domain electrical characteristics;</li> <li>- On-chip peripherals current consumption</li> <li>- DSPI characteristics;</li> <li>- JTAG characteristics;</li> <li>- ADC conversion characteristics;</li> </ul> Inserted a note on "Flash power supply DC characteristics" section.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| 10-Aug-2010 | 3        | <p>"Features" section: Updated information concerning eMIOS, ADC, LINFlex, Nexus and low power capabilities</p> <p>"SPC560D30x and SPC560D40x device comparison" table: updated the "Execution speed" row</p> <p>"SPC560D30x and SPC560D40x series block diagram" figure:</p> <ul style="list-style-type: none"> <li>– updated max number of Crossbar Switches</li> <li>– updated Legend</li> </ul> <p>"SPC560D30x and SPC560D40x series block summary" table: added contents concernig the eDMA block</p> <p>"LQFP100 pin configuration (top view)" figure:</p> <ul style="list-style-type: none"> <li>– removed alternate functions</li> <li>– updated supply pins</li> </ul> <p>"LQFP64 pin configuration (top view)" figure: removed alternate functions</p> <p>Added "Pin muxing" section</p> <p>"NVUSRO register" section: Deleted "NVUSRO[WATCHDOG_EN] field description" section</p> <p>"Recommended operating conditions (3.3 V)" table:</p> <ul style="list-style-type: none"> <li>– TV<sub>DD</sub>: deleted min value</li> <li>– In footnote No. 3, changed capacitance value between V<sub>DD_BV</sub> and V<sub>SS_LV</sub></li> </ul> <p>"Recommended operating conditions (5.0 V)" table: deleted TV<sub>DD</sub> min value</p> <p>"LQFP thermal characteristics" table: changed R<sub>θJC</sub> values</p> <p>"I/O input DC electrical characteristics" table:</p> <ul style="list-style-type: none"> <li>– W<sub>FI</sub>: updated max value</li> <li>– W<sub>NFI</sub>: updated min value</li> </ul> <p>"I/O consumption" table: removed I<sub>DYNSEG</sub> row</p> <p>Added "I/O weight" table</p> <p>"Program and erase specifications (Code Flash)" table: deleted T<sub>Bank_C</sub> row</p> |

Table 49. Document revision history (continued)

| Date        | Revision     | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|-------------|--------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 10-Aug-2010 | 3<br>(cont.) | <p>Updated the following tables:</p> <ul style="list-style-type: none"> <li>– “Voltage regulator electrical characteristics”</li> <li>– “Low voltage monitor electrical characteristics”</li> <li>– “Low voltage power domain electrical characteristics”</li> <li>– “Start-up time/Switch-off time”</li> <li>– “Fast external crystal oscillator (4 to 16 MHz) electrical characteristics”</li> <li>– “FMPLL electrical characteristics”</li> <li>– “Fast internal RC oscillator (16 MHz) electrical characteristics”</li> <li>– “ADC conversion characteristics”</li> <li>– “On-chip peripherals current consumption”</li> <li>– “DSPI characteristics”</li> </ul> <p>“DSPI characteristics” section: removed “DSPI PCS strobe (PCSS) timing” figure</p> <p>Updated “Order codes” table</p> <p>Added “Order codes for engineering samples” table</p> <p>Updated “Commercial product code structure” table</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 16-Sep-2011 | 4            | <p>Formatting and editorial changes throughout</p> <p>Device comparison table: for the “Total timer I/O eMIOS”, changed “13 ch” to “14 ch”</p> <p>SPC560D30/SPC560D40 series block summary:</p> <ul style="list-style-type: none"> <li>– added definition for “AUTOSAR” acronym</li> <li>– changed “System watchdog timer” to “Software watchdog timer”</li> </ul> <p>LQFP64 pin configuration (top view): changed pin 6 from VPP_TEST to VSS_HV</p> <p>Added section “Pad configuration during reset phases”</p> <p>Added section “Voltage supply pins”</p> <p>Added section “Pad types”</p> <p>Added section “System pins”</p> <p>Renamed and updated section “Functional ports” (was previously section “Pin muxing”); update includes replacing all instances of WKUP with WKPU (WKPU is the correct abbreviation for Wakeup Unit)</p> <p>Section “NVUSRO register”: edited content to separate configuration into electrical parameters and digital functionality</p> <p>Added section “NVUSRO[WATCHDOG_EN] field description”</p> <p>Absolute maximum ratings: Removed “C” column from table</p> <p>Replaced “TBD” with “—” in <math>T_{VDD}</math> min value cell of 3.3 V and 5 V recommended operating conditions tables</p> <p>LQFP thermal characteristics: removed <math>R_{\theta JB}</math> single layer board conditions; updated footnote 4</p> <p>I/O input DC electrical characteristics: removed footnote “All values need to be confirmed during device validation”; updated <math>I_{LKG}</math> characteristics</p> |

Table 49. Document revision history (continued)

| Date        | Revision     | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
|-------------|--------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 16-Sep-2011 | 4<br>(cont.) | <p>MEDIUM configuration output buffer electrical characteristics: changed "<math>I_{OH} = 100 \mu A</math>" to "<math>I_{OL} = 100 \mu A</math>" in <math>V_{OL}</math> conditions</p> <p>I/O consumption: replaced instances of "Root medium square" with "Root mean square"</p> <p>Updated section "Voltage regulator electrical characteristics"</p> <p>Section "Low voltage detector electrical characteristics": changed title (was "Voltage monitor electrical characteristics"); added a fifth LVD (LVDHV3B); added event status flag names found in RGM chapter of device reference manual to POR module and LVD descriptions; replaced instances of "Low voltage monitor" with "Low voltage detector"; deleted note referencing power domain No. 2 (this domain is not present on the device); updated electrical characteristics table</p> <p>Updated and renamed section "Power consumption" (was previously section "Low voltage domain power consumption")</p> <p>Program and erase specifications (code flash): updated symbols; updated <math>t_{ESUS}</math> values</p> <p>Updated Flash memory read access timing</p> <p>EMI radiated emission measurement: updated <math>S_{EMI}</math> values</p> <p>Updated FMPLL electrical characteristics</p> <p>Crystal oscillator and resonator connection scheme: inserted footnote about possibly requiring a series resistor</p> <p>Fast internal RC oscillator (16 MHz) electrical characteristics: updated <math>t_{FIRCSU}</math> values</p> <p>Section "Input impedance and ADC accuracy": changed "<math>V_A/V_{A2}</math>" to "<math>V_{A2}/V_A</math>" in Equation 13</p> <p>ADC conversion characteristics:</p> <ul style="list-style-type: none"> <li>– updated conditions for sampling time <math>V_{DD} = 5.0 V</math></li> <li>– updated conditions for conversion time <math>V_{DD} = 5.0 V</math></li> </ul> <p>Updated Abbreviations</p> <p>Removed Order codes tables.</p> |
| 01-Dec-2011 | 5            | <p>Replaced "TBD" with "8.21 mA" in <math>I_{DD\_HV(FLASH)}</math> cell of On-chip peripherals current consumption table</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |



**Table 49. Document revision history (continued)**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|-------------|----------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 04-Feb-2013 | 6        | <p>Removed all instances of table footnote "All values need to be confirmed during device validation"</p> <p>Section 4.1: Introduction, removed Caution note.</p> <p>Table 12: Recommended operating conditions (3.3 V), added minimum value of TVDD and footnote about it.</p> <p>Table 13: Recommended operating conditions (5.0 V), added minimum value of TVDD and footnote about it.</p> <p>Updated Section 4.17.2: Input impedance and ADC accuracy</p> <p>In Table 24, changed VLVDHV3L, VLVDHV3BL from 2.7 V to 2.6 V.</p> <p>Revised the Table 29: Flash module life</p> <p>Updated Table 44: DSPI characteristics, to add specifications 7 and 8, tPCSC and tPASC.</p> <p>Inserted Figure 24: DSPI PCS strobe (PCSS) timing</p> |
| 17-Sep-2013 | 7        | Updated Disclaimer.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
| 01-Nov-2018 | 8        | <p>Removed the following two tables:</p> <ul style="list-style-type: none"> <li>– Order codes</li> <li>– Order codes for engineering samples</li> </ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |

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Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)

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